## International Photovoltaic Science and Engineering Conference



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PL1-12 Yoshihiro Hamakawa Adviser Professor to the Chancellor, Department of Photonics Ritsumeikan University Japan  Solar Age -Bevond Reality-Excitement  Isao Yukawa* K. Shirasswa *President of the Kyosera Slor Group, Japan  Our Solar Power Future: The U.S. PV Industry Roadmap for 2030 and Beyond  Allen Barnet! and Rhone Resch' Ellectrical and Computer Engineering, University of Delaware, Newark, USA 2 Solar Energy Industries Association, Washington, DC, USA  APV Roadmap for Europe  PL2-11 Wolfgang PALZ Chairman, World Council for Renewable Energy, Paris/Brussels  Thin Film Silicon Photovoltaic-from R&D to Commercialization  Subbendu Guha, Jeffrey Yang United Solar Oone, United States of America  Mesoscopic Solar Cells  M. Grätzel Laboratory of Photonics and Interfaces, ISIC, Ecole Polytechnique Fédérale de Lausanne, Switzerland  Produce Technology of CdTe Thin Film Modules and Design of Manufacture Line  Tr  Lianghuan Feng¹, Wei Cai¹, Yaping Cai¹, Jingquan Zhang¹, Bing Li¹, Wei Li¹, Lili Wu¹, Zhi Lei¹, Jiagui Zheng¹, Jianping Xi² IDept. of Materials Science, Sichuan University, China 2 Green Development LLC, USA  The n-type ne-Sti-Ho-type e-Sti Heterojunction Solar Cells with A ne-Sti-H Intrinsic Buffer Layer  Meifang Zhu, Qunfang Zhang, Fengzhen Liu, Jinlog Liu Department of physics, Graduate School of Chinese Academy of Sciences, China  CIS Thin-Film Solar Modules: Scaling un Laboratory Processes and New Developments  M. Powalla¹, B. Dimmler² IZentrum für Sonnencergie- und Wasserstoff-Forschung Baden-Württemberg (ZSW) 2Würth Solar GmbH & Co. KG, Germany  Thin Film Silicon Solar Cells and Deposition Technologies  R.E.I. Schropp, A. Gordijn, R.H.J. Franken, C.H.M. van der Werf, J.K. Rath Thin Film Silicon Solar Cells and Deposition Technologies SID - Physics of Devices, Debye Institute, Utrecht University, Netherlands	0-2	
Adviser Professor to the Chancellor, Department of Photonics Ritsumeikan University Japan  Solar Age -Bevond Reality-Excitement  Isao Yukawa* K. Shirasawa **President of the Kyocen Solar Group, Japan  Our Solar Power Future The U.S. PV Industry Roadmap for 2030 and Beyond  PL1-3  Allen Barnett¹ and Rhone Resch² IElectrical and Computer Engineering, University of Delaware, Newark, USA 2Solar Energy Industries Association, Washington, DC, USA  APV Roadmap for Europe  PL2-1  Wolfgang PALZ Chairman, World Council for Renewable Energy, Paris/Brussels  Thin Film Silicon Photovoltaic-from R&D to Commercialization  PL2-3  Subhendu Guha, Jeffrey Yang United Solar Voonic, United States of America  Mesoscopic Solar Cells  M. Gritzel Laboratory of Photonics and Interfaces, ISIC, Ecole Polytechnique Fédérale de Lausanne, Switzerland  Produce Technology of CdTe Thin Film Modules and Design of Manufacture Line  TF  Lianghuan Feng¹, Wei Ca¹, Yaping Ca¹, Jingquan Zhang¹, Bing Li¹, Wei Li¹, Lili Wu¹, Zhi Le¹, Jiagui Zheng¹, Jianping Xi² 1Dept. of Materials Science, Sichuan University, China 2Green Development LLC, USA  The n-type ne-Si Hel-prope c-Si Heteroiunction Solar Cells with A ne-Si-H Intrinsic Buffer Laver  Meifang Zhu, Qunfang Zhang, Fengzhen Liu, Jinlong Liu Department of physics, Graduate School of Chinese Academy of Sciences, China  CIS Thin-Film Solar Modules: Scaling up Laboratory Processes and New Developments  M. Powalla¹, B. Dimmler² L'Centrum für Sonnemenergie- und Wasserstoff-Forschung Baden-Württemberg (ZSW) 2Würth Solar GmbH & Co. KG, Germany  Thin Film Silicon Solar Cells and Deposition Technologies  TF  R. E. I. Schropp, A. Gordjin, R. H. J. Franken, C. H. M. van der Werf, J. K. Rath  Thin Film Silicon Solar Cells and Deposition Technologies SID - Physics of Devices, Debye Institute, Utrecht University, Netherlands		Progress in Amorphous and Naoncrystalline Silicon Research and Their Applications to Photovoltaics
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*President of the Kyocera Solar Group, Japan  Our Solar Power Future: The U.S. PV Industry Roadmap for 2030 and Beyond  PL1-3 Allen Barnett <sup>1</sup> and Rhone Resch <sup>2</sup> IElectrical and Computer Engineering, University of Delaware, Newark, USA 2Solar Energy Industries Association, Washington, DC, USA  APV Roadmap for Europe  PL2-1 Wolfgang PALZ Chairman, World Council for Renewable Energy, Paris/Brussels  Thin Film Silicon Photovoltaic-from R&D to Commercialization  Subhendu Guha, Jeffrey Yang United Solar Ovonic, United States of America  Mesoscopic Solar Cells  M. Grätzel Laboratory of Photonics and Interfaces, ISIC, Ecole Polytechnique Fédérale de Lausanne, Switzerland  Produce Technology of CdTe Thin Film Modules and Design of Manufacture Line  IF Lianghuan Feng <sup>1</sup> , Wei Cai <sup>1</sup> , Yaping Cai <sup>1</sup> , Jingquan Zhang <sup>1</sup> , Bing Li <sup>1</sup> , Wei Li <sup>1</sup> , Lili Wu <sup>1</sup> , Zhi Lei <sup>1</sup> , Jiagui Zheng <sup>1</sup> , Jianping Xi <sup>2</sup> IDept. of Materials Science, Sichuan University, China 2Green Development LLC, USA  The n-type ne-Si-Hip-type c-Si-Heterojunction Solar Cells with A ne-Si-H Intrinsic Buffer Laver  Meifang Zhu, Qunfang Zhang, Fengzhen Liu, Jinlong Liu Department of physics, Graduate School of Chinese Academy of Sciences, China  CIS Thin-Film Solar Modules: Scaling up Laboratory Processes and New Developments  M. Powalla <sup>1</sup> , B. Dimmler <sup>2</sup> IZentrum für Sonnenenergie- und Wasserstoff-Forschung Baden-Württemberg (ZSW) 2Würth Solar GmbH & Co. KG, Germany  Thin Film Silicon Solar Cells and Deposition Technologies  TF  R.E.I. Schropp, A. Gordijn, R.H.J. Franken, C.H.M. van der Werf, J.K. Rath Thin Film Silicon Solar Cells and Deposition Technologies SID - Physics of Devices, Debye Institute, Utrecht University, Netherlands		Solar Age -Beyond Reality-Excitement
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TF Meifang Zhu, Qunfang Zhang, Fengzhen Liu, Jinlong Liu Department of physics, Graduate School of Chinese Academy of Sciences, China  CIS Thin-Film Solar Modules: Scaling up Laboratory Processes and New Developments  M. Powalla <sup>1</sup> , B. Dimmler <sup>2</sup> 1Zentrum für Sonnenenergie- und Wasserstoff-Forschung Baden-Württemberg (ZSW) 2Würth Solar GmbH & Co. KG, Germany  Thin Film Silicon Solar Cells and Deposition Technologies  R.E.I. Schropp, A. Gordijn, R.H.J. Franken, C.H.M. van der Werf, J.K. Rath Thin Film Silicon Solar Cells and Deposition Technologies SID - Physics of Devices, Debye Institute, Utrecht University, Netherlands	TF	Lianghuan Feng <sup>1</sup> , Wei Cai <sup>1</sup> , Yaping Cai <sup>1</sup> , Jingquan Zhang <sup>1</sup> , Bing Li <sup>1</sup> , Wei Li <sup>1</sup> , Lili Wu <sup>1</sup> , Zhi Lei <sup>1</sup> , Jiagui Zheng <sup>1</sup> , Jianping Xi <sup>2</sup> 1Dept. of Materials Science, Sichuan University, China 2Green Development LLC, USA
Department of physics, Graduate School of Chinese Academy of Sciences, China  CIS Thin-Film Solar Modules: Scaling up Laboratory Processes and New Developments  M. Powalla <sup>1</sup> , B. Dimmler <sup>2</sup> 1Zentrum für Sonnenenergie- und Wasserstoff-Forschung Baden-Württemberg (ZSW) 2Würth Solar GmbH & Co. KG, Germany  Thin Film Silicon Solar Cells and Deposition Technologies  R.E.I. Schropp, A. Gordijn, R.H.J. Franken, C.H.M. van der Werf, J.K. Rath Thin Film Silicon Solar Cells and Deposition Technologies SID - Physics of Devices, Debye Institute, Utrecht University, Netherlands		The n-type nc-Si:H/p-type c-Si Heterojunction Solar Cells with A nc-Si:H Intrinsic Buffer Layer
M. Powalla <sup>1</sup> , B. Dimmler <sup>2</sup> 1Zentrum für Sonnenenergie- und Wasserstoff-Forschung Baden-Württemberg (ZSW) 2Würth Solar GmbH & Co. KG, Germany  Thin Film Silicon Solar Cells and Deposition Technologies  R.E.I. Schropp, A. Gordijn, R.H.J. Franken, C.H.M. van der Werf, J.K. Rath Thin Film Silicon Solar Cells and Deposition Technologies SID - Physics of Devices, Debye Institute, Utrecht University, Netherlands	TF	
M. Powalla¹, B. Dimmler² 1Zentrum für Sonnenenergie- und Wasserstoff-Forschung Baden-Württemberg (ZSW) 2Würth Solar GmbH & Co. KG, Germany  Thin Film Silicon Solar Cells and Deposition Technologies  R.E.I. Schropp, A. Gordijn, R.H.J. Franken, C.H.M. van der Werf, J.K. Rath Thin Film Silicon Solar Cells and Deposition Technologies SID - Physics of Devices, Debye Institute, Utrecht University, Netherlands		CIS Thin-Film Solar Modules: Scaling up Laboratory Processes and New Developments
R.E.I. Schropp, A. Gordijn, R.H.J. Franken, C.H.M. van der Werf, J.K. Rath Thin Film Silicon Solar Cells and Deposition Technologies SID - Physics of Devices, Debye Institute, Utrecht University, Netherlands	TF	
Thin Film Silicon Solar Cells and Deposition Technologies SID - Physics of Devices, Debye Institute, Utrecht University, Netherlands		Thin Film Silicon Solar Cells and Deposition Technologies
TF Development of Novel Nanocrystalline SiC, Si <sub>1-x</sub> Ge <sub>x</sub> C and Ge <sub>1-y</sub> C <sub>y</sub> for Solar Cell Applications	TF	
	TF	Development of Novel Nanocrystalline SiC, Si <sub>1-x</sub> Ge <sub>x</sub> C and Ge <sub>1-y</sub> C <sub>y</sub> for Solar Cell Applications

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TF	X.Geng <sup>1</sup> , X.Liao <sup>2</sup> , M.Zhu <sup>3</sup> , Y.Zhao <sup>1</sup> 1. Institute of Photo-electronic Thin Film Device and Technology, China 2. Institute of Semiconductor, Chinese Academy of Science China 3. Department of physics, Graduate School of Chinese Academy of Sciences, China
	Fabrication of High Efficiency a-Si:Η/μc-Si:Η Tandem Solar Cell Modules
TF	Zhao Ying, Zhang Xiaodan, Zhu Feng, Gao Yantao, Wei Changchun, Xue Junming, Ren Huizhi, Zhang Dekun, Hou Guofu, Sun Ji Geng Xinhua Institute of photo-electronic thin film devices and technology of Nankai University, Key Laboratory of photo-electronic thin film devices and technology of Tianjin, Key Laboratory of Opto-electronic Information Science and Technology, Ministry of Education
	500W DSCs Showcase Design and Building
TF	Dai Song-Yuan, Wang Kong-Jia, Weng Jian, Xiao Shang-Feng, Chen Shuang-Hong, Huang Yang, Sui Yi-Feng, Kong Fan-Tai, Par Xu, Hu Lin-Hua, Shi Cheng-Wu Institute of Plasma Physics, China, Kong Ming-Guang, Key Laboratory of Materials Physics, Institute of Solid State Physics, China
	Light Trapping and Process Scale-up for Thin-film Silicon Solar Cells
TF	B. Rech <sup>1</sup> , T. Repmann <sup>1</sup> , J. Hüpkes <sup>1</sup> , M. van den Donker <sup>1</sup> , T. Kilper <sup>1</sup> , M. Berginski <sup>1</sup> , H. Stiebig <sup>1</sup> , S. Wieder <sup>2</sup> IInstitute of Photovoltaics, Germany 2Applied Films GmbH & Co. KG, Germany
	Design Rules for Ultra High Efficiency Solar Cells
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	Current Enhancement of Quantum Well Solar Cells
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	Development of Large Area, High Efficiency, Thin Film CIGS Modules
02-1	L. Chen, B. Sang, M. Akhtar, R. Govindarajan, S. Guo, J. Cambridge, A. Delahoy, M. Contreras Energy Photovoltaics, USA
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	<u>Transport Results on p-type Bridgman CuGa<sub>x</sub>In<sub>1-x</sub>Se<sub>2</sub></u>
02-3	T. Cheung, C.H. Champness, and I. Shih Electrical & Computer Engineering Department, McGill university, Canada
	CIGS Solar Cells and Submodules on Stainless Steel Substrates with Insulating Layer
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02-5	Characterization of MOCVD- $Zn_{1-X}Mg_XO$ (X $\leq 0.22$ ) Thin Films for CIGS Solar Cells

	Yoshiyuki CHIBA <sup>1</sup> , Hisashi MIYAZAKI <sup>1</sup> , Akira YAMADA <sup>2</sup> and Makoto KONAGAI <sup>1</sup> 1Department of Physical Electronics, Tokyo Institute of Technology, Japan 2Quantum Nanoelectronics Research Center, Tokyo Institute of Technology, Japan
	Building-Integrated Photovoltaics: ITS' PAST, Present and Future Applications in Hong Kong
03-1	Yang Hongxing and Fung Yuyan Renewable Energy Research Group (RERG), The Hong Kong Polytechnic University, Hong Kong
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	A Research Of New-style And Universal PV Building Materials
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	Techno Economic Feasibility of Replacing DG Set with Solar Photo Voltaic for Meeting Emergency Power Requirements of Housing Society
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	Growth of Low Resistivity Ga-doped Multicrystalline Silicon Ingots with High Carrier Lifetimes
04-1	M. Dhamrin <sup>1</sup> , T. Saitoh <sup>1</sup> , K. Kamisako <sup>1</sup> , T. Hirasawa <sup>2</sup> , T. Eguchi <sup>2</sup> and I. Yamaga <sup>2</sup> 1Tokyo Univ. of Agr. & Tech., Japan 2Dai-ichi Kiden Corp, Japan
	Numerical Simulation of Directional Solidification Processes for High-Quality Silicon Ingots
04-2	T. Saitoh, M. Dhamrin, K. Kamisako, T. Hirasawa <sup>1</sup> , T. Eguchi <sup>1</sup> and I. Yamaga <sup>1</sup> Tokyo University of Agriculture & Technology, Tokyo 1Dai-ichi Dentsu Ltd., Japan
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	Electrical Properties around Grain Boundaryof Poly-Crystalline Silicon for Solar Cell EvaluatedUsing the Conductive AFM
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	Effect of Varying the PECVD Microwave Power in SiNx:H Deposition on the Effective Lifetime in Silicon
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Peerlings <sup>1</sup> , Ernst-Ulrich R	Hans-Gerd Stevens <sup>2</sup> , Hermann-Josef Goerkes <sup>2</sup> , Dr. Wolfgang Kaufhold <sup>1</sup> , Andreas Lyding <sup>1</sup> , Dr. Henricus eisner <sup>1</sup> , Jens Ufermann <sup>1</sup> , Marc Vogt <sup>3</sup> AG, Krefeld 2: Meier Vakuumtechnik GmbH, Bocholt 3: Etimex PP GmbH, Dietenheim
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S. Wieder <sup>1</sup> , M.Liehr <sup>1</sup> , T. R 1 Applied Films, Germany	Repmann <sup>2</sup> , B. Rech <sup>2</sup> 2 Institute of Photovoltaics, Germany (IPV)
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Center, Korea Institute of Energy Research, Korea  Research On In, Ga-rich CIGS Thin Films  Xue Yuming, Sun yun, He qing, Zhang li, Xu chuanming, Xiao jianping Institute of Photoelectronic Thin Film Device and Technology, P.R. China  CulnSeg Coaxial Solar Cells by Electrodeposition  Yoonmook Kang and Donghwan Kim Department of Materials Science and Engineering, Korea University, Korea  Improvement in Surface Morphology of Electrodeposited CuGaSeg, Thin-Films by Supporting Electrolyte  Vusuke Oda <sup>1</sup> , Takashi Minemoto <sup>1</sup> , Hideyuki Takakura <sup>1</sup> and Yoshihiro Hamakawa <sup>1</sup> ICollege of Science and Engineering, Japan  Cu(In Ga)Seg Thin-Film Evolution During Se/Ar atmosphere Selenization of Sputtered Metallic Cu-In-Ga Precursors  Lin Zhou, Feng-Yan Li, Chuan-Ming Xu, Yun Sun, Qing He and Zhi-Qiang Zhou Institute of Photoelectronics, Nankai University, P.R. China  Coexistence of Polymorphic Phases in CulnSeg Thin Films  O-7  Chuan-Ming Xu <sup>1</sup> , Yun Sun <sup>1</sup> , Feng-Yan Li <sup>1</sup> , Lin Zhou <sup>1</sup> , Li Zhang <sup>1</sup> , Qing He <sup>1</sup> , Zhi-Qiang Zhou <sup>1</sup> and Hong-Tu Liu <sup>2</sup> Institute of Photoelectronics, Nankai University, P.R. China 2Department of Physics, University of Science and Technology of China, P.R. China  The Multi Solar Window  Eng. Ami Elazari MBA Millennium Electric T. O.U. Ltd., Israel  The First 10kW Grid-Connected BIPV Station on Qinghai-Tibetan Plateau  Liu Hong, Chen Huiling, Zhang Zhimin 1Qinghai Provincial New Energy Research Institute, P.R. China  A Research of the String Inverter Grid-Connected Photovoltaic System Based on Intelligent Cluster Controller		Chu-Wei Jiang, Martin A. Green and Gavin Conibeer Centre of Excellence for Advanced Silicon Photovoltaics and Photonics, University of New South Wales, Australia
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Chuan-Ming Xu*, Yun Sun*, Lin Zhoe*, Feng-Yan Li*, Li Zhang*, Yu-Ming Xue*, Ojing He*, Zhi-Ojang Zhou* and Hong-Tu Liu* Illustitute of Photoelectronics, Nankai University, China 2 Department of Physics, Luiversity of Science and Technology of China Growth and Characterization of a New Double Buffer Laver for Culin GaiNes, Solar Cells  Liudmila Larina*, Ki Hwan Kim*, Min Sik Kim*, Kyung Hoon Yoon* and Byung Tae Ahn* 1 Department of Materiuls Science and Engineering, Korea Advanced Institute of Science and Technology, Korea 2Solar Cell Research Center, Korea Institute of Energy Research, Korea  Research On In, Ga-rach CIGS Thin Falms  Wu Yuming, Sun yun, He qing, Zhang li, Xu chuanming, Xiao jianping Institute of Photoelectronic Thin Film Device and Technology, P.R. China  CalnSeg, Coaxial Solar Cells by Electrodeposition  Voonmook Kang and Donghwan Kim Department of Materials Science and Engineering, Korea University, Korea  Improvement in Surface Morphology of Electrodeposited CuGaSeg Thin-Films by Supporting Electrobite  Vusuke Oda*, Takashi Minemoto*, Hideyuki Takakura* and Yoshihiro Hamakawa*  [College of Science and Trajincering, Japan  Cadla GaiNeg, Thin-Film Evolution Durina Se'Ar atmosobere Scienization of Sputtered Metallic Cu-In-Ga Precursors  Lin Zhou, Feng-Yan Li, Chana-Ming Xu, Yun Sun, Qing He and Zhi-Qiang Zhou Institute of Photoelectronics, Nankai University, P.R. China  Coexistence of Polymorphic Phases in CuInSeg. Thin Films  Chuan-Ming Xu*, Yun Sun*, Feng-Yan Li*, Lin Zhou*, Li Zhang*, Qing He*, Zhi-Qiang Zhou* and Hong-Tu Lur*  The Multi Solar Window  Eng. Am Elazari MBA Milennium Electric To U. Lid , Israel  The First 10-W Grid-Connected BIPV Station on Qimbai-Tibetan Plateau  Liu Hong, Chen Huiling, Zhang Zhimin  [Qinghair Provincial New Energy Research Institute, P.R. China  A Research of the String Inverter Grid-Connected Photovolius System Based on Intelligent Cluster Costroller  The Multi Solar Window  Eng. Am Elazari MBA  Milennium Electric To U. Lid , Israel  The First 10-W Grid-Conne		Effect of Ga Addition on Vibrational Properties of the Quaternary CuIn <sub>1-x</sub> Ga <sub>x</sub> Se <sub>2</sub> Thin Films
109-2 Liudmila Larina <sup>1</sup> , Ki Hwan Kim <sup>1</sup> , Min Sik Kim <sup>3</sup> , Kyung Hon Yoon <sup>2</sup> and Byung Tae Ahn <sup>1</sup> 1 Department of Malerials Science and Engineering, Korea Advanced Institute of Science and Technology, Korea 2Solar Cell Research Center, Korea Institute of Energy Research, Korea Advanced Institute of Science and Technology, Korea 2Solar Cell Research Center, Korea Institute of Energy Research, Korea Advanced Institute of Science and Technology, Korea 2Solar Cell Research Center for June 1997.  Research On In. Garrich CIGS Thin Films  Op. 3 Xue Yuming, Sun yun, He qing, Zhang Ji, Xu chaamming, Xiao jianping Institute of Photoelectronic Thin Film Device and Technology, P.R. China  Cultisee Coaxial Solar Cells by Electrodeposition  Op. 4 Yoonmook Kang and Donglwan Kim Department of Materials Science and Engineering, Korea University, Korea  Improvement in Surface Morphology of Electrodeposited CuGaSes Thin-Films by Supporting Electrolyte  Op. 5 Yusake Oda <sup>1</sup> , Takashi Minemoto <sup>1</sup> , Hideyuki Takakura <sup>1</sup> and Yoshihiro Hamakawa <sup>1</sup> [College of Science and Engineering, Japan  Cultin GalSes Thin-Film Evolution Durina Se/Ar atmosphere Selenization of Sputtered Metallic Cu-In-Ga Procursors  Lin Zhou, Feng-Yan Li, Chuan-Ming Xu, Yun Sun, Qing He and Zhi-Qiang Zhou Institute of Photoelectronics, Nankai University, P.R.China  Coexistence of Polymorphic Phases in CultoSes Thin Films  Coexistence of Polymorphic Phases in CultoSes Thin Films  Coexistence of Polymorphic Phases in CultoSes Thin Films  Coexistence of Polymorphic Phases in CultoSes Thin Etlins  The Mulli Solar Window  Institute of Photoelectronics, Nankai University, P.R.China 2Department of Physics, University of Science and Technology of China, P.R. China  The Mulli Solar Window  Institute of Photoelectronics, Nankai University, P.R.China 2Department of Physics, University of Science and Technology of China, P.R. China  The First JokW Grid-Connected BIPV Station on Qinahai-Tibetan Plateau  Liu Hong, Chen Huiling, Zhang Zhemin 1Qinghai Provinced New Energy Research In	09-1	
1 Department of Materials Science and Engineering, Korea Advanced Institute of Science and Technology, Korea 2Solar Cell Research Center, Korea Institute of Energy Research, Korea  8 Research On In. Ga-rich CIGS Thin Films  2 Xue Yuming, Sun yun, He qing, Zhang Ii, Xu chuanming, Xiao jianping Institute of Photoelectronic Thin Film Device and Technology, P.R. China  2 Culnse; Coaxial Solar Cells by Electrodeposition  9 Yoonnook Kang and Donghwan Kim Department of Materials Science and Engineering, Korea University, Korea  Improvement in Surface Morphology of Electrodeposited CuGaSeg Thin-Films by Supporting Electrolyte  9 yesake Oda <sup>1</sup> , Takashi Minemoto <sup>1</sup> , Hideyuki Takakura <sup>1</sup> and Yoshihiro Hamakawa <sup>1</sup> 1 College of Science and Engineering, Japan  2 Cu(in GaiSeg Thin-Film Evolution During Sei/Ar atmosphere Selenization of Sputtered Metallic Cu-In-Ga Precunors  1 Lin Zhou, Feng-Yan Li, Chuan-Ming Xu, Yun Sun, Qing He and Zhi-Qiang Zhou Institute of Photoelectronics, Nankai University, P.R. China  2 Coexistence of Polymorphic Phases in CulnSeg Thin Films  3 Chuan-Ming Xu <sup>1</sup> , Yun Sun <sup>1</sup> , Feng-Yan Li <sup>1</sup> , Lin Zhou <sup>1</sup> , Li Zhang <sup>1</sup> , Qing He <sup>1</sup> , Zhi-Qiang Zhou <sup>1</sup> and Hong-Tu Liu <sup>2</sup> 1 Institute of Photoelectronics, Nankai University, P.R. China 2Department of Physics, University of Science and Technology of China, P.R. China  2 The Multi Solar Window  10-1 Eng. Ami Elazari MBA  3 Millennium Electric T.O.U. Ltd., Israel  10-2 Liu Hong, Chen Huiling, Zhang Zhimin  1 Tolonghai Provincial New Energy Research Institute, P.R. China  4 Research of the String Inverter Grid-Connected Photovoltaic System Based on Intelligent Cluster Controller  2 Zhang Xing <sup>1</sup> , Ni Hua <sup>1</sup> , Yao Dan <sup>1</sup> , Xu Po <sup>1</sup> , Cao Ren-xian <sup>2</sup> 1 School of Electrical and Automation Engineering, Hefei University of Technology, P.R. China 2 Hefei Sunlight Power Supply Co. Ltd., P.R. China  3 Simulation of Large-scale Photovolaic Grid-connected Systems  4 Mao Metalpin <sup>2</sup> , Su Jianbau J <sup>12</sup> Zhang Guorong J <sup>2</sup> 1 Research Center for PV System Engineering, P.R.C 2 Insti		Growth and Characterization of a New Double Buffer Layer for Cu(In,Ga)Se <sub>2</sub> Solar Cells
Xue Yuming, Sun yun, He qing, Zhang li, Xu chuanming, Xiao jianping Institute of Photoelectronic Thin Film Device and Technology, P.R. China	09-2	1 Department of Materials Science and Engineering, Korea Advanced Institute of Science and Technology, Korea 2Solar Cell Research
Aue Yunning, Sun yun, He, ang, Arnang H, and Leuchanaming, Xiao yanping Institute of Photoelectronic Thin Filin Device and Technology, P.R. China  CulnSe; Coaxial Solar Cells by Electrodeposition  Yoonmook Kang and Donghwan Kim Department of Materials Science and Engineering, Korea University, Korea  Improvement in Surface Morphology of Electrodeposited CuGsSe; Thin-Films by Supporting Electrolyte  Vusuke Oda <sup>1</sup> , Takashi Minemoto <sup>1</sup> , Hideyuki Takakura <sup>1</sup> and Yoshihiro Hamakawa <sup>1</sup> ICollege of Science and Engineering, Japan  Cufin GalSe; Thin-Film Evolution During Se/Ar atmosphere Selenization of Sputtered Metallic Cu-In-Ga Precursors  Lin Zhou, Feng-Yan Li, Chuan-Ming Xu, Yun Sun, Qing He and Zhi-Qiang Zhou Institute of Photoelectronics, Nankai University, P.R. China  Coexistence of Polymorphic Phases in CuInSe; Thin Films  Op-7  Chuan-Ming Xu <sup>1</sup> , Yun Sun <sup>1</sup> , Feng-Yan Li <sup>1</sup> , Lin Zhou <sup>1</sup> , Li Zhang <sup>1</sup> , Qing He <sup>1</sup> , Zhi-Qiang Zhou <sup>1</sup> and Hong-Tu Liu <sup>2</sup> Institute of Photoelectronics, Nankai University, P.R. China 2Department of Physics, University of Science and Technology of China, P.R. China  The Multi Solar Window  Eng. Ami Elazari MBA  Millemium Electric To.U. Ltd., Israel  The First 10kW Grid-Connected BIPV Station on Oinghai-Tibetan Plateau  Liu Hong, Chen Huiling, Zhang Zhimin  IQinghai Provincial New Energy Research Institute, P.R. China  A Research of the String Inverter Grid-Connected Photovoltaic System Based on Intelligent Cluster Controller  Zhang Xing <sup>1</sup> Ni Hua <sup>1</sup> , Yao Dan <sup>1</sup> , Xu Po <sup>1</sup> , Cao Ren-xian <sup>2</sup> 1School of Electrical and Automation Engineering, Hefei University of Technology, P.R. China 2 Hefei Sunlight Power Supply Co.Ltd.  P.R. China  Simulation of Large-scale Photovoltaic Grid-connected Systems  Mao Meiqin <sup>1,2</sup> , Su Jianhui <sup>1,2</sup> Zhang Guorong <sup>1,2</sup> IResearch Center for PV System Engineering, P.R. C 2 Institute of Energy Research, HeFei University of Technology, P.R. C  Minimizing the Dead layer of Industrial Phosphorous Emitters Formed by POCI <sub>2</sub> Diffusion  11-1  Patrick Choulat <sup>1</sup> , Filip		Research On In, Ga-rich CIGS Thin Films
Voonmook Kang and Donghwan Kim	09-3	Xue Yuming, Sun yun, He qing, Zhang li, Xu chuanming, Xiao jianping Institute of Photoelectronic Thin Film Device and Technology, P.R. China
Popurtment of Materials Science and Engineering, Korea University, Korea  Improvement in Surface Morphology of Electrodeposited CuGaSe <sub>2</sub> Thin-Films by Supporting Electrolyte  Yusuke Oda <sup>1</sup> , Takashi Minemoto <sup>1</sup> , Hideyuki Takakura <sup>1</sup> and Yoshihiro Hamakawa <sup>1</sup> [College of Science and Engineering, Japan  Cufin Ga/Se <sub>2</sub> Thin-Film Evolution During Se/Ar atmosphere Selenization of Sputtered Metallic Cu-In-Ga Precursors  Lin Zhou, Feng-Yan Li, Chuan-Ming Xu, Yun Sun, Qing He and Zhi-Qiang Zhou  Institute of Photoelectronics, Nankai University, P.R.China  Coexistence of Polymorphic Phases in CuInSe <sub>2</sub> Thin Films  O9-7  Chuan-Ming Xu <sup>1</sup> , Yun Sun <sup>1</sup> , Feng-Yan Li <sup>1</sup> , Lin Zhou <sup>1</sup> , Li Zhang <sup>1</sup> , Qing He <sup>1</sup> , Zhi-Qiang Zhou <sup>1</sup> and Hong-Tu Liu <sup>2</sup> Institute of Photoelectronics, Nankai University, P.R.China 2Department of Physics, University of Science and Technology of China, P.R.China  The Multi Solar Window  The First IokW Grid-Connected BIPV Station on Qinghai-Tibetan Plateau  Liu Hong, Chen Huiling, Zhang Zhimin  Qinghai Provincial New Energy Research Institute, P.R. China  A Research of the String Inverter Grid-Connected Photovoltaic System Based on Intelligent Cluster Controller  Zhang Xing <sup>1</sup> , Ni Hua <sup>1</sup> , Yao Dan <sup>1</sup> , Xu Po <sup>1</sup> , Cao Ren-xian <sup>2</sup> School of Electrical and Automation Engineering, Hefei University of Technology, P.R.China 2 Hefei Sunlight Power Supply Co.Ltd, P.R.China  Simulation of Large-scale Photovoltaic Grid-connected Systems  Mao Meiqin <sup>1,2</sup> , Su Jianhui <sup>1,2</sup> , Zhang Guorong <sup>1,2</sup> Research Center for PV System Engineering, P.R.C 2 Institute of Energy Research, Hefei University of Technology, P.R.C  Minimizing the Dead layer of Industrial Phosphorous Emitters Formed by POCl <sub>2</sub> Diffusion  11-1  Patrick Choulat <sup>1</sup> , Filip Duerinckx, Emmanuel Van Kerschaver, Frederic Dross, Guy Beaucarne  IIMEC vzw, Belgium		CuInSe <sub>2</sub> Coaxial Solar Cells by Electrodeposition
Yusuke Oda <sup>1</sup> , Takashi Minemoto <sup>1</sup> , Hideyuki Takakura <sup>1</sup> and Yoshihiro Hamakawa <sup>1</sup> [College of Science and Engineering, Japan  Culfin GalSe <sub>2</sub> Thin-Film Evolution During Se/Ar atmosphere Sclenization of Sputtered Metallic Cu-In-Ga Precursors  Lin Zhou, Feng-Yan Li, Chuan-Ming Xu, Yun Sun, Qing He and Zhi-Qiang Zhou Institute of Photocelectronics, Nankai University, P.R.China  Coexistence of Polymorphic Phases in CulnSe <sub>2</sub> Thin Films  Chuan-Ming Xu <sup>1</sup> , Yun Sun <sup>1</sup> , Feng-Yan Li <sup>1</sup> , Lin Zhou <sup>1</sup> , Li Zhang <sup>1</sup> , Qing He <sup>1</sup> , Zhi-Qiang Zhou <sup>1</sup> and Hong-Tu Liu <sup>2</sup> Ilnstitute of Photocelectronics, Nankai University, P.R.China 2Department of Physics, University of Science and Technology of China, P.R.China  The Multi Solar Window  Eng. Ami Elazari MBA Millennium Electric T.O.U. Ltd., Israel  The First 10kW Grid-Connected BIPV Station on Qinghai-Tibetan Plateau  Liu Hong, Chen Huiling, Zhang Zhimin 1Qinghai Provincial New Energy Research Institute, P.R.China  A Research of the String Inverter Grid-Connected Photovoltaic System Based on Intelligent Cluster Controller  Zhang Xing <sup>1</sup> ,Ni Hua <sup>1</sup> , Yao Dan <sup>1</sup> ,Xu Po <sup>1</sup> , Cao Ren-xian <sup>2</sup> 1School of Electrical and Automation Engineering, Hefei University of Technology, P.R.China 2 Hefei Sunlight Power Supply Co.Ltd., P.R.China  Simulation of Large-scale Photovoltaic Grid-connected Systems  Mao Meiqin <sup>1,2</sup> , Su Jianhui <sup>1,2</sup> ,Zhang Guorong <sup>1,2</sup> 1Research Center for PV System Engineering, P.R.C 2Institute of Energy Research, HeFei University of Technology, P.R.C  Minimizing the Dead layer of Industrial Phosphorous Emitters Formed by POCl <sub>3</sub> Diffusion  Patrick Choulat <sup>1</sup> , Filip Duerinckx, Emmanuel Van Kerschaver, Frederic Dross, Guy Beaucarne IIMEC vzw, Belgium	09-4	
Yusuke Oda <sup>1</sup> , Takashi Minemoto <sup>1</sup> , Hideyuki Takakura <sup>1</sup> and Yoshihiro Hamakawa <sup>1</sup> 1College of Science and Engineering, Japan  Quantum Carlon, Japan Li, Chuan-Ming Xu, Yun Sun, Qing He and Zhi-Qiang Zhou Institute of Photoelectronics, Nankai University, P.R. China  Coexistence of Polymorphic Phases in CuInSe <sub>2</sub> Thin Films  O9-7 Chuan-Ming Xu <sup>1</sup> , Yun Sun <sup>1</sup> , Feng-Yan Li <sup>1</sup> , Lin Zhou <sup>1</sup> , Li Zhang <sup>1</sup> , Qing He <sup>1</sup> , Zhi-Qiang Zhou <sup>1</sup> and Hong-Tu Liu <sup>2</sup> Ilnstitute of Photoelectronics, Nankai University, P.R. China 2Department of Physics, University of Science and Technology of China, P.R. China  The Multi Solar Window  Eng. Ami Elazari MBA  Millennium Electric T.O.U. Ltd., Israel  The First 10kW Grid-Connected BIPV Station on Qinghai-Tibetan Plateau  Liu Hong, Chen Huiling, Zhang Zhimin 1Qinghai Provincial New Energy Research Institute, P.R. China  A Research of the String Inverter Grid-Connected Photovoltaic System Based on Intelligent Cluster Controller  Zhang Xing <sup>1</sup> , Ni Hua <sup>1</sup> , Yao Dan <sup>1</sup> , Xu Po <sup>1</sup> , Cao Ren-xian <sup>2</sup> 1School of Electrical and Automation Engineering, Hefei University of Technology, P.R. China 2 Hefei Sunlight Power Supply Co.Ltd, P.R. China  Simulation of Large-scale Photovoltaic Grid-connected Systems  Mao Meiqin <sup>1,2</sup> , Su Jianhui <sup>1,2</sup> , Zhang Guorong <sup>1,2</sup> 1Research Center for PV System Engineering, P.R.C 2Institute of Energy Research, HeFei University of Technology, P.R.C  Minimizing the Dead layer of Industrial Phosphorous Emitters Formed by POCl <sub>2</sub> Diffusion  Patrick Choulat <sup>1</sup> , Filip Duerinckx, Emmanuel Van Kerschaver, Frederic Dross, Guy Beaucarne 11MEC vzw, Belgium		Improvement in Surface Morphology of Electrodeposited CuGaSe <sub>2</sub> Thin-Films by Supporting Electrolyte
Lin Zhou, Feng-Yan Li, Chuan-Ming Xu, Yun Sun, Qing He and Zhi-Qiang Zhou Institute of Photoelectronics, Nankai University, P.R.China	09-5	
Institute of Photoelectronics, Nankai University, P.R.China  Coexistence of Polymorphic Phases in CulnSe <sub>2</sub> Thin Films  Chuan-Ming Xu <sup>1</sup> , Yun Sun <sup>1</sup> , Feng-Yan Li <sup>1</sup> , Lin Zhou <sup>1</sup> , Li Zhang <sup>1</sup> , Qing He <sup>1</sup> , Zhi-Qiang Zhou <sup>1</sup> and Hong-Tu Liu <sup>2</sup> Ilnstitute of Photoelectronics, Nankai University, P.R.China 2Department of Physics, University of Science and Technology of China, P.R.China  The Multi Solar Window  Eng. Ami Elazari MBA Millennium Electric T.O.U. Ltd., Israel  The First 10kW Grid-Connected BIPV Station on Qinghai-Tibetan Plateau  Liu Hong, Chen Huiling, Zhang Zhimin 1Qinghai Provincial New Energy Research Institute, P.R.China  A Research of the String Inverter Grid-Connected Photovoltaic System Based on Intelligent Cluster Controller  Zhang Xing <sup>1</sup> , Ni Hua <sup>1</sup> , Yao Dan <sup>1</sup> , Xu Po <sup>1</sup> , Cao Ren-xian <sup>2</sup> 1School of Electrical and Automation Engineering, Hefei University of Technology, P.R.China 2 Hefei Sunlight Power Supply Co.Ltd, P.R.China  Simulation of Large-scale Photovoltaic Grid-connected Systems  Mao Meiqin <sup>1-2</sup> , Su Jianhui <sup>1,2</sup> Zhang Guorong <sup>1-2</sup> 1Research Center for PV System Engineering, P.R.C 2Institute of Energy Research, HeFei University of Technology, P.R.C  Minimizing the Dead layer of Industrial Phosphorous Emitters Formed by POCl <sub>3</sub> Diffusion  Patrick Choulat <sup>1</sup> , Filip Duerinckx, Emmanuel Van Kerschaver, Frederic Dross, Guy Beaucarne 11MEC vzw, Belgium		Cu(In,Ga)Se <sub>2</sub> Thin-Film Evolution During Se/Ar atmosphere Selenization of Sputtered Metallic Cu-In-Ga Precursors
Chuan-Ming Xu¹, Yun Sun¹, Feng-Yan Li¹, Lin Zhou¹, Li Zhang¹, Qing He¹, Zhi-Qiang Zhou¹ and Hong-Tu Liu² IInstitute of Photoelectronics, Nankai University, P.R.China 2Department of Physics, University of Science and Technology of China, P.R.China  The Multi Solar Window  Eng. Ami Elazari MBA Millennium Electric T.O.U. Ltd., Israel  The First 10kW Grid-Connected BIPV Station on Qinghai-Tibetan Plateau  Liu Hong, Chen Huiling, Zhang Zhimin 1Qinghai Provincial New Energy Research Institute, P.R.China  A Research of the String Inverter Grid-Connected Photovoltaic System Based on Intelligent Cluster Controller  Zhang Xing¹, Ni Hua¹, Yao Dan¹, Xu Po¹, Cao Ren-xian² 1School of Electrical and Automation Engineering, Hefei University of Technology, P.R.China 2 Hefei Sunlight Power Supply Co.Ltd. P.R.China  Simulation of Large-scale Photovoltaic Grid-connected Systems  Mao Meiqin¹², Su Jianhui ¹², Zhang Guorong¹² 1Research Center for PV System Engineering, P.R.C 2Institute of Energy Research, HeFei University of Technology, P.R.C  Minimizing the Dead layer of Industrial Phosphorous Emitters Formed by POCl₃ Diffusion  Patrick Choulat¹, Filip Duerinckx, Emmanuel Van Kerschaver, Frederic Dross, Guy Beaucarne 11MEC vzw, Belgium	09-6	
Institute of Photoelectronics, Nankai University, P.R.China 2Department of Physics, University of Science and Technology of China, P.R.China  The Multi Solar Window  Eng. Ami Elazari MBA Millennium Electric T.O.U. Ltd., Israel  The First 10kW Grid-Connected BIPV Station on Oinghai-Tibetan Plateau  Liu Hong, Chen Huiling, Zhang Zhimin 1Qinghai Provincial New Energy Research Institute, P.R.China  A Research of the String Inverter Grid-Connected Photovoltaic System Based on Intelligent Cluster Controller  Zhang Xing <sup>1</sup> , Ni Hua <sup>1</sup> , Yao Dan <sup>1</sup> , Xu Po <sup>1</sup> , Cao Ren-xian <sup>2</sup> 1School of Electrical and Automation Engineering, Hefei University of Technology, P.R.China 2 Hefei Sunlight Power Supply Co.Ltd, P.R.China  Simulation of Large-scale Photovoltaic Grid-connected Systems  Mao Meiqin <sup>1,2</sup> , Su Jianhui <sup>1,2</sup> , Zhang Guorong <sup>1,2</sup> 1Research Center for PV System Engineering, P.R.C 2Institute of Energy Research, HeFei University of Technology, P.R.C  Minimizing the Dead layer of Industrial Phosphorous Emitters Formed by POCl <sub>3</sub> Diffusion  Patrick Choulat <sup>1</sup> , Filip Duerinckx, Emmanuel Van Kerschaver, Frederic Dross, Guy Beaucarne 11MEC vzw, Belgium		Coexistence of Polymorphic Phases in CuInSe <sub>2</sub> Thin Films
10-1 Eng. Ami Elazari MBA Millennium Electric T.O.U. Ltd., Israel  The First 10kW Grid-Connected BIPV Station on Qinghai-Tibetan Plateau  Liu Hong, Chen Huiling, Zhang Zhimin 1Qinghai Provincial New Energy Research Institute, P.R.China  A Research of the String Inverter Grid-Connected Photovoltaic System Based on Intelligent Cluster Controller  Zhang Xing¹, Ni Hua¹, Yao Dan¹, Xu Po¹, Cao Ren-xian² 1School of Electrical and Automation Engineering, Hefei University of Technology, P.R.China 2 Hefei Sunlight Power Supply Co.Ltd, P.R.China  Simulation of Large-scale Photovoltaic Grid-connected Systems  Mao Meiqin¹², Su Jianhui ¹², Zhang Guorong¹² 1Research Center for PV System Engineering, P.R.C 2Institute of Energy Research, HeFei University of Technology, P.R.C  Minimizing the Dead layer of Industrial Phosphorous Emitters Formed by POCl₃ Diffusion  11-1 Patrick Choulat¹, Filip Duerinckx, Emmanuel Van Kerschaver, Frederic Dross, Guy Beaucarne 11MEC vzw, Belgium	09-7	1 Institute of Photoelectronics, Nankai University, P.R.China 2Department of Physics, University of Science and Technology of China,
Eng. Ami Elazari MBA Millennium Electric T.O.U. Ltd., Israel  The First 10kW Grid-Connected BIPV Station on Qinghai-Tibetan Plateau  Liu Hong, Chen Huiling, Zhang Zhimin 1Qinghai Provincial New Energy Research Institute, P.R.China  A Research of the String Inverter Grid-Connected Photovoltaic System Based on Intelligent Cluster Controller  Zhang Xing <sup>1</sup> , Ni Hua <sup>1</sup> , Yao Dan <sup>1</sup> , Xu Po <sup>1</sup> , Cao Ren-xian <sup>2</sup> 1School of Electrical and Automation Engineering, Hefei University of Technology, P.R.China 2 Hefei Sunlight Power Supply Co.Ltd, P.R.China  Simulation of Large-scale Photovoltaic Grid-connected Systems  Mao Meiqin <sup>1,2</sup> , Su Jianhui <sup>1,2</sup> , Zhang Guorong <sup>1,2</sup> 1Research Center for PV System Engineering, P.R.C 2Institute of Energy Research, HeFei University of Technology, P.R.C  Minimizing the Dead layer of Industrial Phosphorous Emitters Formed by POCl <sub>3</sub> Diffusion  Patrick Choulat <sup>1</sup> , Filip Duerinckx, Emmanuel Van Kerschaver, Frederic Dross, Guy Beaucarne 11MEC vzw, Belgium		The Multi Solar Window
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Liu Hong, Chen Huiling, Zhang Zhimin 1 Qinghai Provincial New Energy Research Institute, P.R.China  A Research of the String Inverter Grid-Connected Photovoltaic System Based on Intelligent Cluster Controller  Zhang Xing <sup>1</sup> , Ni Hua <sup>1</sup> , Yao Dan <sup>1</sup> , Xu Po <sup>1</sup> , Cao Ren-xian <sup>2</sup> 1 School of Electrical and Automation Engineering, Hefei University of Technology, P.R.China 2 Hefei Sunlight Power Supply Co.Ltd, P.R.China  Simulation of Large-scale Photovoltaic Grid-connected Systems  Mao Meiqin <sup>1,2</sup> , Su Jianhui <sup>1,2</sup> , Zhang Guorong <sup>1,2</sup> 1 Research Center for PV System Engineering, P.R.C 2 Institute of Energy Research, HeFei University of Technology, P.R.C  Minimizing the Dead layer of Industrial Phosphorous Emitters Formed by POCl <sub>3</sub> Diffusion  Patrick Choulat <sup>1</sup> , Filip Duerinckx, Emmanuel Van Kerschaver, Frederic Dross, Guy Beaucarne 1 IMEC vzw, Belgium		The First 10kW Grid-Connected BIPV Station on Qinghai-Tibetan Plateau
2 Zhang Xing¹,Ni Hua¹, Yao Dan¹,Xu Po¹, Cao Ren-xian² 1 School of Electrical and Automation Engineering, Hefei University of Technology, P.R.China 2 Hefei Sunlight Power Supply Co.Ltd, P.R.China  Simulation of Large-scale Photovoltaic Grid-connected Systems  Mao Meiqin¹²², Su Jianhui ¹²²,Zhang Guorong¹²² 1 Research Center for PV System Engineering, P.R.C 2Institute of Energy Research, HeFei University of Technology, P.R.C  Minimizing the Dead layer of Industrial Phosphorous Emitters Formed by POCl₃ Diffusion  Patrick Choulat¹, Filip Duerinckx, Emmanuel Van Kerschaver, Frederic Dross, Guy Beaucarne 1 IMEC vzw, Belgium	10-2	
10-4  Simulation of Large-scale Photovoltaic Grid-connected Systems  Mao Meiqin <sup>1,2</sup> , Su Jianhui <sup>1,2</sup> , Zhang Guorong <sup>1,2</sup> 1Research Center for PV System Engineering, P.R.C 2Institute of Energy Research, HeFei University of Technology, P.R.C  Minimizing the Dead layer of Industrial Phosphorous Emitters Formed by POCl <sub>3</sub> Diffusion  Patrick Choulat <sup>1</sup> , Filip Duerinckx, Emmanuel Van Kerschaver, Frederic Dross, Guy Beaucarne 1IMEC vzw, Belgium		A Research of the String Inverter Grid-Connected Photovoltaic System Based on Intelligent Cluster Controller
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Mao Meiqin 1-2, Su Jianhui 1-2, Zhang Guorong 1-2 IResearch Center for PV System Engineering, P.R.C 2Institute of Energy Research, HeFei University of Technology, P.R.C  Minimizing the Dead layer of Industrial Phosphorous Emitters Formed by POCl <sub>3</sub> Diffusion  Patrick Choulat 1, Filip Duerinckx, Emmanuel Van Kerschaver, Frederic Dross, Guy Beaucarne IIMEC vzw, Belgium		Simulation of Large-scale Photovoltaic Grid-connected Systems
Patrick Choulat <sup>1</sup> , Filip Duerinckx, Emmanuel Van Kerschaver, Frederic Dross, Guy Beaucarne 1IMEC vzw, Belgium	10-4	Mao Meiqin <sup>1,2</sup> , Su Jianhui <sup>1,2</sup> , Zhang Guorong <sup>1,2</sup> 1Research Center for PV System Engineering, P.R.C 2Institute of Energy Research, HeFei University of Technology, P.R.C
Patrick Choulat <sup>1</sup> , Filip Duerinckx, Emmanuel Van Kerschaver, Frederic Dross, Guy Beaucarne 1IMEC vzw, Belgium		Minimizing the Dead layer of Industrial Phosphorous Emitters Formed by POCl <sub>3</sub> Diffusion
11-2 Impact of a SiN Barrier Layer on EVA Polycrystalline Silicon Thin-Film Solar Cells	11-1	
	11-2	Impact of a SiN Barrier Layer on EVA Polycrystalline Silicon Thin-Film Solar Cells

	Dengyuan Song, Per I. Widenborg, Mason L. Terry and Armin G. Aberle Centre of Excellence for Advanced Silicon Photovoltaics and Photonics, Australia
	I-V Characteristic Modeling of in-field Aged Polysilicon Solar Cells
11-3	K. Ben Ali <sup>1</sup> , A. S. Bouazzi <sup>1</sup> , M. Zagdoudi <sup>2</sup> and M. Fathallah <sup>2</sup> 1 ENIT -LPMS, University of Tunis El Manar, Tunisia 2 ESSTT, University of Tunis, Tunisia
	Silicon Epitaxy on Large-Area Substrates (43×43cm²) by Convection-Assisted Chemical Vapor Deposition (CoCVD)
11-4	T. Kunz <sup>1</sup> , I. Burkert <sup>1</sup> , M. Grosch <sup>1</sup> , R. Auer <sup>1</sup> , and M. Schulz <sup>1,2</sup> 1 Bavarian Center for Applied Energy Research (ZAE Bayern), Germany 2 Institut für Angewandte Physik, Universität Erlangen-Nürnberg, Germany
	Analysis of Thin Monocrystalline Silicon Solar Cell by Photographic Surveying
11-5	Yu Takahashi, Yasue Kaji, Akiyoshi Ogane, Yukiharu Uraoka and Takashi Fuyuki Graduate School of Materials Science, Nara Institute of Science and Technology, Japan
	Thin Silicon Solar Cell by Layer Transfer Process Using QMPS as Active Layer-Challenges and Prospects
11-6	M. Banerjee <sup>1</sup> , S. K. Datta <sup>2</sup> , U. Gangopadhyay <sup>3</sup> & H. Saha <sup>1</sup> 1IC Design & Fabrication Centre, Electronics & Tele-communication Engineering Department, Jadavpur University, India 2Department of Physics 3School of Electrical and Computer Engineering, Sungkyunkwan University, S.Korea
	Manufacturing Large Area Monocrystalline Silicon Thin-Film Solar Cells by applying the PSI-Process
11-7	Barbara Terheiden, Renate Horbelt, and Rolf Brendel Institut für Solarenergieforschung GmbH Hameln (ISFH), Germany,
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22-7	A. Alemu <sup>1</sup> , J. A. H. Coaquira and A. Freundlich Photovoltaics and Nanostructures Laboratories, Center for Advanced Materials and Physics Department, University of Houston, USA,
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22-8	Jean-Francois Guillemoles <sup>1,2</sup> , Gavin Conibeer <sup>1</sup> , Martin Green <sup>1</sup> 1Centre of Excellence for Advanced Silicon Photovoltaics and Photonics, University of New South Wales, Paris,
	Investigation of Current Matching on Triple Junction Cell for Concentrator Application
23-1	Hiroyuki Juso, Atsushi Yoshida, Takaaki Agui, Kazuyo Nakamura, Kazuaki Sasaki, Tatsuya Takamoto, Masao Tanaka, Minoru Kaneiwa, and Kohji Okamoto Soler System Group, Japan,
	Numerical Simulation of GaAs/Si Heterojunction Solar Cells
23-2	P.Q. Luo <sup>1</sup> *, Z.B. Zhou <sup>1</sup> , W. Jiang <sup>1</sup> , Z.G. Liu <sup>1</sup> , H.C. Yu <sup>1</sup> , S.W. Ku <sup>1</sup> , Q.H. Ye <sup>1</sup> , R.Q. Cui <sup>1</sup> , X.M. Dou <sup>1</sup> , J.L. Tu <sup>2</sup> , M.B. Chen <sup>2</sup> 1Solar Energy Inst., Dept. of Physics, Shanghai Jiao Tong Univ., P.R. China, 2Shanghai Institute of Space Power Sources, P.R. China
	Impurities in GaAsN Grown by Chemical Beam Epitaxy Using Monomethylhydrazine or Dimethylhidrazine as N Precursor
23-3	H. Suzuki <sup>1</sup> , K. Nishimura <sup>1</sup> , H. S. Lee <sup>1</sup> , Y. Ohshita <sup>1</sup> , I. Gono <sup>2</sup> , N. Kojima <sup>1</sup> and M. Yamaguchi <sup>1</sup> 1Toyota Technological Institute, Japan, 2 Aichi Steel, Japan,
	Improvements of Cell Properties by Thermal Cycle Annealing in Lattice-mismatched InGaAs
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23-5	Enhancing GaSb/GaAs TPV Performance Using an Offset p-n Junction

O, Fan 1, B. McQuillar' and Y. Xe'  1. Department of Materials, Oxen Mary College, University of Lendon, UK 25chool of Engineering, Sheffield Hallam University, UK 3 Beijing Solar Energy Research Institute, China  Performance Department of Materials, Oxen Mary College, University of Lendon, UK 25chool of Engineering, Sheffield Hallam University, UK 3 Beijing Solar Energy Research Institute, China  Performance Department of Materials, December May College, University of London, UK 3 School of Engineering, Sheffield Hallam University, UK 162 Like V 12 aboratory of Hearn Technology and Materials Modification of Vinistry of Education Beijing Normal University, China 2 Department of Materials, December 1985 and Sheffield, UK Sleiping Institute of Sodar Energy, China 2 The School of Physics and Engineering, Sheffield Hallam University, UK 4P/SMC Like V 12 Engineering Sheffield Hallam University, UK 4P/SMC Like V 12 Engineering Asserting Materials and Sodar Medicles  Study of Techniques for Encandating Glass-alass Solar Medicles  Study of Techniques for Encandating Glass-alass Solar Medicles  24-1 Zhang Zhan <sup>12</sup> , Shen Bahi, La Wan ping <sup>1</sup> 1 Guangelbon Pearl Fearl River Telecoon. Equipment Manufacturing Co. Ltd., China 2 The School of Physics and Engineering, Phongham University, China Plant Pla		
R. Wanga, Q. Fana, b. JB, Yanga, XF. Suna, B. McQuilline, G. Hilld, J. Robertsd, and Y. Xue  Rey Laboratory of Beam Technology and Materials Modification of Ministry of Education Beijing Normal University, China  2Department of Materials, Queen May College, University of London, U. S. School of Engineering, Sheffield Hallam University, UK  4EFSKC IH-VF Sectlist, University of Sheffield, U.S. Stepling Institute of Solar Energy, China  Study of Techniques for Enconoulatine Class-class Solar Medicals  Study of Techniques for Enconoulatine Class-class Solar Medicals  24-1 Zhang Zheni <sup>2</sup> , Shen Hui <sup>2</sup> , Li Wan pingi  1 Guangzhou Pearl Pearl River Telectron, Equipment Manufacturing Co. Ltd., China 2 The School of Physics and Engineering, Zhongshan University, China  24-2 Yang Hongxing and Fung Yuyan  Renevable Energy Research Group (RFRG), The Hong Kong Polytechnic University, Hung Horn, Hong Kong,  An Evaluation Method of Area dependency Equalization of Output Fluctuation from Distributed PV System by Using Frequency  Analysis  And Rechark KUROKAWA <sup>1</sup> 1 Takyo University of Agriculture and Technology, Japan 2 National Institute of Advanced Industrial Science and Technology (AIST)  3 Medicesha Corporation, 4 Kandenko co., Ind. 5 Nibon University  Denzar Cruz Martins, Douglas P. da Silva, Andre S. de Andrade, Antonio J. B. Bottion and Rieber C. A. de Souza  Department of Electrical Engeneering, Federal University of Santa Catarina,—Floranopois, S.C. Brazil,  1 Pha Application of Neural Network in MPPT of Solar Army  Study and Delivers of Computer Science and Technology, Japan 10 Study Sciences, P. R. China  24-5 Shenghi Xia, Gengheo Zhao, Qingzhang Wang, Yu Wang  1 Kay Laboratory of Opto-electronic Information Science and Technology, Ministry of Education Institute of Photo and Electronics Device and Technology, Nanakai University, P. R. China  24-6 Kinghammer, Winfried <sup>1</sup> : Ma Shenghong <sup>2</sup> : Noceonberg, Rosstantin <sup>2</sup> 1 Dockst-Constit Grabble Implementation of a Large-Scale Program on PV Hybrid Village Power Plants in W		1.Department of Materials, Queen Mary College, University of London, UK 2School of Engineering, Sheffield Hallam University, UK
18cy Laboratory of Beam Technology and Materials Modification of Ministry of Education Beijing Normal University, China 2Department of Materials, Queen May College, University of London, UK School of Engineering, Sheffleld Hallam University, UK 4FPSRC III-V Facility, University of Sheffleld, UK Shejing Institute of Solar Energy, China  Study of Techniques for Encapoulating Glass-alsas Solar Modules  24-1  Zhang Zhon Pari Pant River Telecom. Equipment Manufacturing Co. Ltd., China 2 The School of Physics and Engineering, Zhongshan University, China,  Building-Integrated Photovolatics: Its' Past, Present and Future Applications in Hong Kong.  An Evaluation Method of Area-dependency Equalization of Output Fluctuation from Distributed PV System by Using Frequency Analysis  24-3  Northro KAWASAKI <sup>1</sup> , Takashi OOZEKI <sup>1</sup> , Kenji OTANI <sup>3</sup> , Kiyoyida KITAMURA <sup>3</sup> , Hiroyuki SUGHIARA <sup>4</sup> , Shogo NISHIKAWA <sup>3</sup> , and Konake KUROKAWA <sup>3</sup> 1 Tokyo University of Agriculture and Technology, Japan, 2 National Institute of Advanced Industrial Science and Technology (AIST) 3 Medicasha Corporation, 4 Kandenko co., Isl., 5 Nihon Intiversity  Application of the Photovolais: Solar Energy in the Residential Refinerator Suprov  Application of the Photovolais: Solar Energy in the Residential Refinerator Suprov  Denizar Cruz Martins, Douglas P. da Silva, Anale's de Andrade, Annonio J. B. Bottion and Kleber C. A. de Soura Department of Plentrial Engineering, Federal University of Santa Caratina, —Florianopolis, S. C. Brazil.  Ibe Application of Neural Network in MPPT of Solar Arme  Shengthi Xu, Gengelom Also, Oingshing Wang, Yu Wang  Ise Special Consult Cindhi, Germany Linching of Selected Program on PV Hybrid Village Power Plants in Western China  Kingharmare, Winfried <sup>1</sup> , Ma Shenghong <sup>2</sup> ; Nocreuberg, Korostantin <sup>3</sup> 1 Project-Consult Cindhi, Germany 2 Institute of Flexifical Program on PV Hybrid Village Power Plants in Western China  Stude on D-UPFC in the Clustered PV System with Grid  Kyungsoo Lee, Kosake Kurokawa  Tokyo University of		Performance Degradation of GaAs Multi Quantum well Solar Cells after Proton Irradiation
24-1 Zhang Zheon <sup>13</sup> , Shen Hui <sup>2</sup> , Li Wan ping <sup>1</sup> 1 Guangzhou Pearl Pearl River Telecom. Equipment Manufacturing Co. Ltd., China 2 The School of Physics and Engineering. Zhongshan University, China.  Building-Integrated Photovoltaics. Its Past. Present and Future Applications in Hong Kong.  Building-Integrated Photovoltaics. Its Past. Present and Future Applications in Hong Kong.  An Evaluation Method of Area-dependency Equalization of Output Fluctuation from Distributed PV System by Using Frequency Analysis  24-3 Norihiro KAWASAKI <sup>1</sup> , Takashi OOZEKI <sup>1</sup> , Kenji OTANI <sup>2</sup> , Kiyoyuki KITAMURA <sup>3</sup> , Hiroyuki SUGHHARA <sup>4</sup> , Shogo NISHIKAWA <sup>3</sup> and Kosake KIROKAWA <sup>1</sup> Tokyo University of Agriculture and Technology, Japan. 2 National Institute of Advanced Industrial Science and Technology (AIST) 3 Meidensha Corporation, 4 Kandenko co., Id. 5 Nihon University  Application of the Photovoltaic Solar Energy in the Residential Refrigerator Supry.  Application of Memilian Photovoltaic Solar Energy in the Residential Refrigerator Supry.  Application of Neural Network in MPPT of Solar Arrax.  The Application of Neural Network in MPPT of Solar Arrax.  Shengzhi Xu, Gengshen Zhao, Qingzhang Wang, Yu Wang IKey Laboratory of Opto-electronic Information Science and Technology, Ministry of Education Institute of Photo and Electronics Device and Technology, Naniac Liviersity, P.R.China.  Eirst Experiences swith the Implementation of a Large-Scale Program on PV Hybrid Village Power Plants in Western China Klinghammer, Winfried <sup>3</sup> ; Ma Shenghong <sup>3</sup> ; Noerenberg, Konstantin <sup>1</sup> 1 Projekt-Consult GmbH, Germany 2 Institute of Electrical Engineering/IKD, Chinese Academy of Sciences, P.R. China Study on D-LIPFC in the Clustered PV System with Grid  Kyungsoo Lee, Kosuke Kurokawa Tokyo University of Agriculture & Technology, Japan  Design and Application Considerations of Grid-Connected Photovoltaic Inverters for International Markets  Raymond M, Hudson <sup>1</sup> and Dr. Renjig Xu <sup>2</sup> Xantrex Technology In Residency Agriculture & Technology, Japan  E	23-6	1Key Laboratory of Beam Technology and Materials Modification of Ministry of Education Beijing Normal University, China 2Department of Materials, Queen Mary College, University of London, UK 3School of Engineering, Sheffield Hallam University, UK
1 Guinagzhou Pearl Pearl River Telecom. Equipment Manufacturing Co. Ltd., China 2 The School of Physics and Engineering, Zhongshan University, China,  Building-Integrated Photovoltaics: 1sc Past, Present and Future Applications in Hong Kong Yang Hongxing and Fung Yuyan Renewable Energy Research Group (RERG), The Hong Kong Polytechnic University, Hung Hom, Hong Kong, An Evaluation Method of Area-dependency Equalization of Output Fluctuation from Distributed PV System by Using Frequency Analysis  24-3 Northiro KAWASAKI <sup>1</sup> , Takashi OOZEKI <sup>1</sup> , Kenji OTANI <sup>2</sup> , Kiyoyuki KITAMURA <sup>3</sup> , Hiroyuki SUGHARA <sup>4</sup> , Shogo NISHIKAWA <sup>3</sup> , and Kosuke KUROKAWA <sup>3</sup> 1 Tokyo University Of Agriculture and Technology, Japan, 2 National Institute of Advanced Industrial Science and Technology (AIST) 3 Meidensha Corporation, 4 Kandenko co., Itd, 5 Nihon University  Application of the Photovoltuic Solar Energy in the Residential Refrigerator Suppy  24-4 Denizar Cruz Martins, Douglas P da Silva, André S de Andrade, Antonio J B Bottion and Kleber C. A. de Souza Department of Electrical Engeneering, Federal University of Stata Catarina, - Florianopolis, SC - Bruzil,  The Application of Neural Network in MPPT of Solar Array  24-5 Shengzhi Xu, Gengshen Zhao, Qingzhang Wang, Yu Wang IKey I aboratory of Opto-electronic Information Science and Technology, Ministry of Education Institute of Photo and Electronics Device and Technology, Sankai University, P. R. China,  Erist Experiences with the Implementation of a Large-Scale Program on PV Hybrid Village Power Plants in Western China  Klinghammer, Winfried <sup>1</sup> ; Ma Shenghong <sup>2</sup> ; Noerenberg, Konstantin <sup>1</sup> 1 Projekt-Consult Gribhl, Germany 2 Institute of Electrical Engineering/IKD, Chinese Academy of Sciences, P.R. China  Study on D-UPPC in the Clustered PV System with Grid  Kyungsoo Lee, Kosuke Kurokawa Tokyo University of Agriculture & Technology, Japan  Design and Application Considerations of Grid-Connected Photovoltaic Invertors for International Markets  Raymond M. Hudson <sup>1</sup> and Dr. Renjie		Study of Techniques for Encapsulating Glass-glass Solar Modules
24-2 Yang Hongxing and Fung Yuyan Renewable Energy Research Group (RERG), The Hong Kong Polytechnic University, Hung Hom, Hong Kong,  An Evaluation Method of Area-dependency Equalization of Output Fluctuation from Distributed PV System by Using Frequency Analysis  24-3 Northiro KAWASAKI <sup>1</sup> , Takashi OOZEKI <sup>1</sup> , Kenji OTANI <sup>2</sup> , Kiyoyuki KITAMURA <sup>3</sup> , Hiroyuki SUGHARA <sup>4</sup> , Shogo NISHIKAWA <sup>5</sup> , and Kosuke KUROKAWA <sup>1</sup> 1 Tokyo University of Agriculture and Technology, Japan, 2 National Institute of Advanced Industrial Science and Technology (AIST) 3 Medersha Corporation, 4 Kandehako co., Ind. 5 Nihon University  Application of the Photovoltaic Solar Energy in the Residential Refrigerator Suppy  Denizar Cruz Martins, Douglas P. da Silva, André S. de Andrade, Antonio J. B. Bottion and Kleber C. A. de Souza Department of Electrical Engeneering, Federal University of Santa Catarina, – Florianshpolis, SC Brazil,  The Application of Neural Network in MPPT of Solar Army.  Shengzhi Xu, Gengshen Zhao, Qingzhang Wang, Yu Wang IKey Laboratory of Opta-electronic Information Science and Technology, Ministry of Education Institute of Photo and Electronics Device and Technology, Nanisal University, P.R. China,  First Experiences with the Implementation of a Large-Scale Program on PV Hybrid Village Power Plants in Western China  Klinghammer, Winfried <sup>1</sup> ; Ma Shenghong <sup>2</sup> ; Noerenberg, Konstantial  Phojekt-Consult GmBH, Germany 2 Institute of Electrical Engineering/IKD, Chinese Academy of Sciences, P.R. China  Sludy on D-UPPC in the Clustered PV System with Grid  Kyungsoo Lee, Kosuke Kurokawa Tokyo University of Agriculture & Technology, Japan  Design and Application Considerations of Grid-Connected Photovoltaic Inverters for International Markets  Raymond M. Hudson <sup>1</sup> and Dr. Renjie Xu <sup>2</sup> Xantex Technology Inc. USA I Vice President Advanced Technology, 2Senior Power Electronics Engineer,  Surface Passivation of Crystalline Silicon Solar Cells by High-Pressur Thermal Oxidation at Low Temperature  H. Sai <sup>1</sup> , K. Yamanshita <sup>1</sup> ,	24-1	1 Guangzhou Pearl Pearl River Telecom. Equipment Manufacturing Co. Ltd., China 2 The School of Physics and Engineering,
An Evaluation Method of Area-dependency Equalization of Output Fluctuation from Distributed PV System by Using Frequency Analysis  24-3 Northiro KAWASAKI <sup>1</sup> , Takashi OOZEKI <sup>1</sup> , Kenji OTANI <sup>2</sup> , Kiyoyuki KITAMURA <sup>3</sup> , Hiroyuki SUGIHARA <sup>4</sup> , Shogo NISHIKAWA <sup>3</sup> , and Kosuke KUROKAWA <sup>3</sup> 1 Tokyo University of Agriculture and Technology, Japan. 2 National Institute of Advanced Industrial Science and Technology (AIST) 3 Meidensha Corporation, 4 Kandenko co., Ind. 5 Nihon University  24-4 Denizar Cruz Martins, Douglas P, da Silva, André S, de Andrade, Antonio J, B. Bottion and Kleber C. A. de Souza Department of Electrical Engeneering, Federal University of Santa Calarina, Floriandpolis, SC - Brazil,  The Application of Neural Network in MPPT of Solar Array.  24-5 Shengzhi Xu, Gengshen Zhao, Qingzhang Wang, Yu Wang IKey Laboratory of Opto-Geteronic Information Science and Technology, Ministry of Education Institute of Photo and Electronics Device and Technology, Nankai University, P.R. China.  24-6 Kinghammer, Winfried <sup>1</sup> ; Ma Shenghong <sup>2</sup> ; Noerenberg, Konstantin <sup>1</sup> 1 Projekt-Consult GmbH, Germany 2 Institute of Electrical Engineering/IKD, Chinese Academy of Sciences, P.R. China  24-7 Kyungsoo Lee, Kosuke Kurokawa Tokyo University of Agriculture & Technology, Japan  24-8 Raymond M. Hudson <sup>1</sup> and Dr. Renjie Xu <sup>2</sup> 24-8 Raymond M. Hudson <sup>1</sup> and Dr. Renjie Xu <sup>2</sup> 24-8 Raymond M. Hudson <sup>1</sup> and Dr. Renjie Xu <sup>2</sup> 24-8 Raymond M. Hudson <sup>1</sup> and Dr. Renjie Xu <sup>2</sup> 25-1 H. Sai <sup>1</sup> , K. Yamashita <sup>1</sup> , N. Yamamoto <sup>2</sup> , R. Imai <sup>1</sup> , T. Ishiwata <sup>1</sup> , K. Arafune  1, Japan, Zlshikawajima-Harima Heavy Industries Co., Ltd., Japan  Electric and Crystalline Silicon Solar Cells by High-Pressure Thermal Oxidation at Low Temperature  25-1 Clinkao Okamoto <sup>1</sup> , Takashi Minemoto <sup>1</sup> , Mikio Murozono <sup>2</sup> , Hideyuki Takakura <sup>1</sup> and Yoshihiro Hamakawa <sup>1</sup> ICollege of Science and Engineering, Ritsumekan University, Japan 2Clean Venture 21 Co., Japan  Electric and Crystalline Effect in High-Efficiency Silicon Solar Cells  25-3 Raymson, M. Cudzinov		Building-Integrated Photovoltaics: Its' Past, Present and Future Applications in Hong Kong
Analysis  Norihiro KAWASAKI <sup>1</sup> , Takashi OOZEKI <sup>1</sup> , Kenji OTANI <sup>2</sup> , Kiyoyuki KITAMURA <sup>3</sup> , Hiroyuki SUGIHARA <sup>4</sup> , Shogo NISHIKAWA <sup>3</sup> , and Kosuke KUROKAWA <sup>1</sup> 1 Tokyo University of Agriculture and Technology, Japan, 2 National Institute of Advanced Industrial Science and Technology (AIST) 3 Meddensha Corporation, 4 Kandenko co., Ind., 5 Nihon University  Application of the Photovoltaic Solar Energy in the Residential Refrigerator Suppy  Application of the Photovoltaic Solar Energy in the Residential Refrigerator Suppy  Denizar Cruz Martins, Douglas P. da Silva, André S. de Andrade, Antonio J. B. Bottion and Kleber C. A. de Souza Department of Electrical Engencering, Federal University of Santa Catarina, – Florianôpolis, SC - Brazil,  The Application of Neural Network in MPPT of Solar Array  Shengahi Xu, Gengshen Zhao, Qingzhang Wang, Yu Wang 1Key Laboratory of Opto-electronic Information Science and Technology, Ministry of Education Institute of Photo and Electronics Device and Technology, Nankai University, P. R. China,  First Experiences with the Implementation of a Large-Scale Program on PV Hybrid Village Power Plants in Western China  Klinghammer, Winfried <sup>1</sup> Ma Shenghong <sup>2</sup> ; Noerenberg, Konstantin <sup>1</sup> 1 Projekt-Consult GmbH, Germany 2 Institute of Electrical Engineering/JKD, Chinese Academy of Sciences, P.R. China  Study on D-UPFC in the Clustered PV System with Grid  Kyungsoo Lee, Kosuke Kurokawa Tokyo University of Agriculture & Technology, Japan  Design and Application Considerations of Grid-Connected Photovoltaic Inverters for International Markets  Raymond M. Hudson <sup>1</sup> and Dr. Renjie Xu <sup>2</sup> Xantrex Technology Inc. USA IVice President Advanced Technology, 2Senior Power Electronics Engineer,  Surface Passivation of Crystalline Silicon Solar Cells by High-Pressure Thermal Oxidation at Low Temperature  H. Sai <sup>1</sup> , K. Yamashita <sup>1</sup> , N. Yamamoto <sup>2</sup> , R. Imai <sup>1</sup> , T. Ishiwata <sup>1</sup> , K. Arafune 1, Japan, 2Ishikawajima-Harima Heavy Industries Co., Ltd., Japan  Electric and Crystallographic Characterizations on H-	24-2	
s, and Kosuke KUROKAWA 1 1 Tokyo University of Agriculture and Technology, Japan, 2 National Institute of Advanced Industrial Science and Technology (AIST) 3 Mediensha Corporation, 4 Kandenko co., Id., 5 Nihon University  Application of the Photovoltaic Solar Energy in the Residential Refrigerator Suppy  Denizar Cruz Martins, Douglas P. da Silva, André S. de Andrade, Antonio J. B. Bottion and Kleber C. A. de Souza Department of Electrical Engeneering, Federal University of Santa Catarina,—Florianòpolis, SC - Brazil,  The Application of Neural Network in MPPT of Solar Array  24-5 Shengzhi Xu, Gengshen Zhao, Qingzhang Wang, Yu Wang Ikey Laboratory of Opto-electronic Information Science and Technology, Ministry of Education Institute of Photo and Electronics Device and Technology, Nankai University, PR China,  Eirst Experiences with the Implementation of a Large-Scale Program on PV Hybrid Village Power Plants in Western China  Klinghammer, Winfried <sup>1</sup> : Ma Shenghong <sup>2</sup> : Noerenberg, Konstantin <sup>1</sup> 1 Projekt-Consult GmbH, Germany 2 Institute of Electrical Engineering/JKD, Chinese Academy of Sciences, P.R. China  Study on D-UPFC in the Clustered PV System with Grid  Kyungsoo Lee, Kosake Kurokawa Tokyo University of Agriculture & Technology, Japan  Design and Application Considerations of Grid-Connected Photovoltaic Inverters for International Markets  Raymond M. Hudson <sup>1</sup> and Dr. Renjie Xu <sup>2</sup> Xantrex Technology Inc. USA I Vice President Advanced Technology, 2Senior Power Electronics Engineer,  Surface Passivation of Creatalline Silicon Solar Cells by Hish-Pressure Thermal Oxidation at Low Temperature  H. Sai <sup>1</sup> , K. Yamashita <sup>1</sup> , N. Yamamoto <sup>2</sup> , R. Imai <sup>1</sup> , T. Ishiwata <sup>1</sup> , K. Arafune 1, Japan, 2Ishikawajima-Harima Heavy Industries Co., Ltd., Japan  Electric and Creatallographic Characterizations on H-passivated Spherical Si Solar Cells  Chikao Okamoto <sup>1</sup> , Takashi Minemoto <sup>1</sup> , Mikio Murozono <sup>2</sup> , Hideyuki Takakura <sup>1</sup> and Yoshihiro Hamakawa <sup>1</sup> ICollege of Science and Engineering, Ritsumeinkan University, Japan 2Clean Ve		
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30-1	Zhenhua Shen <sup>1</sup> , M. Eguchi <sup>1</sup> , S. Ogawa <sup>1</sup> , T. Gotoh <sup>2</sup> , K.Sato <sup>3</sup> , T.Itoh <sup>1</sup> , N.Yoshida <sup>1</sup> and S. Nonomura <sup>1</sup> 1Environmental and Renewable Energy Systems Division, 1Gifu University, 2Department of physics, Gunma University, Japan 3Research Center, Japan
	Phase Matched Simultaneous Cell Gap Measurement Reflective LCD by Polarization - Angle
30-2	Chia-Fu,Chang, Yi-Ci,Chan, Zou-ni,Wan Chinese Taipei of Kun Shan Technolog University,Taiwan, R.O.C.,
	Eu Doped CaF <sub>2</sub> Crystals for Photovoltaic Applications
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30-4	X. A. Bubnova, V. E. Nikulin, T. I. Taurbaev Department of Physics, Al-Farabi Kazakh National University, Almaty, Kazakhstan
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	X. A. Bubnova, V. E. Nikulin, T. I. Taurbaev Department of Physics, Al-Farabi Kazakh National University, Almaty, Kazakhstan  Detection of Deep Defect Levels in Cu <sub>2</sub> O/ZnO Heterostructure Solar Cells by DLTS Spectroscopy  G.K.Paul <sup>1</sup> , Y.Nawa, H.Sato, M.M.Islam, N.Ishida, T.Sakurai, K.Akimoto
	X. A. Bubnova, V. E. Nikulin, T. I. Taurbaev Department of Physics, Al-Farabi Kazakh National University, Almaty, Kazakhstan  Detection of Deep Defect Levels in Cu <sub>2</sub> O/ZnO Heterostructure Solar Cells by DLTS Spectroscopy  G.K.Paul <sup>1</sup> , Y.Nawa, H.Sato, M.M.Islam, N.Ishida, T.Sakurai, K.Akimoto Institute of Applied Physics, University of Tsukuba, Japan
30-5	X. A. Bubnova, V. E. Nikulin, T. I. Taurbaev Department of Physics, Al-Farabi Kazakh National University, Almaty, Kazakhstan  Detection of Deep Defect Levels in Cu <sub>2</sub> O/ZnO Heterostructure Solar Cells by DLTS Spectroscopy  G.K.Paul <sup>1</sup> , Y.Nawa, H.Sato, M.M.Islam, N.Ishida, T.Sakurai, K.Akimoto Institute of Applied Physics, University of Tsukuba, Japan  Improved Reproducibility in the Fabrication of Large-area CU(INGA)SE <sub>2</sub> -based Thin-film Submodules  Katsumi Kushiya, Satoru Kuriyagawa, Yoshiaki Tanaka, Masaru Onodera  Manabu Tanaka, Toshiaki Yamaura, Muneyori Tachiyuki, Ayako Tanaka, Yousuke Fujiwara Showa Shell Sekiyu K.K., Central R&D

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	K. Yoshino, A. Kinoshita, H. Matsuo and T. Ikari Department of Electrical and Electronic Engineering, University of Miyazaki, Japan.
	Preparation of AgInS <sub>2</sub> Thin Films by Sulfurization of Ag/In Precursors for Solar Cell Application
31-4	Shigeyuki Nakamura <sup>1</sup> , Dai Okamoto <sup>2</sup> 1Department of Electric and Electronic Engineering, Tsuyama National College of Technology, Japan, 2 Advanced Electronic and Information System Engineering Course, Tsuyama National College of Technology
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31-5	Yumi Tanaka <sup>1,2</sup> , Manabu Ihara <sup>2,1</sup> 1"Conversion and control by advanced chemistry", PRESTO, Japan science and technology corporation (JST) 2Tokyo institute of technology, Research center for carbon recycling and energy, Tokyo
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	Structural and Optical Characterization of Bi-doped CuInS <sub>2</sub> Thin Films Grown by Vacuum Evaporation Method
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	$\underline{ Effects \ of \ Sn \ Concentration \ in \ Indium \ Tin \ Oxide \ Back \ Contacts \ on \ the \ Device \ Performance \ of \ Cu(In_{1-x}Ga_x)Se_2 \ Thin \ Film \ Solar \ Cells}$
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	Fabrication of Absorber Layer for CIGSS Solar Cells by RTP
32-4	Neelkanth G. Dhere, Jyoti S. Shirolikar, Sachin S.Kulkarni, Matthew Nugent Florida Solar Energy Center, University of Central Florida, USA
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32-6	Yu <sup>1,2</sup> , Rongqiang Cui <sup>1</sup> , Chunjiang Zhao <sup>1,2</sup> , Fanying Meng <sup>1</sup> , Hong Chen <sup>1</sup> , Wei Pan <sup>1</sup> , He Wang <sup>3</sup> , Shiwei Ku <sup>1</sup> , Liang Zhao <sup>4</sup> , Hua Peng <sup>4</sup> , Zhibin Zhou <sup>1</sup> , Zhigang Liu <sup>1</sup> , Wei Jiang <sup>1</sup> , Dunyi Tang <sup>1</sup> , Shuquan Lin <sup>1</sup> , Yuliang He <sup>1</sup> 1 Solar Energy Institute, Shanghai Jiaotong University, China 2 Shanghai Linyang Solar Energy Science & Technology Co., Ltd., China 3 Solar Energy Institute, Xi'an Jiaotong University, China 4 Jiangsu Linyang Solarfun Co., Ltd., China
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Koi, Masahiro Goto, Tomonii Meguro, Takahiro Matsuda, Masataka Kondo, Toshiaki Sasaki and Yuko Tawada Kanda Corporation, Japan  MiniPV. Power Systems with a. Si Module  Liu Xiaobo Sheazhen ZHI-YU PV Science & Technique Inc., China  Desradation Induced Performance Loss of Two Commercial CIS Modules Under Sub-tropical and Temperate Climates  King-hang Lami*, Josic Close*, Huey Pang*, Wilhelm Durisch* Diopartment of Architecture, The University of Hong Kong, Hong Kong SAR, P.R.China, 2Paul Scherrer Institute, PSI, Switzerla  One Step Method to Produce Hydrogen Using AmorphousSilicon Solar Cells  Song Hong, Sun Jian, Zhang Dekun, Zhang QingBao, ZhaoYing, Geng XinHua Institute of Photo-Electronics thin film devices and technique of Tianjin, China Key Laboratory of photo-electronics thin film devices and technique of Tianjin, China Key Laboratory of photo-electronics thin film devices and technique of Tianjin, China Key Laboratory of Opto-electronic Information Science and Technology, (Nankai University), Tianjin University), Ministry of Education, China  Optimisation of the Front Contact for Low to Medium Concentrations in LGBC Silicon Solar Cells  A Cole, S Roberts, I'M Bruton, K C Heasman  PVIC, NaREC, Albert St., Blyth, Northumberland, UK,  Reliabilities of High Concentrator PV Modules Using III-V Cells  Kenji Araki*, Hissfami Ucomnii, Massfamii Yamaguethi* 1 Daido Steel Co., Ltd. Japan, 2Toyota Technological Institute, Japan,  B&D Activities for Super High-efficiency Multi-inuction and Concentrator Solar Cells in Japan  Massfami Yamaguchi*, Tastayaya Takamonof. Kenji Araki*, N.J. Ekins-Daukcs¹, Hae-Seok Lee¹, Tatsuya Takamoto', T. Ay Minoru Kanetwa', K. Karnimura', Takeshi Orishima' and Hisayoshi toth* 1 Toyota Technological Institute, Japan Zipana Acropace Exploration Agency, Japan 3*Sharp Corporation, Japan Adapan Atornic Larregy Research Institute, Japan Zipana Acropace Exploration Agency, Japan 3*Sharp Corporation, Japan Ajapan Atornic Larregy Research Institute, Japan Zipana Arengace Exploration Agency, J		C.J.J. Tool, M. Koppes, E.J. Koppes, H.C. Rieffe, I.G. Romijn, A.W. Weeber ECN Solar Energy, The Netherlands.
Department of Physics, Shantou Liversity, Pepile Republic of China,  Iliuh Efficience Thin Film Silicon Hybrid Cell and Module  34-1  Kemit Yamumoto, Alchiko Nakajima, Massahi Yoshimi, Toru Suvada, Susuum Fukuda, Takashi Suezaki, Mitsuru Ichikuwa Yobe Kaneka Corporation, Japan  Mma-PV Power Systems with a-Si Module  34-2  Lau Xinabo  Shenchen ZHI-YU PV Science & Technique Inc., China  Deemadation Induced Performance Loss of Lwo Commercial CIS Modules Under Sub-iropical and Temperate Climates  King-hang Lum <sup>14</sup> , Josic Close <sup>1</sup> , Huey Pang <sup>1</sup> , Withelm Durisch <sup>2</sup> IDepartment of Architecture, The University of Hong Kong, Hong Kong SAR, P. R. China, 2Paul Scherrer Institute, PSI, Switzerla  One Step Method to Produce Hydrogen Using Amorphomolision Solar Cells  One Step Method to Produce Hydrogen Using Amorphomolision Solar Cells  Hutture of Proto-Electronic white film devices on technique of Nankat University, China Key, Laboratory of photo-electronic in University, Tianjin University, Ministry of Education, China  Optimisation of the Front Connect for Loss to Medium Concentrations in LGBC Silicon Solar Cells  A Cole, S Roberts, T M Braton, K C Heasman  PVIC, NARKE, Albert LS, Blyth, Northumberland, UK,  Beliabilities of High Concentrator PV Medales Using III-V Cells  Kenji Araki <sup>1</sup> , Hisafumi Uozami <sup>1</sup> , Masafumi Yamaguchi <sup>2</sup> Todo Steel Co., 1ad. Japan, 2Toyota Technological Institute, Japan,  Masafumi Yamaguchi <sup>3</sup> , Taishi Sumita <sup>2</sup> , Mitsuru Imaizumi <sup>2</sup> , Nicholas J. Ekins-Daukes <sup>3</sup> .  Masafumi Yamaguchi <sup>3</sup> , Taishi Sumita <sup>2</sup> , Mitsuru Imaizumi <sup>2</sup> , Nicholas J. Ekins-Daukes <sup>3</sup> .  Masafumi Yamaguchi <sup>3</sup> , Taishi Sumita <sup>2</sup> , Mitsuru Imaizumi <sup>2</sup> , Nicholas J. Ekins-Daukes <sup>3</sup> .  Movert Technological Institute, Japan Japan Arenspace Exploration Agency, Japan 3*Sharp Corporation, Japan Alomic Facery Research Institute, Japan  Preparation of CGSS Thu-film Solar Cells on Flexible and Ultim-liabhewaith Ti Substrates  Ankur A Kadam, Neelkanth G. Dhere, Anantt H. Jahagirdur and Mike Murphy  Florida Solar Facery Center, University of Cent		Study on Improvement of the Uniformity for Preparing Polycrystalline Silicon Films
Seepi Vanamoto, Akihiko Nakajima, Masashi Yoshimi, Toru Sawada, Susumu Fukuda, Takashi Suezaki, Missuru Jehikawa Yohe Koi, Masahiro Giot, Tomorni Meguro, Takahiro Matsuda, Masataka Kondo, Toshiaki Sasaki and Yuko Tawada Kandec Corporation, Japan  Mini-PV Power Systems with a-Si Module  Liu Xiaobo ShenZhen ZHI-VUPV Science & Technique Inc., China  Degradation Induced Performance Loss of Two Commercial CIS Modules Under Sub-tropical and Temperate Climates  King-hang Lam **, Josic Close*, Huey Pang*, Wilbelm Durisch* 1Department of Architecture, The University of Hong Kong, Hong Kong SAR, P.R.China, 2Paul Scherrer Institute, PSI, Switzerla  One Step Method to Produce Hydrogen Using AmorphousSilicon Solar Cells  Song Hong, Sun Jian, Zhang Dokan, Zhang Gingibao, Zhao Ying, Geng Xinillua  Institute of Photo-Electrone that Influence was and technique of Nankail University, China Key Laboratory of photo-electronic the Influence of Commercial University, China Key Laboratory of photo-electronic that Influence of Commercial University, China Key Laboratory of photo-electronic Information Science and Technology, (Nankai University), Jimian University), Ministry of Education, China  Optimisation of the Front Contact for Low to Medium Concentrations in LGBC Silicon Solar Cells  34-5  A Cole, S Roberts, T. M Braton, K. C Heasman  PVTC, NaREC, Albert St, Blyth, Northumberland, UK,  Reliabilities of Hish Concentrator PV Modules Using III-V Cells  46-6  Kenji Araki, Hisafami Uozumi*, Masafami Yamagachi* 1 Daido Steel Co., Ltd. Japan, 2Toyota Technological Institute, Japan,  87-1  Masafami Yamagachi*, Tatsaya Takamono*, Kenji Araki*, N.J. Ekins-Daukce*, Irae-Seok Lee*, Tatsuya Takamoto*, T. A. Minori Kaneiwa*, K. Karnimura*, Takeshi Ohishina* and Hissyoshi Inferiora.  Masafami Yamagachi*, Taishi Summata*, Mitsura Inarama*, Nicholas J. Ekins-Daukce*, Irae-Seok Lee*, Tatsuya Takamoto*, T. A. Minori Kaneiwa*, K. Karnimura*, Takeshi Ohishina* and Hissyoshi Inferiora.  Masafami Yamagachi*, Taishi Summata*, Mitsura Inarama*, Nicholas	33-4	
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Liu Xiaobo ShenZhen ZHL-YU PV Science & Technique Inc., China  Destradation Induced Performance Loss of Two Commercial C18 Modules Under Sub-tropical and Temperate Climates  King-hamp Lama haman Josie Close ham, Pang haman Miletan Durisch i Department of Architecture, The University of Hong Kong, Hong Kong SAR, P.R.China, 2Paul Scherrer Institute, PSI, Switzerla  One Step Method to Produce Hydrogen Usine Ameribaous Silicon Solar Cells  Song Hong, Sun Jian, Zhang Dekun, Zhang QingBao, Zhao Ying, Geng XinHua Institute of Photo-Electronics thin film devices and technique of Nankai University, China Key Laboratory of Poto-electronic Information Science and Technology, (Nankai University, Tianjin University), Ministry of Education, China  Optimisation of the Front Contact for Low to Medium Concentrations in LGBC Silicon Solar Cells  A Cole, S Roberts, T M Bruton, K C Heasman  Pyr C, NaREC, Albert St, Blyth, Norbumberland, UK,  Reliabilities of High Concentrator PV Modules Using III-V Cells  Kenji Araki Hisafumi Uozumi Masafumi Vamaguchi 1 Daido Steel Co., Ltd. Japan, 2Toyota Technological Institute, Japan,  R&D Activities for Super High-efficiency Multi-junction and Concentrator Solar Cells in Japan  Masafumi Vamaguchi Tatsaya Takamotor Nenji Araki N. J. Ekins-Duukes 1  Troyota Technological Institute, Japan, 2Sharp Corporation, Japan 3Daido Steel Corporation, JapanAuthor's  Analysis for Radiation-Resistance of GiaAs Sub-Cells for India PGiaAcGa Junction Solar Cells  Masafumi Vamaguchi , Tatsishi Sumita*, Mitsuru Imaizumi², Nicholas J. Ekins-Duukes¹, Hae-Sook Lee¹, Tatsuya Takamoto', T. Aj Minoru Kaneiwa', K. Kamimura', Takeshi Obshima' and Hisayoshi Itoh*  Troyota Technological Institute, Japan 2Japan Aerospace Exploration Agency, Japan 3*Sharp Corporation, Japan 4 Japan Atomic Energy Research Institute, Japan 2Japan Aerospace Exploration Agency, Japan 3*Sharp Corporation, Japan 4 Japan Atomic Energy Research Institute, Japan 2Japan Aerospace Exploration Agency, Japan 3*Sharp Corporation, Japan 4 Japan Atomic Energ	34-1	
Degradation Induced Performance Loss of Two Commercial CIS Modules Under Sub-tropical and Temperate Climates  Wing-hang Lam¹*, Josic Close¹, Huey Pang¹, Withelm Durisch² IDepartment of Architecture, The University of Hong Kong, Hong Kong SAR, P.R. China, 2Paul Scherrer Institute, PSI, Switzerla  One Step Method to Produce Hydrosen Using AmorphousSilicon Solar Cells  Song Hong, Sun Jian, Zhang Dekun, Zhang QingBao, ZhaoYing, Geng XinHua Institute of Photo-Electronics thin film devices and technique of Nankai University, China Key Laboratory of photo-electronics thin film devices and technique of Tanajin, China Key Laboratory of Opto-electronic Information Science and Technology, (Nankai University, Tianjin University), Ministry of Education, China  Optimisation of the Front Contact for Low to Medium Concentrations in LGBC Silicon Solar Cells  A Cole, S Roberts, T M Bruton, K C Heasman PYTC, NaREC, Albert St., Blyth, Northumberland, UK,  Relabilities of High Concentrator PV Modules Using III-V Cells  Kenji Araki¹, Hisafumi Uozumi¹, Masafumi Yamaguchi² I Daido Steel Co., Lid, Japan, 2 Iroyota Technological Institute, Japan,  Masafumi Yamaguchi¹, Tatsuya Takamoto², Kenji Araki², N.J. Ekins-Daukes¹ IToyota Technological Institute, Japan, 2Sharp Corporation, Japan 3baido Steel Corporation, JapanAuthor's  Analysis for Radiation-Resistance of GiAs Sub-Cells for InGaP/GiAs/Ge 3-junction Solar Cells  Masafumi Yamaguchi¹, Tatsihi Sumita², Mitsuru Imaizumi², Nicholas J. Ekins-Daukes¹, Hae-Seok Lee¹, Tatsuya Takamoto³, T. A. Minoru Kaneiwa², K. Kamimura³, Takeshi Ohshima³ and Hisayoshi Indi³  IToyota Technological Institute, Japan 2Japan Aerospace Exploration Agency, Japan 3*Sharp Corporation, Japan 4 Japan Atomic Energy Research Institute, Japan Cells on Flexible and Ultra-lightweight Ti Substrates  Arkar A. Kadam, Neelkanth G. Dhere, Anant H. Jahagirdar and Mike Murphy Florida Solar Energy Center, University of Central Florida, USA  MOVPE Growth Conditions and Characterization of InGaAsh³ an Alternative 1.0 eV Bandaan Sol		MiniPV Power Systems with a-Si Module
34-3 King-hang Lam <sup>1*</sup> , Josic Close <sup>1</sup> , Huey Pang <sup>1</sup> , Wilhelm Durisch <sup>2</sup> 1Department of Architecture, The University of Hong Kong, Hong Kong SAR, P.R.China, 2Paul Scherrer Institute, PSI, Switzerla  34-4 Song Hong, Sun Jian, Zhang Dekun, Zhang QingBao, Zhao Ying, Geng XinHua Institute of Photo-Electronics thin film devices and technique of Thaing, China Key Laboratory of Opto-electronic Information Science and Technology, (Nankai university), Tanjin University), Ministry of Education, China  34-5 PAC, SaRberts, Th Bruton, K.C. Heasman PYCP, NaREC, Albert St., Blyth, Northumberland, UK,  Reliabilities of High Concentrator PV Modules Using III-V Cells  34-6 Kenji Araki <sup>1</sup> , Hisafumi Uozumi <sup>1</sup> , Masafumi Yamaguchi <sup>2</sup> 1 Daido Steel Co., Ltd. Japan, 2Toyota Technological Institute, Japan,  88D Activities for Super High-efficiency Multi-iunction and Concentrator Solar Cells in Japan  35-1 Masafumi Yamaguchi <sup>1</sup> , Tatsuya Takamoto <sup>2</sup> , Kenji Araki <sup>2</sup> , N.J. Ekins-Daukes <sup>1</sup> 1Toyota Technological Institute, Japan, 2Sharp Corporation, Japan 3Daido Steel Corporation, Japan Author's  Analysis for Radiation-Resistance of GaAs Sub-Cells for InGaP/GaAs/Ge 3-junction Solar Cells  Masafumi Yamaguchi <sup>1</sup> , Taishi Sumita <sup>2</sup> , Misuru Imaizumi <sup>2</sup> , Nicholas J. Ekins-Daukes <sup>1</sup> , Hae-Seok Lee <sup>1</sup> , Tatsuya Takamoto <sup>3</sup> , T. Ay Minoru Kanciwa <sup>3</sup> , K. Kamimura <sup>3</sup> , Taleeshi Ohshima <sup>4</sup> and Hisayoshi Itoh <sup>4</sup> 1Toyota Technological Institute, Japan Zhapa Aerospace Exploration Agency, Japan 3*Sharp Corporation, Japan 4 Japan Atomic Energy Research Institute, Japan Zhapa Aerospace Exploration Agency, Japan 3*Sharp Corporation, Japan 4 Japan Atomic Energy Research Institute, Japan  Preparation of CIGSS Thin-film Solar Cells on Flexible and Ultra-lightweight Ti Substrates  35-3 Ankur A. Kadam, Neelkanth G. Dhere, Anant H. Jahagirdar and Mike Murphy Flioda Solar Energy Center, University of Central Florida, USA  Solar Cells on MCZ/Ge Silicon Substrates  Du Yongchao, Sun Yamzheng, Liu Chumming, Li Chao, Ren Jing, Wang Jingxiao Tianjin Institute of Power Sources,	34-2	
Name		Degradation Induced Performance Loss of Two Commercial CIS Modules Under Sub-tropical and Temperate Climates
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Institute of Photo-Electronics thin film devices and technique of Nankai University, China Key Laboratory of photo-electronics thin film devices and technique of Tianjin, China Key Laboratory of Opto-electronic Information Science and Technology, (Nankai University, Tianjin University), Ministry of Education, China  Optimisation of the Front Contact for Low to Medium Concentrations in LGBC Silicon Solar Cells  A Cole, S Roberts, T M Bruton, K C Heasman PVTC, NaREC, Albert St., Blyth, Northumberland, UK,  Reliabilities of High Concentrator PV Modules Using III-V Cells  Kenji Araki <sup>1</sup> , Hisafumi Uozumi <sup>1</sup> , Masafumi Yamaguchi <sup>2</sup> 1 Daido Steel Co., Ltd. Japan, 2Toyota Technological Institute, Japan,  R&D Activities for Super High-efficiency Multi-junction and Concentrator Solar Cells in Japan  Masafumi Yamaguchi <sup>1</sup> , Tatsuya Takamoto <sup>2</sup> , Kenji Araki <sup>2</sup> , N.J. Ekins-Daukes <sup>1</sup> 1Toyota Technological Institute, Japan, 2Sharp Corporation, Japan 3Daido Steel Corporation, JapanAuthor's  Analysis for Radiation-Resistance of GaAs Sub-Cells for InGaP/GaAs/Ge 3-junction Solar Cells  Masafumi Yamaguchi <sup>1</sup> , Taishi Sumita <sup>2</sup> , Mitsuru Imaizumi <sup>2</sup> , Nicholas J. Ekins-Daukes <sup>1</sup> , Hae-Seok Lee <sup>1</sup> , Tatsuya Takamoto <sup>3</sup> , T. Ag Minoru Kanciwa <sup>3</sup> , K. Kamimura <sup>3</sup> , Takeshi Ohshima <sup>4</sup> and Hisayoshi Itoh <sup>4</sup> 1Toyota Technological Institute, Japan Zlapan Aerospace Exploration Agency, Japan 3*Sharp Corporation, Japan 4 Japan Atomic Energy Research Institute, Japan Papan Aerospace Exploration Agency, Japan 3*Sharp Corporation, Japan 4 Japan Atomic Energy Research Institute, Japan Papan Aerospace Exploration Agency, Japan 3*Sharp Corporation, Japan 4 Japan Atomic Energy Research Institute, Japan Papan Aerospace Exploration Agency, Japan 3*Sharp Corporation, Japan 4 Japan Atomic Energy Research Institute, Japan Papan Atomic Energy Research Institute of Power Sources, P. R. China,  MOVPE Growth Conditions and Characte		One Step Method to Produce Hydrogen Using AmorphousSilicon Solar Cells
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Renji Araki*, Hisafumi Uozumi*, Masafumi Yamaguchi* 1 Daido Steel Co., Ltd. Japan, 2Toyota Technological Institute, Japan,  R&D Activities for Super High-efficiency Multi-junction and Concentrator Solar Cells in Japan  35-1  Masafumi Yamaguchi¹, Tatsuya Takamoto², Kenji Araki³, N.J. Ekins-Daukes¹ 1 Toyota Technological Institute, Japan, 2Sharp Corporation, Japan 3Daido Steel Corporation, JapanAuthor's  Analysis for Radiation-Resistance of GaAs Sub-Cells for InGaP/GaAs/Ge 3-junction Solar Cells  Masafumi Yamaguchi¹, Taishi Sumita², Mitsuru Imaizumi², Nicholas J. Ekins-Daukes¹, Hae-Seok Lee¹, Tatsuya Takamoto³, T. Aj Minoru Kaneiwa³, K. Kamimura³, Takeshi Ohshima⁴ and Hisayoshi Itoh⁴ 1 Toyota Technological Institute, Japan 2Japan Aerospace Exploration Agency, Japan 3*Sharp Corporation, Japan 4 Japan Atomic Energy Research Institute, Japan  Preparation of CIGSS Thin-film Solar Cells on Flexible and Ultra-lightweight Ti Substrates  Ankur A. Kadam, Neelkanth G. Dhere, Anant H. Jahagirdar and Mike Murphy Florida Solar Energy Center, University of Central Florida, USA  Solar Cells on MCZ(Ge) Silicon Substrates  Du Yongchao, Sun Yanzheng, Liu Chunming, Li Chao, Ren Jing, Wang Jingxiao Tianjin Institute of Power Sources, P.R. China,  MOVPE Growth Conditions and Characterization of InGaAsN; an Alternative 1.0 eV Bandgap Solar Cell Material  35-5  Sakuntam Sanorpim¹, Fumihiro Nakajima², Wataru Ono², Ryuji Katayama², and Kentaro Onabe² 1Semiconductor Physics Research Laboratory, Department of Physics, Faculty of Science, Chulalongkorn University, Pathumwan Thailand. 2 Department of Advanced Materials Science, The University of Tokyo, Japan.  Radiation-Resistance of a Wide Band-Gap AllnGaP Space Solar Cell under 1 MeV Electron Irradiation  H.S. Lee¹, M. Yamaguchi¹, N.J. Ekins-Daukes², A. Khan³, T. Takamoto⁴, M. Imaizumi⁵, T. Ohshima⁶, H. Itoh⁶		Reliabilities of High Concentrator PV Modules Using III-V Cells
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	35-6	H.S. Lee <sup>1</sup> , M. Yamaguchi <sup>1</sup> , N.J. Ekins-Daukes <sup>2</sup> , A. Khan <sup>3</sup> , T. Takamoto <sup>4</sup> , M. Imaizumi <sup>5</sup> , T. Ohshima <sup>6</sup> , H. Itoh <sup>6</sup> 1Toyota Technological Institute, Japan, 2University of Sydney, School of Physics, Australia, 3University of South Alabama, Mobile, USA, 4SHARP Corporation, Japan, 5Japan Aerospace Exploration Agency, Japan, 6Japan Atomic Energy Research Institute, Japan,

chen Xinition, Xu Bitheng, Zhao Ying, Sun Jun, Wei Changchun, Genu Xinhua beriation of Photo-electronics Than Film Decessors and Exchange of Annals University Key Inhonatory of Optro-electronic Information Science and Technology for Ministry of Education, Nankat University, China Zino Laven Incorporated Line use SLH Schar Cells, Quamma Efficiency (OE) Results and Protocol for a Fixed Merit S. Fig.). Steinbauer, R. Schilchter, L. Ferdersch, C., Ballif, A. Shah Intrinsic of Ministry of Photosophics, Forchungscrotters in July 1997.  36-4  36-4  36-4  36-6  36-6  36-6  36-6  36-6  36-7	36-1	Boron-doped ZnO Films for A-Si Solar Cell Grown by MOCVD
36-2  S. Fag, J. Steinbauser, R. Schlücher, L. Feithnecht, C. Ballif, A. Shah Institut de Merrotechnique (MIN, Nea AL. Breguet 2, Switzerland  Stability of Non-meanstalited Hun-film Silicon Solar Cells in Damp Heat Tests  H. Stiebig, W. Roety, C. Hasse, T. Repmann, and R. Reels  H. Stiebig, W. Roety, C. Hasse, T. Repmann, and R. Reels  Institute of Phonovolnics, Fonchungschemun Juelich, Germany  Indo-Coated TCO (StOc): Films Prepared by AP-CVD with High Durability against Hydrogen Radiculs  Maka Kambe <sup>12</sup> , Kazuo Satol, *Yasuyeshi Kurokawa*, Shinsake Miyajima*, Makoto Fukuwa*, Naoki Tuneda*, and Makoto Konaga*  I Roescarde Center, Asahi Glias Ce, Ltd., Japan, 2 Department of Physical Electronics, Teckyo Institute of Technology, Japan  Effect of Zao Lavers as Front TCO and Back Reflector in Superstrate pin uc-St. Hand a-St-Huc-St. H Tim-film Solar Cells  Josag Chul Lee*, Sang Won Jeon*, Jussia Yi*, Sae Jia Ahal. Jae Ho Yua*, Sook Ki Kim*, Jiasoo Soog* and Kyung Hono Yoon**  I Solar Cells Research Center, Korea Institute of Energy Research, Korea* 2 School of Information and Communication Ingineering, Sangkyunkwan University  Control of Microruchura and Surface Morphology of Indium Tim Oxide Films by Changing Initial Growth Conditions  Jung Hwan Lee**, Jun Sik Cho*, Young Whan Baeg* and Donghwan Kim*  1. Department of Materials Science and Engineering, Korea University, Anam-dong, Korea 2: P&I R&D Center, Korea  Relationshim of Structures and Photoelectris Properties of Novel Cyanine Dyes with Different Methine Chairs as Sensitizes for Nanorystalline Solar Cell  36-7  Xiaying Chen*, Xiaojun Peng**, Jiahao Guo*, Shengmin Cai**  1. State key Ishoritary of fine chemicals, Dalian University of Technology, P.R.China, 2 College of Chemistry and Molecular Engineering, Penglu Guiversity, P. R. Eddos*  Photoelaic University, P. K. Brackos* of Research, Norfolk State University, Norfolk, USA, 2Institute for Organic Solar Cells, Johanne Kepter University, Ling, Astrina  Photovolaic Characteristics of Benomineoproparted Na		Institute of Photo-electronics Thin Film Devices and Technique of Nankai University Key laboratory of Opto-electronic Information
S. Fay, J. Steinhauser, R. Schender, C. Stallir, A. Stall  Stability of Non-encanoulated Him-film Silicon Solar Cells in Dump Heat Tests  H. Stiebig, W. Reetz, C. Hause, T. Regmann, and B. Rech  Institute of Photosolusies, Forschungscarrum Judich, Germany  Tio_Coated TCO (SiO_F) Films Prepared by AP-CVD with High Darability against Hydrogen Radicals  Mikat Karmbe <sup>13</sup> , Kazuo Sato <sup>1</sup> , Yasuyoshi Kurokawa <sup>1</sup> , Shinsuke Miyajima <sup>1</sup> , Makoto Fukawa <sup>1</sup> , Naoia Taneda <sup>1</sup> , and Makoto Konngan <sup>2</sup> 1 Research Center, Asahi Glass Co., Ltd., Japan, 2 Department of Physical Electronies, Tokyo Institute of Technology, Japan  Effect of ZaO Lavers as Front TCO and Back Reflector in Superstate pin ue-Si Hand a Si-Hue-Si Hinsi Solar Cells  Jeong Chul Lee <sup>2</sup> , Sang Won Jeon <sup>1</sup> , Junsan Yl <sup>2</sup> , Sac Jin Ahn <sup>1</sup> , Jae Ho Yun <sup>1</sup> , Seok Ki Kim <sup>1</sup> , Jinsoo Song <sup>1</sup> and Kyung Hoon Yoon <sup>1</sup> *  ISolar Cells Research Center, Korea Institute of Energy Research, Korea <sup>22</sup> 2 School of Information and Communication Engineering, Sanglyunkwan University  Centrol of Microstineature and Surface Morphology of Indium Tim Oxide Films by Changing Initial Growth Conditions  36-6  Jung Hywan Lee <sup>4</sup> , Jun Sik Cho <sup>3</sup> , Young Whan Baeg <sup>3</sup> and Donghwan Kim <sup>3</sup> 1: Department of Materials Science and Ingineering, Korea University, Anam-dong, Korea 2: P&I R&D Center, Korea  Relationshin of Structures and Photoelectric Properties of Novel Contine Dress with Different Methine Chains as Sensitizers for Nanocrystalline Solar Cell  36-7  Xiving Chen <sup>1</sup> , Xiangun Peng <sup>1-8</sup> , Juahao Guo <sup>3</sup> , Shengmann Cai <sup>3+</sup> 1 State key Jahoratory of fine chemicals, Dalian University of Technology, P. R. China, 2 College of Chemistry and Molecular Engineering, Exion Jurveysty, P. R. China, 2 College of Chemistry and Molecular Engineering, Northumber University, Port Solar Cell Amplications  24-1 Reseawable Energy Solutions, Inc. (RESI), USA, 2 TerraSolar Global, USA;  Physical Investigations on StoNAs Schottky Diodea  37-1 N. K. Reddy <sup>1</sup> , K. Ramesh <sup>1</sup> , K. T. R. Reddy <sup>2+</sup> and R. W. Mide <sup>2</sup> 1 Depa		ZnO Layers Incorporated into μc-Si :H Solar Cells : Quantum Efficiency (QE) Results and Proposal for a Fig.of Merit
16-4  18-51  18-52  18-52  18-52  18-52  18-53  18-54  18-52  18-52  18-52  18-52  18-52  18-52  18-53  18-	36-2	
It Steenge, W. Reetz, C. Hases, J. Repmann, and B. Reetn institution of Photovolanes, Forechangescrimum Judeich, Germany  TiO2-Coated TCO (StoO2-F) Firms Prepared by AP-CVD with High Durability against Hydrogen Radicals  Mfka Kambe 1-2, Kazuo Sato <sup>1</sup> , Yasuyoshi Kurokawa <sup>2</sup> , Shinsuke Miyajima <sup>2</sup> , Makoto Fukawa <sup>1</sup> , Naoki Taneda <sup>1</sup> , and Makoto Konagai <sup>2</sup> I Research Center, Asabi Glass Co., Lid., Japan, 2 Department of Physical Electronics, Tokyo Institute of Tachnology, Japan  Effect of ZnO Lavers as Front TCO and Back Reflector in Superstrate pin uc-Si-H and a-Si-Hou-Si-H Thin-film Solar Cells  Jeong Chul Lee <sup>1</sup> , Sang Won Jeon <sup>1</sup> , Junsin Yi <sup>2</sup> , Sae Jin Ahn <sup>1</sup> , Jae Ho Yun <sup>1</sup> , Seok Ki Kim <sup>1</sup> , Jinsoo Song <sup>1</sup> and Kyang Hoon Yoon <sup>1</sup> * 1Solar Cells Research Center, Korea Institute of Energy Research, Korea* 2 School of Information and Communication Engineering, Sungkyunkwan University  Control of Microstructure and Surface Morphology of Indium Tin Oxide Films by Changing Initial Growth Conditions  Jung Hwan Lee <sup>3</sup> Jun Sik Cho <sup>2</sup> , Young Whan Baeg <sup>2</sup> and Donghwan Kim <sup>1</sup> 1. Department of Materials Science and Engineering, Korea University, Anan-dong, Korea 2: P&I R&D Center, Korea  Relationship of Structures and Photoelectric Properties of Novel Cyanine Dyes with Different Methine Chains as Sensitizers for Nanocrystalline Solar Cell  Xunying Chen <sup>1</sup> , Xinojun Peng 1-4, Jiahao Gao <sup>2</sup> , Shengmin Cai <sup>2</sup> -4 1 Sate key laboratory of fine chemicals, Dalian University of Technology, P.R. China, 2 College of Chemistry and Molecular Engineering, Peking University, P.R.China.  Etch-Induced Deposition on SixH for Solar Cell Applications  Yuan-Min Li <sup>1</sup> and Zoltan J. Kiss  2,1 Renewable Energy Solutions, Inc. (RESI), USA; 2TerraSolar Global, USA;  Physical Investigations on SixSAs Schottky Diodes  37-1  N. K. Reddy <sup>1</sup> , K. Ramesh <sup>1</sup> , K. T. R. Reddy <sup>2</sup> s and R. W. Miles <sup>2</sup> 1Department of Physics. Indian Institute of Science, India, 2 <sup>2</sup> Department of Physics, Sri Venkateswara University, India, 3School of Engineering, Northorbits Universit		Stability of Non-encapsulated Thin-film Silicon Solar Cells in Damp Heat Tests
Mika Kambe <sup>12</sup> , Kazuo Suto <sup>1</sup> , Yasuyoushi Kurokawa <sup>2</sup> , Shinsake Miyajimu <sup>2</sup> , Makoto Fukawa <sup>1</sup> , Naoki Taneda <sup>1</sup> , and Makoto Konagai <sup>2</sup> I Research Center, Asahi Glass Co., Lid., Japan, 2 Department of Physical Electronics, Tokyo Institute of Technology, Japan  Effect of ZnG Lavers as Front TCO and Back Reflector in Superstrate pin use. Si:H and a-Si:Huse-Si:H Thin-film Solar Cells  Beong Chal Lee <sup>1</sup> , Sang Won Jeon <sup>1</sup> , Junsin Yi <sup>2</sup> , Sae Jin Ahn <sup>1</sup> , Jae Ho Yun <sup>1</sup> , Seok Ki Kim <sup>1</sup> , Jinsoo Song <sup>1</sup> and Kyung Hoon Yoon <sup>18</sup> 1Solar Cells Research Center, Korea Institute of Eactgry Research, Korea <sup>2</sup> 2 School of Information and Communication Engineering, Sangayandwan University  Control of Microstructure and Surface Morphology of Indium Tin Oxide Films by Changing Initial Growth Conditions  36-6  Jung Hwan Lee <sup>4</sup> , Jun Sik Cho <sup>2</sup> , Young Whan Bage <sup>2</sup> and Donghwan Kim <sup>1</sup> 1. Department of Materials Science and Engineering, Korea University, Anam-dong, Korea <sup>2</sup> : P&I R&D Center, Korea  Relationship of Structures and Photoelectric Properties of Novel Cyanine Dyes with Different Methine Chains as Sensitizers for Namory and Cyange Change of Chemistry and Molecular Engineering, Psking University, P. RChina,  Eleb-Induced Deposition of SiH for Solar Cell Applications  Yuan-Min Li <sup>1</sup> and Zoltan J. Kiss  2,1 Renewable Energy Solutions, Inc. (RESI), USA; ZierraSolar Global, USA;  Physical Investigations on SaS/Ag Schotty Diodes  37-1  N. K. Reddy <sup>1</sup> , K. Ramesh <sup>1</sup> , K. T. R. Reddy <sup>2</sup> and R. W. Miles <sup>2</sup> 1Department of Physics, Indian Institute of Science, India, <sup>29</sup> Department of Physics, Sri Venkateswara University, India, 38chool of Engineering, Northmorba University, Newcastic Niel SSI <sup>1</sup> , UK,  Optimizations of Organic and Polymeric Photovoltaic Materials and Devices  37-2  S. Sun <sup>1*</sup> , C. Zhang <sup>1</sup> , J. Halibutron <sup>1</sup> , S. Cho <sup>3</sup> , A. Ledbetter <sup>1</sup> , C. Bonner <sup>1</sup> , M. Dees <sup>2</sup> and N. Saricifte <sup>2</sup> 1Center for Organic Photonic Materials Research, Norfolk State University, Norfolk, USA, 2Institute for Organic Solar Cells, Johanne Kepler Univer	36-3	
Mika Kambe <sup>1</sup> , Kazuo Sahi, <sup>1</sup> Yasuyoshi Kurokawa, Shirasuke Miyajima, <sup>1</sup> Makoto Pukawa, <sup>1</sup> Nabi Taekearch Center, Ashi Glass Co., Ltd., Japan, <sup>2</sup> Department of Physical Electronics, Tokyo Institute of Technology, Japan  Effect of ZnO Lavers as Front TCO and Back Reflector in Superstrate pin use-Si-H and a Si-Hue-Si-H Thin-film Solar Cells  Jeong Chul Lee <sup>1</sup> , Sang Won Jeon <sup>1</sup> , Jumin Yi <sup>2</sup> , Sae Jin Ahn <sup>1</sup> , Jae Ho Yun <sup>1</sup> , Seok Ki Kim <sup>1</sup> , Jinsoo Song <sup>1</sup> and Kyung Hoon Yoon <sup>1</sup> *  ISolar Cells Research Center, Korea Institute of Energy Research, Korea* <sup>2</sup> School of Information and Communication Engineering, Sungkyunkwan University  Control of Microstructure and Surface Morphology of Indium Tin Oxide Films by Changing Initial Growth Conditions  Jung Hoan Lee*, Jan Sik Cho <sup>2</sup> , Young Whan Baeg <sup>2</sup> and Donghwan Kim <sup>1</sup> 1 Department of Materials Science and Engineering, Korea University, Anam-dong, Korea 2: P&I R&D Center, Korea  Relationship of Structures and Photoelectric Properties of Novel Cyanine Dives with Different Methins Chains as Sensitizers for Nanocrystalline Sular Cell  Xiuying Cho <sup>1</sup> , Xiaojun Peng <sup>1</sup> *, Jiahao Guo <sup>2</sup> , Shengmin Cai <sup>2</sup> *  1 Xiuying Cho <sup>1</sup> , Xiaojun Peng <sup>1</sup> *, Jiahao Guo <sup>2</sup> , Shengmin Cai <sup>2</sup> *  1 Xiuying Cho <sup>1</sup> , Xiaojun Peng <sup>1</sup> *, Jiahao Guo <sup>2</sup> , Shengmin Cai <sup>2</sup> *  1 Xiuying Cho <sup>1</sup> , Xiaojun Peng <sup>1</sup> *, Jiahao Guo <sup>2</sup> , Shengmin Cai <sup>2</sup> *  1 Xiuying Cho <sup>1</sup> , Xiaojun Peng <sup>1</sup> *, Jiahao Guo <sup>2</sup> , Shengmin Cai <sup>2</sup> *  2 Yuan-Min Li <sup>1</sup> * and Zoftan J. Kiss  2 Yuan-Min Li <sup>1</sup> * and Zoftan J. Kiss  2 Yuan-Min Li <sup>1</sup> *, Ramesh <sup>1</sup> *, K. T. R. Reddy <sup>2</sup> * and R. W. Miles <sup>3</sup> IDepartment of Physics, Indian Institute of Science, India, 2º Department of Physics, Sri Venkateswara University, India, 3School of Engineering, Northumbria University, Newcastle NEI 8ST, UK,  Optimizations of Organic Photonic Materials Research, Norfolk State University, Norfolk, USA, 2Institute for Organic Photonic Materials Research, Norfolk State University, Norfolk, USA, 2Institute for Organic Solar Cells, Johanne Kepler University, Day Day Day Day		TiO <sub>2</sub> -Coated TCO (SnO <sub>2</sub> :F) Films Prepared by AP-CVD with High Durability against Hydrogen Radicals
Jeong Chul Lee <sup>1</sup> , Sang Won Jeon <sup>1</sup> , Junsin Yi <sup>2</sup> , Sae Jin Ahn <sup>1</sup> , Jae Ho Yun <sup>1</sup> , Seok Ki Kim <sup>1</sup> , Jinsoo Song <sup>1</sup> and Kyung Hoon Yoon <sup>1+</sup>   Isolar Cells Research Center, Korea Institute of Energy Research, Korea* 2 School of Information and Communication Engineering, Sungkyunkwan University   Control of Microstructure and Surface Morphology of Indium Tin Oxide Films by Changing Initial Growth Conditions   Jung Hwan Lee* 1, Jun Sik Cho <sup>2</sup> , Young Whan Baeg <sup>2</sup> and Donghwan Kim <sup>1</sup>   Department of Materials Science and Engineering, Korea University, Anam-dong, Korea 2: P&I R&D Center, Korea   Relationship of Structures and Photoelectric Properties of Novel Cvanine Dves with Different Methine Chains as Sensitizers for Nanocrystalline Solar Cell   Xiuying Chen <sup>1</sup> , Xiaojun Peng <sup>1, 8</sup> , Jinhao Guo <sup>2</sup> , Shengmin Cai <sup>2, 6</sup>   1 State key laboratory of fine chemicals, Dalian University of Technology, P.R.China, 2 College of Chemistry and Molecular Engineering, Peking University, P.R.China,   Etch-Induced Deposition of Si/H for Solar Cell Applications   Yuan-Min Li	36-4	
Solar Cells Research Center, Korea Institute of Energy Research, Korea* 2 School of Information and Communication Engineering, Sungkyunkwan University  Control of Microstructure and Surface Morphology of Indium Tin Oxide Films by Changing Initial Growth Conditions  Jung Hwan Lee* 1, Jun Sik Cho², Young Whan Baeg² and Donghwan Kim¹ 1: Department of Materials Science and Engineering, Korea University, Anam-dong, Korea 2: P&I R&D Center, Korea  Relationship of Structures and Photoelectric Properties of Novel Cyanine Dyes with Different Methine Chains as Sensitizers for Nanocrystalline Solar Cell  Xiuying Chen¹, Xiaojun Peng¹-½, Jiahao Guo², Shengmin Cai²-½ 1 State key laboratory of fine chemicals, Dalian University of Technology, P.R.China, 2 College of Chemistry and Molecular Engineering, Peking University, P.R.China,  Eich-Induced Deposition of Si:H for Solar Cell Applications  Yuan-Min Li¹ and Zoltan J. Kiss 2,1 I Renewable Energy Solutions, Inc. (RESI), USA; 2TerraSolar Global, USA;  Physical Investigations on SnS/Ag Schottky Diodes  37-1  N. K. Reddy¹-, K. Ramesh¹-, K. T. R. Reddy²-and R. W. Miles² 1Department of Physics, Indian Institute of Science, India, 2* Department of Physics, Sri Venkateswara University, India, 3School of Engineering, Northumbria University, Newcastle NE1 8ST, UK,  Optimizations of Organic and Polymeric Photovoltaic Materials and Devices  37-2  S. Sun¹-, C. Zhang¹-, J. Haliburton¹-, S. Choi¹-, A. Ledbetter¹-, C. Bonner¹-, M. Drees² and N. Saricifter² 1 Center for Organic Photonic Materials Research, Norfolk State University, Norfolk, USA, 2Institute for Organic Solar Cells, Johanne Replet University, Luzz, Austin  Photovoltaic Characteristics of Boron-incorporated Nanocrystalline Carbon on Silicon as Heterojunction Solar Cell  37-3  Z. Q. Ma¹-, Q. Zhang²-, D.M. Wang¹-, W. Li¹-, Y. Wang¹-, Z. X. Zhao¹ 1 Microelectronic Group, Department of Physics, Shanghai University, P.R. China,  Baman Spectroscopy of Carbon Nitride Films Prepared by Ion Beam Sputtering Technique  W. Jiang*, Z.B. Zhou		Effect of ZnO Layers as Front TCO and Back Reflector in Superstrate pin μc-Si:H and a-Si:H/μc-Si:H Thin-film Solar Cells
Jung Hwan Lee*, Jun Sik Cho², Young Whan Baeg² and Donghwan Kim¹  1. Department of Materials Science and Engineering, Korea University, Anam-dong, Korea 2: P&I R&D Center, Korea  Relationship of Structures and Photoelectric Properties of Novel Cyanine Dyes with Different Methine Chains as Sensitizers for Nanocrystalline Solar Cell  Xiuying Chen¹, Xiaojun Peng¹*, Jiahao Guo², Shengmin Cai²*  1. State key laboratory of fine chemicals, Dalian University of Technology, P.R.China, 2 College of Chemistry and Molecular Engineering, Peking University, P.R.China,  Etch-Induced Deposition of Si:H for Solar Cell Applications  36-8  Yuan-Min Li¹ and Zoltan J. Kiss  2,1 IRenewable Energy Solutions, Inc. (RESI), USA; 2TerraSolar Global, USA;  Physical Investigations on SnS/Ag Schottky Diodes  37-1  N. K. Reddy¹, K. Ramesh¹, K. T. R. Reddy²* and R. W. Miles² 1Department of Physics, Indian Institute of Science, India; 2* Department of Physics, Sri Venkateswara University, India, 3School of Engineering, Northumbria University, Newcastle NEI 8ST, UK,  Optimizations of Organic and Polymeric Photovoltaic Materials and Devices  37-2  S. Sun¹*, C. Zhang¹, J. Haliburton¹, S. Choi¹, A. Ledbetter¹, C. Bonner¹, M. Drees² and N. Saricifter² 1 Center for Organic Photonic Materials Research, Norfolk State University, Norfolk, USA, 2Institute for Organic Solar Cells, Johanne Kepler University, Linz, Austria  Photovoltaic Characteristics of Boron-incorporated Nanocrystalline Carbon on Silicon as Heterojunction Solar Cell  37-3  Z.Q. Ma¹, Q. Zhang², D.M. Wang¹, W. Li¹, Y. Wang¹, Z.X. Zhao¹  1. Microelectronic Group, Department of Physics, Shanghai University, P.R.China, 2 Department of Chemistry, Shanghai University, P.R.China, P.R.China, P.R.China, P.R.China, P.R.China, P.P., R. Dept. of Physics, Shanghai Jiao Tong Univ., P.R. China, P.R. Ch	36-5	1Solar Cells Research Center, Korea Institute of Energy Research, Korea* 2 School of Information and Communication Engineering,
Jung Hwan Lee* Jun Sik Cho*, Young Whan Baeg* and Donghwan Kim* 1: Department of Materials Science and Engineering, Korea University, Anam-dong, Korea 2: P&I R&D Center, Korea  Relationship of Structures and Photoelectric Properties of Novel Cyanine Dyes with Different Methine Chains as Sensitizers for Namocrystalline Solar Cell  Xiuying Chen ¹, Xiaojun Peng ¹-a, Jiahao Guo², Shengmin Cai ²-a 1 State key laboratory of fine chemicals, Dalian University of Technology, P.R.China, 2 College of Chemistry and Molecular Engineering, Peking University, P.R.China,  Etch-Induced Deposition of Si:H for Solar Cell Applications  Yuan-Min Li¹ and Zoltan J. Kiss 2,1 1Renewable Energy Solutions, Inc. (RESI), USA; 2TerraSolar Global, USA;  Physical Investigations on SnS/Ag Schottky Diodes  37-1  N. K. Reddy¹, K. Ramesh¹, K. T. R. Reddy²+ and R. W. Miles² 1Department of Physics, Indian Institute of Science, India, 2* Department of Physics, Sri Venkateswara University, India, 3School of Engineering, Northumbria University, Newcastle NE1 8ST, UK,  Optimizations of Organic and Polymeric Photovoltaic Materials and Devices  37-2  S. Sun¹+, C. Zhang¹, J. Haliburton¹, S. Choi¹, A. Ledbetter¹, C. Bonner¹, M. Drees² and N. Sariciftei² 1Center for Organic Photonic Materials Research, Norfolk State University, Norfolk, USA, 2Institute for Organic Solar Cells, Johanne Kepler University, Linz, Austria  Photovoltaic Characteristics of Boron-incorporated Nanocrystalline Carbon on Silicon as Heterojunction Solar Cell  37-3  Z. Q. Ma¹, Q. Zhang², D.M. Wang¹, W. Li¹, Y. Wang¹, Z. X. Zhao¹ 1 Microelectronic Group, Department of Physics, Shanghai University, P.R.China, 2 Department of Chemistry, Shanghai University, P.R.China,  Raman Spectroscopy of Carbon Nitride Films Prepared by Ion Beam Sputtering Technique  W. Jiang*, Z.B. Zhou, P.Q. Luo, X.D. Pu, Z.G. Liu, H.C. Yu, S.W. Ku, Q.H. Ye, R.Q. Cui, X.M. Dou Solar Energy Inst., Dept. of Physics, Shanghai Tiao Tong Univ., P.R. China  Defect Density Reduction in a-C Lavers for Coo'da-C Superlattice So		Control of Microstructure and Surface Morphology of Indium Tin Oxide Films by Changing Initial Growth Conditions
Nanocrystalline Solar Cell  Xiuying Chen <sup>1</sup> , Xiaojun Peng <sup>1,a</sup> , Jiahao Guo <sup>2</sup> , Shengmin Cai <sup>2,a</sup> 1 State key laboratory of fine chemicals, Dalian University of Technology, P.R.China, 2 College of Chemistry and Molecular Engineering, Peking University, P.R.China,  Etch-Induced Deposition of Si:H for Solar Cell Applications  36-8  Yuan-Min Li <sup>1</sup> and Zoltan J. Kiss 2,1 1Renewable Energy Solutions, Inc. (RESI), USA; 2TerraSolar Global, USA;  Physical Investigations on SnS/Ag Schottky Diodes  37-1  N. K. Reddy <sup>1</sup> , K. Ramesh <sup>1</sup> , K. T. R. Reddy <sup>2,a</sup> and R. W. Miles <sup>2</sup> 1Department of Physics, Indian Institute of Science, India, 2* Department of Physics, Sri Venkateswara University, India, 3School of Engineering, Northumbria University, Newcastle NE1 SST, UK,  Optimizations of Organic and Polymeric Photovoltaic Materials and Devices  37-2  S. Sun <sup>1,a</sup> , C. Zhang <sup>1</sup> , J. Haliburton <sup>1</sup> , S. Choi <sup>1</sup> , A. Ledbetter <sup>1</sup> , C. Bonner <sup>1</sup> , M. Drees <sup>2</sup> and N. Sariciftei <sup>2</sup> 1Center for Organic Photonic Materials Research, Norfolk State University, Norfolk, USA, 2Institute for Organic Solar Cells, Johanne Kepler University, Linz, Austria  Photovoltaic Characteristics of Boron-incorporated Nanocrystalline Carbon on Silicon as Heterojunction Solar Cell  37-3  Z.Q. Ma <sup>1</sup> , Q. Zhang <sup>2</sup> , D.M. Wang <sup>1</sup> , W. Li <sup>1</sup> , Y. Wang <sup>1</sup> , Z.X. Zhao <sup>1</sup> 1 Microelectronic Group, Department of Physics, Shanghai University, P.R.China, 2 Department of Chemistry, Shanghai University, P.R.China,  Raman Spectroscopy of Carbon Nitride Films Prepared by Ion Beam Sputtering Technique  W. Jiang*, Z.B. Zhou, P.Q. Luo, X.D. Pu, Z.G. Liu, H.C. Yu, S.W. Ku, Q.H. Ye, R.Q. Cui, X.M. Dou Solar Energy Inst., Dept. of Physics, Shanghai Jiao Tong Univ., P.R. China  Defect Density Reduction in aC. Lavers for C <sub>60</sub> /a-C Superlattice Solar Cells  Nobuaki Kojima, Takehiko Imaizumi, Takashi Terayama, Hidetoshi Suzuki and Masafumi Yamaguchi Toyota Technological Institute, Japan,	36-6	
1 State key laboratory of fine chemicals, Dalian University of Technology, P.R.China, 2 College of Chemistry and Molecular Engineering, Peking University, P.R.China,  Etch-Induced Deposition of Si:H for Solar Cell Applications  36-8  Yuan-Min Li ¹ and Zoltan J. Kiss 2,1 1 Renewable Energy Solutions, Inc. (RESI), USA; 2TerraSolar Global, USA;  Physical Investigations on SnS/Ag Schottky Diodes  37-1  N. K. Reddy¹, K. Ramesh¹, K. T. R. Reddy²* and R. W. Miles³ IDepartment of Physics, Indian Institute of Science, India, 2* Department of Physics, Sri Venkateswara University, India, 3School of Engineering, Northumbria University, Newcastle NE1 8ST, UK,  Optimizations of Organic and Polymeric Photovoltaic Materials and Devices  37-2  S. Sun¹*, C. Zhang¹, J. Haliburton¹, S. Choi¹, A. Ledbetter¹, C. Bonner¹, M. Drees² and N. Sariciftci² 1 Center for Organic Photonic Materials Research, Norfolk State University, Norfolk, USA, 2Institute for Organic Solar Cells, Johanne Kepler University, Linz, Austria  Photovoltaic Characteristics of Boron-incorporated Nanocrystalline Carbon on Silicon as Heterojunction Solar Cell  37-3  Z.Q. Ma¹, Q. Zhang², D.M. Wang¹, W. Li¹, Y. Wang¹, Z.X. Zhao¹ 1 Microelectronic Group, Department of Physics, Shanghai University, P.R.China,  Raman Spectroscopy of Carbon Nitride Films Prepared by Ion Beam Sputtering Technique  W. Jiang*, Z.B. Zhou, P.Q. Luo, X.D. Pu, Z.G. Liu, H.C. Yu, S.W. Ku, Q.H. Ye, R.Q. Cui, X.M. Dou Solar Energy Inst., Dept. of Physics, Shanghai Jiao Tong Univ., P.R. China  Defect Density Reduction in a-C Layers for Cov/a-C Superlattice Solar Cells  Nobuaki Kojima, Takchiko Imaizumi, Takashi Terayama, Hidetoshi Suzuki and Masafumi Yamaguchi Toyota Technological Institute, Japan,		
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	Y.J.Kim, H.H.Yang, W.J.Jeong, J.Y.Park, G.C.Park, H.D.Chung, C.D Kim*, H.R.Park* Dept. of Electrical Engineering, Mokpo National University * Dept. of Physics, Mokpo National University, South Korea
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	Growth Rate Controlling of μc-SiGe Films Prepared by Reactive Thermal CVD
52-8	Jianjun Zhang, Ying Zhao, Chunya Wu, Shaozhen Xiong, Xinhua Geng Tianjin Key Laboratory of Photo-electronic Thin Film Devices and Technology Institute of Photo-electronics, Nankai University, China
	Performance Silicon Solar Cell by Using Step Graded Si <sub>0.7</sub> Ge <sub>0.3</sub> Layer
53-1	Nji Raden Poespawati <sup>1</sup> , Arief Udhiarto <sup>2</sup> , Djoko Hartanto <sup>3</sup> , Gunawan Witjaksono <sup>4</sup> 1,2,3,4Department of Electrical Engineering, Faculty of Engineering, University of Indonesia, Kampus Baru UI, Indonesia
	The RISE-EWT Solar Cell – A New Approach Towards Simple High Efficiency Silicon Solar Cells
53-2	Peter Engelhart, Andreas Teppe, Agnes Merkle, Rainer Grischke, Rüdiger Meyer, Nils-Peter Harder, Rolf Brendel Institut für Solarenergieforschung GmbH Hameln/Emmerthal (ISFH), Germany
	Innovative Emitter Design and Metal Contact for Screen-Printed Solar Cells
53-3	S.R. Wenham <sup>1,2</sup> , L. Mai <sup>1</sup> , B. Tjahjono <sup>1</sup> , J. Ji <sup>2</sup> , Z. Shi <sup>2</sup> 1Centre for Photovoltaic Engineering, University of New South Wales, Australia, 2 Suntech Power Co. Ltd., China
	Crystallographic Properties of Large Grain Poly-Si Thin Films Deposited by Intermittent Source Gas Supply
53-4	Akiyoshi Ogane, Yu Takahashi, Yukiharu Uraoka, and Takashi Fuyuki Graduate School of Material Science, Nara Institute of Science and Technology (NAIST), Japan

	Electrical Properties around Grain Boundaryof Poly-Crystalline Silicon for Solar Cell EvaluatedUsing the Conductive AFM
53-5	Toru Ujihara <sup>1</sup> , Kazuo Nakajima <sup>2</sup> , Yoshikazu Takeda <sup>1</sup> 1Department of Crystalline Materials Science, Graduate School of Engineering, Nagoya University, JAPAN, 2 Institute for Materials Research, Tohoku University, JAPAN
	Study on Growth Behavior of Polycrystalline Silicon Thin Films on the Foreign Substrates
53-6	Shen Hui, Ai Bin Institute for Solar Energy System, Energy Engineering Academy, Sun Yat-Sen University, China
	Study on Defects Around Grain Boundaries in Cast-Grown Polycrystalline Silicon
53-7	K. Arafune, T. Sasaki, F. Wakabayashi, H. Sai, Y. Ohshita and M. Yamaguchi Semiconductor Labratory, Toyota Technological Institute, Japan
	Fabrication of Poly-Si Seed Layer by Aluminium- Induced Crystallisation of a-Si Deposited by PECVD or Sputtering
53-8	Per I. Widenborg, Sin Von Chan, Daniel Inns, and Armin G. Aberle Centre of Excellence for Advanced Silicon Photovoltaics and Photonics University of New South Wales, Australia
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54-1	Ding Shiming <sup>1</sup> , An Dawei <sup>2</sup> Hastitute of Air Conditioning of China Academy of Building Reach, 2School of Environment Science and Technology of TianJin University
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54-2	Cui Yan <sup>1,2</sup> , Song Chaoling <sup>2</sup> , Cai Binghuang <sup>2</sup> , Li Dayong <sup>1</sup> , Hu Hongxuan <sup>3</sup> , Dong Jingwei <sup>1</sup> , Shi Dequan <sup>1</sup> 1 Harbin University of Science and Technology, China, 2 Shantou University, China, 3 Shanghai Jiao Tong University, Shanghai, P.R.China Cui Yan: Engineering college, Shantou University, China
	Determination of I-V Characteristics of Solar Photovoltaic Module by Computer Controlled Loading
54-3	R.K. Nema <sup>1</sup> , Savita Nema <sup>2</sup> , Gayatri Agnihotri <sup>3</sup> Department of Electrical Engineering, M.A. National Institute of Technology, India
	A Solar Cell String Tester
54-4	Zhang Kenong, Zhang Qinglong, Lu Jiahua School of Eletrical Engineering, Xi'an Jiao Tong University, China
	Designing and Analyzing of 1kW Photovoltaic System in Beijing
54-5	Li yingzi <sup>1</sup> , Yin zhenyong <sup>1</sup> , Niu jincang <sup>2</sup> 1Department of Electrical Engineering and Automation, Beijing Institute of Civil Engineering & Architecture, China, 2Dispatching & Communication Center of Beijing Electric, China
	Photovoltaic Powered Mixture and Stock Solution Controller for The Plants by Hydroponics Method
54-6	Ratchadawan Nimnual and Khanchai Tunlasakun King Mongkut's University of Technology Thonburi, THAILAND.
	Computer Aided Design for Wind and PV Power Supply
54-7	Pan Jianbo <sup>1</sup> , Wang Sicheng <sup>2</sup> , Charlie Dou <sup>3</sup> 1-2 Beijing Jike Energy New Tech Development Company, 3 Beijing Bergey Wind Power Co. Ltd.,
	Application and Prospects on Wind-PV Hybrid Generating Electricity Household System
54-8	Li Defu <sup>1</sup> , Si Xinwen <sup>2</sup> Hinstitute of Electrical Engineering, Chinese Academy of Sciences, Haidian District, China, 2Department of Physics, Shanghai Jiao Tong University, China
	Development of a Reliable, Long Life PyranometerComposed of Multiple Photosensors
54-9	Keiji Hirata <sup>1</sup> , Kosuke Kurokawa <sup>1</sup> , Yukiharu Miyake <sup>2</sup> , Kouzou Nakamura <sup>2</sup> and Tadashi Kato <sup>2</sup> 1Tokyo University of Agriculture and Technology, Japan, 2EKO Instruments Trading Co., Ltd. Sasazuka Center Bldg, Japan
55-1	Investigation on Deposition of a-Si:H Films with Uniformity in Large Area Base on hw-mweer-CVD System
	Hu Yue-Hui <sup>1,2</sup> , He Bin <sup>1</sup> Chen Guang-Hua <sup>1</sup> 1 Department of Materials Science and Engineering, Beijing University of Technology, China,2 Institute of Jingdezhen Ceramic, China

	Research & Development On Luminescence Characteristics Of Nanocrystalline Silicon NC Si Films
55-2	Hexigema <sup>1</sup> , Qiangchen <sup>2</sup> 1,2Department of Science, BUAA university, China
	Cyanide Treatment for Polycrystalline Cu <sub>2</sub> O/ZnO Heterojunction Thin Films Grown by RF Magnetron Sputtering
55-3	H.sato <sup>1</sup> , Y.Nawa <sup>1</sup> , G.K.Paul <sup>1</sup> , M.Islam <sup>1</sup> , T.Sakurai <sup>1</sup> , K.Matsubara <sup>2</sup> , S.Niki <sup>2</sup> , N.Fujiwara <sup>3</sup> , H.Kobayashi <sup>3</sup> , K.Akimoto <sup>1</sup> 1Institute of Applied Physics, University of Tsukuba, Japan, 2 Energy Electronics Institute, National Institute of Advanced Industrial Science and Technology, Japan, 3The Institute of Scientific and Industrial Research, Osaka University, Japan
	The Role of Antireflective Coating in Micromorph Silicon Solar Cells
55-4	J. Krc, F. Smole and M. Topic University of Ljubljana, Faculty of Electrical Engineering, Slovenia
	Development of a Simple and Low Cost I-V Tracer and Its Application for Measuring the Characteristics of Solar Module
56-1	Wilson W. Wenas, Daniel Kurnia, Boaz Aryanto and Yuliar Firdaus Departement of Physics, Bandung Institute of Technology, II, Indonesia
56-2	Maximum Power Point Tracking Control of Photo-voltaic Power Generation System using an Online Monitor with L-C Resonant Circuit
30-2	Yusuke Ogata <sup>1</sup> , Shinji Nakahara <sup>2</sup> , Miki Kobayashi <sup>3</sup> , Yoshio Sawada <sup>4</sup> , and Ichiro Takano <sup>5</sup> All of Kogakuin University, Japan
	Fundamental Studies of Electrical Diagnoses of Failed Modules in PV Array
56-3	Takumi TAKASHIMA, Kenji OTANI, and Kazuhiko KATO Research Center for Photovoltaics (RCPV), National Institute of Advanced Industrial Science and Technology (AIST), JAPAN
	PV Impedance Characterization Using Square Wave Method and Frequency Response Analyzer
56-4	Chamnan Limsakul, Nattavut Chayavanich, Dhirayut Chenvidhya and Krissanapong Kirtikara Clean Energy System Group (CES) King Mongkut's University of Technology Thonburi, Thailand.
	Modelling and Performance Evaluation of Hybrid Solar Parabolic Trough Concentrator Systems
56-5	PANG Huey <sup>1</sup> #, LO, Edward W.C. <sup>1</sup> , CHUNG, T.S. <sup>1</sup> , CLOSE Josie <sup>2</sup> 1Department of Electrical Engineering, The Hong Kong Polytechnic University, China, 2Department of Architecture, The University of Hong Kong, 3/F Knowles Building, Pok Fu Lam Road, China
57-1	Influence of Substrate Roughness on the Quality of Thin-Film Polycrystalline-Silicon Solar Cells Made by Aluminium-Induced Crystallization
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	The Application of p-uc-Si Layers in Micromorph Solar Cells and Modules
57-2	Zhu feng, Zhao ying, Wei changchun, Ren huizhi, Xue junming, Zhang xiaodan, Gao yantao, Zhang dekun, Sun jian, Geng xinhua Institute of photo-electronics thin film devices and technique of Nankai University, Key Laboratory of photo-electronics thin film devices and technique of Tianjin, Key Laboratory of Opto-electronic Information Science and Technology Author
	Flexible Thin Film Amorphous and Microcrystalline Silicon Tandem Modules in the Temporary Superstrate Concept
57-3	M.N. van den Donker <sup>1</sup> , T. Repmann <sup>1</sup> , H. Stiebig <sup>1</sup> , F. Finger <sup>1</sup> , B. Rech <sup>1</sup> , B. Stannowski <sup>2</sup> , R. Schlatmann <sup>2</sup> , G.J. Jongerden <sup>2</sup> IInstitute of Photovoltaics, Forschungszentrum Juelich GmbH, Germany, 2Solar Cells R&D Dept., Akzo Nobel Research & Technology Center, The Netherlands
	Surface Textures for Large-grained Poly-silicon Thin-film Solar Cells On Glass Using the AIT Method
57-4	Patrick Campbell, Per I. Widenborg, Alistair Sproul and Armin G. Aberle Centre of Excellence for Advanced Silicon Photovoltaics and Photonics, University of New South Wales, Australia
	The Properties of Nitrogenated Amorphous Carbon Films Grown by Microwave Surface-wave Plasma CVD; Effects of Gas Composition Pressure
58-1	Sudip Adhikari <sup>1</sup> *, Hare Ram Aryal <sup>1</sup> , Ashraf M.M. Omer <sup>1</sup> , Sunil Adhikary <sup>2</sup> , Hideo Uchida <sup>2</sup> , Masayoshi Umeno <sup>2</sup> 1Department of Electronic Engineering, Chubu University, Japan, 2Department of Electronics and Information Engineering, Chubu University, Japan

	Microwave Surface-wave Plasma Chemical Vapor Deposited Amorphous Carbon Thin Films Aimed for the Application of Photovoltaic Solar Cells
	S. Adhikary <sup>1</sup> @, N. Furuichi <sup>2</sup> , T. Shinagawa <sup>2</sup> , Y. Kawahara <sup>2</sup> , O. Saiki <sup>2</sup> , H.R. Aryal <sup>2</sup> , D.C. Ghimire <sup>2</sup> , S. Adhikari <sup>2</sup> , A.M.M. Omer <sup>2</sup> , X.M. Tian <sup>1</sup> , H. Uchida <sup>1</sup> , M. Umeno <sup>1</sup> 1Department of Electronics and Information Engineering, Chubu University, Japan, 2 Department of Electrical and Electronic Engineering, Chubu University, Japan
50.2	Photovoltaic Characteristics of Iodine-doped Amorphous Carbon Thin Films Grown by Microwave Surface- Wave Plasma CVD
58-3	Masayoshi Umeno Department of Electronics and Information Engineering, Chubu University, Japan
	Characterization of Microcrystalline Germanium Carbon Thin Films – A Novel Absorber Material for PV Applications
58-4	Yasutoshi Yashiki, Shinsuke Miyajima, Akira Yamada <sup>1</sup> and Makoto Konagai Department of Physical Electronics, Tokyo Institute of Technology 1. Quantum Nanoelectronics Research Center, Tokyo Institute of Technology, Japan
	High Efficiency Back Contact Si Solar Cells Based on Industrial Technology
59-1	Kyotaro Nakamura <sup>1</sup> , Takayuki Isaka <sup>2</sup> , Yasushi Funakoshi <sup>2</sup> , Yoshifumi Tonomura <sup>2</sup> , Tomohiro Machida <sup>2</sup> and Koji Okamoto <sup>1</sup> SHARP Corporation, 1Solar Systems Development Center, 2Solar Systems Division, Engineering Dept, Japan
50.5	C-Si Thin-Film Solar Cells on Ceramic Substrates with SiC Intermediate Layers
59-2	Stefan Janz, Stefan Reber, Holger Habenicht Fraunhofer Institute for Solar Energy Systems, Heidenhofstrasse 2, Germany
	Minority Carrier Lifetime of Silicon Solar Cells Research and Measurement
59-3	Xun Ma, Zuming Liu, Tingjin Chen, Hua Liao, Jiehui Li, Jingtian Li Solar Energy Research Institute, Yunnan Provincial Renewable Energy Engineering Key Laboratory, Yunnan Normal University, China
	Development of High Throughput – High Yield Solar Ingots Manufacturing Process
59-4	A. Müller <sup>1,2</sup> , B.Geyer <sup>2</sup> , M.Ghosh <sup>2</sup> , R.Schindler <sup>3</sup> 2Deutsche Solar AG., Berthelsdorfer Str, Germany, 1corresponding author, 3 Fraunhofer Institute for Solar Energy Systems, Heidenhofstraße 2, Germany
	High Trap Densities in Wafers from Regions of Reduced Lifetime in Multicrystalline Silicon Blocks
59-5	Andreas Bentzen <sup>1</sup> , Harsharn Tathgar <sup>2</sup> , Julia Barthez <sup>1</sup> , and Arve Holt <sup>1</sup> 1Section for Renewable Energy, Institute for Energy Technology, Norway, 2ScanWafer AS, c/o Section for Renewable Energy, Institute for Energy Technology, Norway
	Efficient Silicon Heterojunction Solar Cells O N-Type and P-Type Substrates Processed at Low Temperatures
60-1	K. v. Maydell, E. Conrad and M. Schmidt Hahn-Meitner-Institute Berlin, Germany
	Large Area N-Type Multicrystalline Silicon Solar Cells with B-Emitter: Efficiencies Exceeding 14%
60-2	R. Kopecek <sup>1</sup> , T. Buck <sup>1</sup> , J. Libal <sup>1</sup> , R. Petres <sup>1</sup> , I. Röver <sup>2</sup> , K. Wambach <sup>2</sup> , R. Kinderman <sup>3</sup> , L. J. Geerligs <sup>3</sup> , P. Fath <sup>1</sup> 1University of Konstanz, Faculty of Sciences, Department of Physics, Jakob-Burckhardt-Str, Germany, 2Deutsche Solar AG, Alfred-Lange Str, Germany, 3Energy research Centre of the Netherlands - ECN, The Netherlands
	Bifacial Solar Cells on Multi-crystalline Silicon
60-3	A. Kränzl, R. Kopecek, B. Terheiden, P. Fath University of Konstanz, Faculty of Sciences, Department of Physics, Germany *now at: Institut für Solarenergieforschung GmbH Hameln, Germany
	<u>Fabrication of Novel Silicon Based Heterojunction Solar Cell by Using n-type Microcrystalline 3C-SiC</u>
60-4	<sup>1</sup> Chandan Banerjee*, <sup>1</sup> S. Miyajima, <sup>1</sup> K. L. Narayanan, <sup>2</sup> Akira Yamada and <sup>1</sup> Makoto Konagai 1Department of Physical Electronics, 2Quantum Nanoelectronics Research Center, Tokyo Institute of Technology, Japan
	High Quality Granular Polycrystalline Silicon for Efficient Low-Cost PV-Applications
60-5	P. Ege, B. Ceccaroli, R. Hamilton <sup>1</sup> , T. Hartmann, E. Macalalad, J. Maurits 1Solar Grade Silicon LLC, USA

61-1	Installation and Performance Evaluation of 100 kWp PV System in Tibet
	Jinsoo Song, Jae Ho Yun, Seok Ki Kim, Jeong Chul Lee, Se Jin Ahn, Kyung Hoon Yoon Li Junfeng*, Xu Honghua** Solar Cells Research Center, Korea Institute of Energy Research, Korea *Chinese Renewable Energy Industries Association, China, **Beijing Corona Science and Technology Co.Ltd., China
	New Storage PV Home Power Supply
61-2	JianPing Zhao, ShuKun Liu Baoding Tianwei Yingli New Energy Resources Co., Ltd, Baoding
	Off-Grid Electricity Supply with AC Coupling Further Trend for Solar Village Electrification in Provinces of China
61-3	Wollny, M.; Mark, P. SMA Technologie AG, Germany
	Toward High Efficient Polymer-Nanoparticle Photovoltaic Devices
62-1	T-W Zeng, <sup>1</sup> L-Y Wang, <sup>2,3</sup> C-A Dai, <sup>3,4</sup> C-W Chen, <sup>1</sup> W-F Su <sup>1,2,3</sup> 1 Department of Materials Science and Engineering, National Taiwan University, Taiwan, 2 Center of Condensed Matter, National Taiwan University, China, 3 Institute of Polymer Science and Engineering, National Taiwan University, China, 4 Department of Chemical Engineering, National Taiwan University, China
	Iron Disilicide (β-FeSi <sub>2</sub> ) Thin Film Formed by Sputtering on Stainless Steel Substrate for Solar Cell Application
62-2	Zhengxin Liu <sup>1,*</sup> , Masato Osamura <sup>1</sup> , Teruhisa Ootsuka <sup>1</sup> , Yasuhiro Fukuzawa <sup>2</sup> , Naotaka Otogawa <sup>2</sup> Yasuhiko Nakayama <sup>2</sup> , Hisao Tanoue <sup>3</sup> , Yunosuke Makita <sup>3</sup> 1 Technology Development Department, System Engineers' Co., Ltd., AIST Tsukuba West, Japan, 2 Kankyo Semiconductors Co., Ltd., AIST Tsukuba West, Japan, 3 National Institute of Advanced Industrial Science and Technology (AIST), AIST Tsukuba Central 2, Japan
	The Analysis of Key Factors to Determine the Electrochemical Activity of Fe:NiOx Film for Solar Cell
62-3	Li Hailing <sup>1</sup> , Wang Wenjing <sup>1</sup> , Kang Guohu <sup>1</sup> , Huang Jinzhao <sup>2</sup> , Xu Zheng <sup>2</sup> 1.Beijing solar energy resarch institute, China, 2.Laboratory of Materials for Information Storage and Display, Institute of Optoelectronic Technology, Beijing Jiaotong University, China
	Heat-Resistant Properties of CIGS-Based Thin Film Solar Cells
62-4	Shunsuke Kijima and Tokio Nakada Dept of Electrical Engineering and Electronics, Aoyama Gakuin University, Japan
63-1	Effects of Rapid Thermal Annealing and Hydrogen Passivation on Crystalline Silicon Thin-film Solar Cells on Glass made by PECVD Solid-Phase Crystallization
03-1	Mason L. Terry, Per I. Widenborg, Oliver Kunz and Armin G. Aberle Centre of Excellence for Advanced Silicon Photovoltaics and Photonics, University of New South Wales, Australia
	Direct Plasma Hydrogenation and SiN:H Hydrogenation of Thin-film Polycrystalline-Silicon Solar Cells
63-2	L. Carnel, I. Gordon, H.F.W. Dekkers, D. Van Gestel, K. Van Nieuwenhuysen, G. Beaucarne, J. Poortmans IMEC vzw, Belgium
63-3	Investigation on The Role of Hydrogen in Hydrogenated Microcrystalline Silicon and Its Growth Process under RF and VHF-PECVD Technique
03-3	Huidong Yang Department of Electronic Engineering, Jinan University, China
	Pole Fig.Characterization of μc-Si Photovoltaic Layers Prepared by VHF PECVD
63-4	Yasushi Sobajima <sup>1</sup> , Shinya Nakano <sup>1</sup> , Takafusa Kitagawa <sup>1</sup> , Tsuyoshi Sugano <sup>1</sup> , Toshihiro Toyama <sup>1</sup> , Hiroaki Okamoto <sup>1</sup> Shinya Honda <sup>2</sup> , Satoshi Omae <sup>2</sup> , Takashi Minemoto <sup>2</sup> , Hiroyuki Takakura <sup>2</sup> , and Yoshihiro Hamakawa <sup>2</sup> 1Department of Systems Innovation, Graduate School of Engineering Science, Osaka University, Japan, 2Faculty of Science and Engineering, Ritsumeikan University, Japan
	Development of Ultra Thin P-type Microcrystalline Silicon with High Conductivity and High Crystalline Volume by RF-PECVD at High Pressure
63-5	Guo Qunchao, Hou Guofu, Geng Xinhua, Xue Junming, Liu Jiayu Institute of photoelectronics thin film devices and technique of Nankai University Key Laboratory of photoelectronics thin film devices and technique of Tianjin Key Laboratory of Optoelectronic Information Science and Technology, Ministry of Education, China
63-6	Structural Change of Microcrystalline Silicon Thin Films Deposited by Hot Wire CVD and Its Influence on the Solar Cell Performance

	Shuichi Hiza <sup>1</sup> , Wataru Matsuda <sup>1</sup> , Akira Yamada <sup>2</sup> and Makoto Konagai <sup>1</sup> 1Department of Physical Electronics, Tokyo Institute of Technology, 2Quantum Nanoelectronics Research Center, Tokyo Institute of Technology, Japan
	Barrier Layers Deposited at Low Temperature on Metal Carrier Foil for the Use in µc-Si Solar Cells
63-7	M.Späth <sup>1</sup> , J. Löffler <sup>1</sup> , W. J. Soppe <sup>1</sup> C. Devilee <sup>1</sup> , X. Niquille <sup>2</sup> 1ECN Solar Energy, The Netherlands, 2Institut de Microtechnique, Université de Neuchâtel, Switzerland
	Study on Growth Mechanism of Polycrystalline Silicon Films Deposited at Low Temperature Using SiCl <sub>4</sub> H <sub>2</sub>
63-8	Xuanying Lin, Kuixun Lin, Yunpeng Yu, Rui Huang, Chuajun Huang, Junhong Wei, Zusong Zhu, Chuying Yu Department of Physics, Shantou University, China
	A Novel Design for Stand-alone PV Control System
64-1	Zhang Xianmou <sup>1,2</sup> , Lin Shaohua <sup>2</sup> , Xu Honghua <sup>1,2</sup> 1 Beijing Corona Science & Technology Co. Ltd., China, 2Institute of Electrical Engineering, Chinese Academy of Sciences, China
	Photovoltaic Array Shading Study
64-2	Jiehui LI <sup>1,2</sup> , Zuming LIU <sup>2</sup> 1 Kunming Photovoltaic Technology Ltd., China, 2 Solar Energy Research Institute, Yunnan Provincial Renewable Energy Engineering Key Laboratory Yunnan Normal University, China
	Evaluation on MPPT Methods of Photovoltaic Power Systems
64-3	Li Jing <sup>1</sup> , Dou Wei <sup>1</sup> , Xu Zheng-guo <sup>1,2</sup> , Peng Yan-chang <sup>1,2</sup> , Xu Hong-hua <sup>1,2</sup> 1 Institute of Electrical Engineering, Chinese Academy of Sciences, China, 2 Beijing Corona Science & Technology Co. Ltd., China
	Solar Panel Design, Manufacture and In-flight Performance for the Disaster Monitoring Constellation
64-4	Rick Kimber <sup>1</sup> , Guy Smekens <sup>2</sup> , Carlo Flores <sup>3</sup> 1Surrey Satellite Technology Limited, University of Surrey, United Kingdom, 2ENE, Avenue van der, Belgium, 3CESI-ASP, Via, Italy
	A Solar Pumping System of High Voltage, High Power and High Outflow Rate
64-5	Lei Ting, Yu Guoguang, Gao Yan, Zhang Shengzhong, Wu Jinsheng, Li Weijiang Xinjiang Sunoasis Co., Ltd., China
	PV Powered Biological Treatment & UV Disinfection Wastewater Recycling
64-6	Josie Close <sup>1</sup> , Jasper Ip, and Lam King-hang Centre of Renewable Energy, University of Hong Kong
	Rate of Self-consumption of PV Output in a Residential House
64-7	Shogo Nishikawa <sup>1</sup> , Hiroyuki Sugihara <sup>2</sup> 1College of Science and Technology, Nihon University, Japan, 2Kandenko co., ltd., Japan
	Construction of Photovoltaic Power Station in Suzhou Region and its Scenario Analysis
64-8	Lingjun Zhang, Jinfeng Hu CSI solar Manufacture Inc. Building A6,Export processing zone,Suzhou New &Hitech distric, China
	Development of Efficient Thin-Film Polycrystalline-Silicon Solar Cells based on Aluminium- Induced Crystallization
65-1	I. Gordon, L. Carnel, D. Van Gestel, K. Van Nieuwenhuysen, G. Beaucarne, and J. Poortmans IMEC vzw, Belgium
	Fabrication of Relatively High Growth Rate Microcrystalline Silicon Thin Films and Its Application in Solar Cells
65-2	Gao Yantao Zhang Xiaodan Zhao Ying Sun Jian Zhu Feng Wei Changchun Wang Yan Han XiaoYan Institute of photo-electronic thin film devices and technology of Nankai University, China, Key Laboratory of Opto-electronic Information Science and Technology (Nankai University, Tianjin University), Ministry of Education, China
	Influences of Discharge Power and Total Flow Rate in the High Rate Deposition of μc-Si:H Solar Cells by PECVD
65-3	Y. Mai <sup>1,2</sup> , S. Klein <sup>1</sup> , R. Carius <sup>1</sup> , T. Repmann <sup>1</sup> , X. Geng <sup>2</sup> and F. Finger <sup>1</sup> 1IPV, Forschungszentrum Jülich GmbH, Germany, Institute of Photoelectronics, Nankai University, China
65-4	Studies on Transport and Structural Properties of Si:H Network in the Amorphous-to-microcrystalline Transition Phase

	Tick induced POC as in The december 1911,
65-5	Light-induced Effects in Undoped Polycrystalline Silicon Films Prepared From SiCl4/H2 Mixture  Zhu Zu-song Lin Xuan-ying Lin Kui-xun Qiu Gui-ming Huang Rui Yu yun-peng Wang Zhao-kui Wei Jun-hong  Department of Physics, Shantou University, China,* Project supported by the State Key Development Program for Basic Research of China
	Polycrystalline Silicon Thin Films by Solid Phase Crystallization for Solar Cell Applications
65-6	Qi Wang <sup>1</sup> , Paul Stradins, David L. Young, Bob Reedy, Yanfa Yan, Eugene Iwaniczko, and Howard M. Branz lNational Renewable Energy Laboratory
	The Role of Oxygen in the Structural Properties of Microcrystalline Silicon Thin Films
65-7	Zhang Xiaodan, Zhao Ying, Gao Yantao, Zhu Feng, Wei Changchun, Sun Jian, Chen Fei, Geng Xinhua, Xiong Shaozhen Institute of photo-electronic thin film devices and technology of Nankai University, Tianjin, Key Laboratory of photo-electronic thin film devices and technology of Tianjin, Tianjin, Key Laboratory of Opto-electronic Information Science and Technology, Ministry of Education, Tianjin
	Hydrogen Induced Passivation of Fine-Grained Polycrystalline Silicon Films
65-8	A. Slaoui, E. Pihan, I. Ka, N.A. Mbow, S. Roques, J.M. Koebel InESS-CNRS, France
	Surface Morphology and Defects of Polycrystalline Silicon Thin Film
66-1	Hu Yunfei <sup>1</sup> , Guo Zhiqiu <sup>3</sup> , Liu Xiyun <sup>3</sup> Liang Zongcun <sup>1</sup> Shen Hui <sup>2</sup> 1 Guangzhou Institute of Energy Conversion, CAS, China, 2 Institute of Solar Energy System, Zhongshan University, China, 3Collo of Mechanical Engineering, South China University of Technology, China
	New Concepts to Obtain High Efficiency Microcrystalline Silicon Solar Cells Made at High Deposition Rates
66-2	Aad Gordijn, J.K.Rath*, R.E.I.Schropp Utrecht University, SID-Physics of Devices, The Netherlands
	Investigation of Microcrystalline Silicon Film Prepared by Layer-By-Layer Technology
66-3	HU Yue-Hui <sup>1,2</sup> , Zhang wen-Li <sup>1</sup> Chen Guang-Hua <sup>1</sup> 1 Department of Materials Science and Engineering, Beijing University of Technology, China, 2 Institute of Jingdezhen Ceramic, China
	Controlling of the Structural Properties of Thin-film Crystalline Si by Ge Incorporation
66-4	Kunihiro Kawamoto, Masaki Shima, Akira Terakawa, Kenji Murata and Makoto Tanaka Advanced Energy Research Center, Sanyo Electric Co., Ltd, Japan
	Fabrication and Application Nanocrystalline Thin Film Deposited by PECVD
66-5	Cai Hong-kun, Zhang De-xian, Feng Kai, Qi Long-yin, Sun Yun Department of Information Technology and Science, Nankai University, China
	Nanocrystalline Silicon Film Characteristics at Low Temperature by RF-sputtering
66-6	Meng F.Y., Tang D.Y, Lin S.Q., Si X.W., Yu H.C., Cui R.Q. Department of Physics, Shanghai Jiao Tong University, China
	Influence of p-layer on Characteristics of Absorber Layer and Microcrystalline Silicon Thin Film Solar Cells
66-7	Swati Ray, Koel Adhikary, Amartya Chowdhury and Sumita Mukhopadhyay Energy Research Unit, Indian Association for the Cultivation of Science, adavpur, India
	Effects of Hydrogen on the Properties in Nanocrystalline Silicon Films by RF-Sputtering
66-8	Meng F.Y., Sun T.T., Si X.W., Tang D.Y., Xu L., Zhou Z.B. Cui R.Q Department of Physics, Shanghai Jiao Tong University, China
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67-1	J. Libal <sup>1</sup> , R. Petres <sup>1</sup> , R. Kopecek <sup>1</sup> , G. Hahn <sup>1</sup> , M. Vetter <sup>2</sup> , I. Roever <sup>3</sup> , K. Wambach <sup>3</sup> , P. Fath <sup>1</sup> 1University of Konstanz, Faculty of Sciences, Department of Physics, Germany, 2Universitat Politecnica de Catalunya, Dept. Enginyeria Electronica, Spain 3Deutsche Solar AG, Germany

	Frédéric Dross, Emmanuel Van Kerschaver, Guy Beaucarne Silicon Solar Cell group, IMEC, Belgium
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67-5	S. Sridharan <sup>1</sup> *, S. Kim <sup>2</sup> , C. Khadilkar <sup>1</sup> , A. Shaikh <sup>2</sup> , and D. Gnizak <sup>1</sup> 1Ferro Corporation, Posnick Center for Innovative Technology, USA, 2 Ferro Corporation, Electronic Materials System, USA
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67-6	Ding Bingbing Guangzhou Ruxing Technology Development Co., Ltd Guangzhou Research Institute of Synthetic Materials, China
	Electronic Transport Properties of B-doped Polycrystalline Silicon Thin Films Prepared on Quartz Substrates
67-7	Ai Bin <sup>1</sup> , Shen Hui <sup>1</sup> , Kong Guanglin <sup>2</sup> , Liao Xianbo <sup>2</sup> 1Institute for Solar Energy System, Energy Engineering Academy, Sun Yat-Sen University, China, 2State Key Laboratory for Surface Physics, Institute of Semiconductors, Chinese Academy of Sciences, China
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	AFORS-HET, Version 2.1, a Numerical Computer Program for Simulation of (thin film) Heterojunction Solar Cells
68-1	R. Stangl <sup>1</sup> *, M. Kriegel <sup>1</sup> , D. Schaffarzik <sup>1</sup> , M. Schmidt <sup>1</sup> 1Hahn-Meitner Institute Berlin (HMI), Germany
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68-2	Hasna Hamzaoui, Ahmed S. Bouazzi & Bahri Rezig PV & Semicond. Mat. Lab. –ENIT, University of Tunis El Manar, Tunisia
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68-3	Heiko Plagwitz, Andreas Wolf, Barbara Terheiden, and Rolf Brendel Institut fuer Solarenergieforschung GmbH Hameln/Emmerthal (ISFH), Germany
	Electrical Properties of 10×10 cm2 HIT Solar Cells with Screen-printed Metal Grids Manufactured on Textured p-type mc-Si Substrates
68-4	M. Scherff <sup>1</sup> , H. Windgassen <sup>2</sup> , Y. Ma <sup>1,*</sup> , H. Stiebig <sup>3</sup> , T. Mueller <sup>1</sup> , W. R. Fahrner <sup>1</sup> 1: Chair of Electronic Devices, University of Hagen, Germany, 2: Chair and Institute of Semiconductor Electronics, Aachen University, Germany, 3: Institute of Photovoltaics, Research Centre Jülich, Germany
	Intensity Dependent Surface Photovoltage used for Interface Characterization of c-Si surfaces and a-Si:H/c-Si Heterojunctions
68-5	R. Stangl <sup>1</sup> *, D. Schaffarzik <sup>1</sup> , E. Rudigier <sup>1</sup> , M. Schmidt <sup>1</sup> 1Hahn-Meitner Institute Berlin (HMI), Germany
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	Silicon Heterojunction Solar Cells with Hydrogenated-Amorphous Silicon Emitters and Back-Surface-Field Contacts
68-7	T.H. Wang, M.R. Page, E. Iwaniczko, Y. Xu, Q. Wang, Y. Yan, D. Levi V. Yelundur*, A. Rohatgi*, H.M. Branz National Renewable Energy Laboratory, USA *Georgia Institute of Technology, USA
68-8	Capacitance-Voltage Study of a-SiCN:H / Si Interfaces Fabricated by Hotwire Chemical Vapor Deposition Using Hexamethyldisilazane

	Amornrat Limmanee <sup>1</sup> , Michio Otsubo <sup>1</sup> , Takehiko Sato <sup>2</sup> , Shinsuke Miyajima <sup>1</sup> , Tatsuro Watahiki <sup>1</sup> , Adash Sandhu <sup>3</sup> , Akira Yamada <sup>3</sup> and Makoto Konagai <sup>1</sup> 1Department of Physical Electronics, Tokyo Institute of Technology, Japan, 2Material & Process Technology Department, Advanced Technology R&D Center, Mitsubishi Electric Corporation, Japan, 3Quantum Nanoelectronics Research Center, Tokyo Institute of Technology, Japan
	Indicator of Evaluation Performance of Photovoltaic Systems
69-1	Yang Jinhuan, Tan Beiyu, Ge Liang, Chen Zhonghua, Jiang Xiuli, Gao Lanxiang Solar Energy Research Group, Shanghai University of Electric Power, China
	Solder Version of 8 Inch Back-contacted Solar Cells
69-2	M.Späth <sup>1</sup> , P.C. de Jong <sup>1</sup> , S. Lust <sup>2</sup> , H. Clasen <sup>2</sup> 1ECN Solar Energy, The Netherlands, 2Q-cells AG, Germany
	Simulation of PV Module Connection Method to Minimize the Output Lowering of the Shaded PV Array
69-3	Masaaki Inoue, Sanshiro Yamanaka, Hajime Kawamura, Hideyuki Ohno, Hideaki Kawamura Department of Electrical and Electronic Engineering, Meijo University, Japan
	Recycling Loop Test of the Expanded 16-cells Recyclable PV-module
69-4	Takuya DOI <sup>1</sup> , Sanekazu IGARI <sup>2</sup> , Izumi TSUDA <sup>3</sup> , Koichi SAKUTA <sup>4</sup> 1Research Center for Photovoltaics, National Institute of Advanced Industrial Science and Technology (AIST) AIST Central 2, Japan, 2Research Center for Photovoltaics, National Institute of Advanced Industrial Science and Technology (AIST) AIST Central 2, Japan, 3Technology Information Department, National Institute of Advanced Industrial Science and Technology (AIST) AIST Central 2, Japan, 4Research Center for Photovoltaics, National Institute of Advanced Industrial Science and Technology (AIST) AIST Central 2, Japan
	The Optimum Output and Cost Selection Of Versatile Production in PV Modules Enterprise
69-5	Shi Shanglin <sup>1</sup> , Zuoyan <sup>2</sup> 1Xi'an REW Co., Ltd, China
	Thought after PV Power Station was Built
69-6	Li Jingtian <sup>12</sup> Liao Hua <sup>12</sup> Liu Zuming <sup>1</sup> Li Jiehui <sup>2</sup> 1 Solar Energy Institute, Yunnan Normal University, China, 2 Kunming Photovoltaic Technology Lit. Co, China
	Resonant Ballast for Photovoltaic Powered Street Lighting System in Remote Rural Area
69-7	Tanes Tanitteerapan and Suriyan Pan-A Power Electronics and Circuit Systems Laboratory, Department of Electrical Technology Euducation, King Mongkut's University of Technology Thonburi, Thailand
	Design and Evaluation of High-performance Solar Electric Car
69-8	DENG Tao <sup>1,2,3</sup> , SHEN Hui <sup>1,2</sup> , WANG donghai <sup>1,2</sup> , DENG youjun <sup>1,2</sup> 1School of Physics Science and Engineering, Sun Yat-sen University, China, 2Institute for Solar Energy System, Sun Yat-sen University, China, 3Solar Energy Research Center for Sun Yat-sen University and Bailixing, China
	Study of Technics for Encapsulating Glass-glass Solar Modules
69-9	Zhang Zhen <sup>1,2</sup> , Shen Hui <sup>2</sup> , Li Wan ping <sup>1</sup> Guangzhou Pearl River Telecom. Equipment Manufacturing Co. Ltd., China, 2. The School of Physics and Engineering, Zhongshan University, China
	Ga Content Dependence of Cell Performance for Bifacial CIGS Thin Film Solar Cells
70-1	Yosuke Kanda, Shunsuke Kijima, Yusuke Komiya, Hiroki Ishizaki, Naoomi Yamada, and Tokio Nakada Dept. of Electrical Engineering and Electronics, Aoyama Gakuin University, Japan
	<u>Investigations on the Structural Properties of Sprayed In<sub>2</sub>O<sub>3</sub> Films</u>
70-2	P. Prathap, Y. P. V. Subbaiah, M. Devika and K. T. Ramakrishna Reddy* *Thin Film Laboratory, Department of Physics, Sri Venkateswara University, India
	Synthesis of Photovoltaic Thin Films by Hydrothermal Crystallization
70-3	Tong Ren, Rui Yu, Zhibin Lei, Guoqing Jia, Jing Zhang, Can Li* State Key Laboratory of Catalysis, Dalian Institute of Chemical Physics, Chinese Academy of Sciences, China
AD-1	SISP' S Development on 28% Efficient Triple- junction GaAs Solar Cells for Space

	J.L.Tu <sup>1,3</sup> , L. X. Wang <sup>1</sup> , Z. W. Zhang <sup>1</sup> , B. Wan, L.Y. Zeng <sup>1</sup> , C.Q. Chen <sup>1</sup> , M. B. Chen <sup>1</sup> , X. B. Xiang <sup>2</sup> , X. B. Liao <sup>2</sup> 1 Shanghai Institute of Space Power Sources, China, 2The Institute of Semiconductors, Chinese Academy of Sciences, China, 3Solar Energy Research Institute, Yunnan Normal University, China
	Electron Radiation Study of GaInP2/GaAs/Ge Solar Cell
	Wan Bin <sup>1,2</sup> , Tu JieLei <sup>1</sup> , Zeng LongYue <sup>1</sup> , Wang LiangXing <sup>1</sup> , Chi WeiYing <sup>1</sup> , Chen ChaoQi <sup>1</sup> 1 ShangHai Institute of Space Power-Sources, China, 2 Institute of Material, Shanghai University, China
	An Auto-Bonding Technique of Coverglass for Space Solar Cells
	Wang xunchun <sup>1</sup> , Chen mingbo <sup>1</sup> , Zhang zhongwei <sup>1</sup> , Tang zeqi <sup>1</sup> , Cai shiming <sup>1</sup> , Zhao yanzheng <sup>2</sup> , Fu zhuang <sup>2</sup> , 1 Shanghai Institute of Space Power-sources, China, 2The Robotics Institute, School of Mechanical Engineering, Shanghai Jiao Tong University, China
	Large Area Solar Cells Module Laminating Technology Research
	X. Yuan <sup>1</sup> , H. B. Li <sup>2</sup> , W. Z. Shi <sup>1</sup> 1 Shanghai Solar Energy S&T Co., Ltd (SSEC) China, 2 Shanghai Institute of Space Power Source (SISP), China
	Analyzing Zigzag Reflection in GaInP2/InGaAs/Ge Solar Cells
	Wang Liangxing, Tu Jielei, Zeng Lengyue, Wan bin Ye Xiaojun, Li Hongbo, Chen Mingbo, Chen Chaoqi, Li Zhigang Shanghai Institute of Space Power Sources, Shanghai
	Structural Design of GaAs Poly-crystal Film Solar Cell
	J.L. Tu <sup>1,2</sup> , T.J. Chen <sup>1</sup> L.F.Wang <sup>1</sup> Y.D. Song <sup>1</sup> C.J. Zhang <sup>1</sup> Z.S Shi <sup>1</sup> X. Liu <sup>1</sup> 1Solar Energy Research Institute, Yunnan Normal University, China, 2 Shanghai Institute of Space Power Sources, China
	High Efficiency Silicon Solar Cells for Space Use
	T. T. Yu, M. B. Chen, H. B. Li, Z. Liu, H. Zhou, X. C. Hao, Y. S. Xue Shanghai I, Shangha Institute of Space Power Sources, China
	The Status and Developing Trend of China Space Photovoltaic Application
	Z.Q. Tang, D.P. Jiang, G. X. Li, M.B.Chen, Y. Qian Shanghai Institute of Space Power-Sources, China
	The High Efficiency of the Graded Optical Band Gap na-Si:H Solar Cell Prepared by PECVD
AD-9	Huacong Yu <sup>1,2</sup> , Rongqiang Cui <sup>1</sup> , Fanying Meng <sup>1</sup> , Chunjiang Zhao <sup>1,2</sup> ,He Wang <sup>3</sup> , Hong Yang <sup>3</sup> Hong Chen <sup>1</sup> ,Peiqing Luo <sup>1</sup> ,Dunyi Tang <sup>1</sup> ,Shuquan Lin <sup>1</sup> ,Yuliang He <sup>1</sup> ,Tietun Sun <sup>1</sup> ,Qinghao Ye <sup>1</sup> 1 Solar Energy Institute, Shanghai Jiaotong University, China, 2 Shanghai Linyang Solar Energy Science & Technology Co.,Ltd., China, 3 Solar Energy Institute, Xi'an Jiaotong University, China
	High Stable Efficiency Double Junction Amorphous Silicon Tandem Solar Cell Deposited by RF-PECVD
1-1	Yan Wang <sup>1</sup> , Huizhi Ren <sup>1</sup> , Guofu Hou <sup>1</sup> , Pei Dong <sup>1</sup> , Junming Xue <sup>1</sup> , Jian Sun <sup>1</sup> , Ying Zhao <sup>1</sup> , Xinhua Geng <sup>1</sup> , Xiaoyan Han 1 Institute of Photo-Electronics Thin Film Devices and Technology, Nankai University Key Laboratory of Photo-Electronics Thin Film Devices and Technique of Tianjin Key Laboratory of Opto-electronic Information Science and Technology, Nankai University, Ministry of Education, 2 Lab of Information and Functional Materials, Hebei University of Technology
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1 -2	Hongwei Han <sup>1</sup> , Jianhua Wei <sup>1</sup> , Jing Zhang <sup>1</sup> , Wei Liu <sup>1</sup> , Kan Liu <sup>1</sup> , Shengxiang Wang <sup>1</sup> , Xiaohua Sun <sup>1</sup> , Conghua Zhou <sup>1</sup> , Jiasheng Zhong <sup>2</sup> , Kongqi Ding <sup>3</sup> , Kongxian Ding <sup>3</sup> , Xingzhong Zhao <sup>1</sup> *  1 Department of Physics, Wuhan University, China, 2 Department of Chemistry, Wuhan University, China 3 Wuhan JiaWei Industries Co., LTD., China
	Light at Ambient Temperature
	Thomas Prevenslik Consultant, 3F Mountain View, Discovery Bay, China
P-4	Consultant, 3F Mountain View, Discovery Bay, China

P-6  Nu Wei-Wei, Dai Song-Yuan*, Wang Kong-Jia Institute of Plasma Physics, Chinese Academy of Sciences, China  Senaration of p-n Junction by Back Etching  Liu Zhigang*, Sun Tietun*, Ku Shiwei, Zhou Zhibin, Jiang Wei, Luo Peiqing, Yu Huacong, Cui Rongqiang IDepartment of Physics, Shanghai Jiao Tong University, China, 2 Department of Physics, Shanghai Jiao Tong University Comparative Study of Multicrystalline Silicon Texturing with Different Chemicals for Solar Cell Fabrication  P-10  Kyunghae Kim, S. K. Dhungel, U. Gangopadhyay, U. Manna, J. Yi School of information and Communication Engineering, Sungkyunkwan University Korea  Texture Etching of Multicrystalline Si by Atomic Hydrogen Generated by Hot Wire Method  P-11  Takchiko Salo*, Michio Ohtsubo*, Shigeru Matsuno*, and Makoto Konagai* I Material & Processing Technology Department, Advanced Technology, R&D Center, Mitsubishi Electric Corporation, Japan, 2 Department of Physical Electronics, Tokyo Institute of Technology, Japan  Development about Texturing Multicrystalline Silicon Solar Cells  P-12  Liu Zhigang, Sun Tietun, Ku Shiwei, Luo Peiqing, Jiang Wei, Yu Huacong, Cui Rongqiang Department of Physics, Shanghai Jiao Tong University, China  Characteristics of Multi-crystalline Silicon in High Temperature Annealing  P-13  Xianfang Gou¹², Shuang Song² Lifen Ma¹² Bingyan Ren¹ Xudong Li² Ying Xu² Wenjing Wang² 1. Institute of Information Function Materials, Hebei University of Technology, China, 2. Beijing Solar Energy Research Institute, 3/ Huayuan Road,Haliban District Beijing, China  Development of Improved Screen Printed Albased Paste for Crystalline Silicon Solar Cells  P-14  V. Mikhitaryan¹, A. Kravtchenko¹, S. Garanzha¹, O. Tehaplygina¹ I. Melnyk², P. Fath² 1 JSC Analog, Russia, 2 Department of Physics, University of Konstanz, Germany  Behavior of Fe Impurity in Ga-doped Multicrystalline Silicon Solar Cells  P-15  M. Dhamrin¹, T. Saitoh¹, K. Kamisako¹, T. Hirasawa², T. Eguchi² and I. Yamaga² 1 Tokyo Univ. of Agr. & Tech., Japan, 2Dai-ichi Kiden Corp., J
Institute of Plasma Physics, Chinese Academy of Sciences, China  Separation of p-n Junction by Back Etching  Liu Zhigang <sup>1</sup> , Sun Tietun <sup>2</sup> , Ku Shiwei, Zhou Zhibin, Jiang Wei, Luo Peiqing, Yu Huacong, Cui Rongqiang IDepartment of Physics, Shanghai Jiao Tong University, China, 2 Department of Physics, Shanghai Jiao Tong University, China, 2 Department of Physics, Shanghai Jiao Tong University, China, 2 Department of Physics, Shanghai Jiao Tong University, China, 2 Department of Physics, Shanghai Jiao Tong University, China, 2 Department of Physics, Shanghai Jiao Tong University, China Comparative Study of Multicrystalline Silicon Texturing with Different Chemicals for Solar Cell Fabrication  P-10 Kyunghae Kim, S. K. Dhungel, U. Gangspadhyay, U. Manna, J. Yi School of information and Communication Engineering, Sungkyunkwan University Korea  Texture Etching of Multicrystalline Silv Atomic Hydrosen Generated by Hott Wire Method  P-11 Takehiko Sato <sup>1</sup> , Michio Ohtsubo <sup>2</sup> , Shigeru Matsuno <sup>1</sup> , and Makoto Konagai <sup>2</sup> 1 Takehiko Sato <sup>1</sup> , Michio Ohtsubo <sup>2</sup> , Shigeru Matsuno <sup>1</sup> , and Makoto Konagai <sup>2</sup> 1 Takehiko Sato <sup>1</sup> , Michio Ohtsubo <sup>2</sup> , Shigeru Matsuno <sup>1</sup> , and Makoto Konagai <sup>2</sup> 1 Takehiko Sato <sup>1</sup> , Michio Ohtsubo <sup>2</sup> , Shigeru Matsuno <sup>1</sup> , and Makoto Konagai <sup>2</sup> 1 Development about Texturing Multicrystalline Silicon Solar Cells  P-12 Liu Zhigang, Sun Tietun, Ku Shiwei, Luo Peiqing, Jiang Wei, Yu Huacong, Cui Rongqiang Department of Physics, Bhanghai Jiao Tong University, China  Characteristics of Multi-crystalline Silicon in High Temperature Annealing  Characteristics of Multi-crystalline Silicon in High Temperature Annealing  P-13 Xianfang Gou <sup>1/2</sup> , Shuang Song <sup>2</sup> Lifer Ma <sup>1/2</sup> Bingyan Ren <sup>1</sup> Xudong Li <sup>2</sup> Ying Xu <sup>2</sup> Wenjing Wang <sup>2</sup> 1 Institute of Information Function Materials, Hebei University of Technology, China, 2 Beijing Solar Energy Research Institute, 3/  1 Hua Yuan Road, HaiDian District Beijing, China  Development of Improved Screen Printed Albased Paste for Crystalline Silicon Solar Cells  P-14 W. Mikhitaryan <sup>1</sup> ,
P-10 Liu Zhigang <sup>1</sup> , Sun Tietun <sup>2</sup> , Ku Shiwei, Zhou Zhibin, Jiang Wei, Luo Peiqing, Yu Huacong, Cui Rongqiang IDepartment of Physics, Shanghai Jiao Tong University, China, 2 Department of Physics, Shanghai Jiao Tong University, China Comparative Study of Multicrystalline Silison Texturing with Different Chemicals for Solar Cell Fabrication  P-10 Kyunghae Kim, S. K. Dhungel, U. Gangopadhyay, U. Manna, J. Yi School of information and Communication Engineering, Sungkyunkwan University Korea  Texture Etching of Multicrystalline Sil by Atomic Hydrogen Generated by Hot Wire Method  P-11 Takchiko Sato <sup>1</sup> , Michio Ohtsubo <sup>2</sup> , Shigeru Matsuno <sup>1</sup> , and Makoto Konagai <sup>2</sup> 1 Material & Processing Technology Department, Advanced Technology R&D Center, Mitsubishi Electric Corporation, Japan, 2 Department of Physical Electronics, Tokyo Institute of Technology, Japan  Development about Texturing Multicrystalline Silicon Solar Cells  Liu Zhigang, Sun Tietun, Ku Shiwei, Luo Peiqing, Jiang Wei, Yu Huacong, Cui Rongqiang Department of Physics, Shanghai Jiao Tong University, China  Characteristics of Multi-crystalline Silicon in High Temperature Annealing  P-13 Xianfang Gou <sup>12</sup> , Shuang Song <sup>2</sup> Lifen Ma <sup>12</sup> Bingyan Ren <sup>1</sup> Xudong Li <sup>2</sup> Ying Xu <sup>2</sup> Wenjing Wang <sup>2</sup> 1. Institute of Information Function Materials, Hebei University of Technology, China, 2.Beijing Solar Energy Research Institute, 3/Hua <sup>2</sup> Uana Road, HaiDian District Beijing, China  Development of Improved Screen Printed Albased Paste for Crystalline Silicon Solar Cells  P-14 V. Mikhituryan <sup>1</sup> , A. Kravtchenko <sup>1</sup> , S. Garanzha <sup>1</sup> , O. Tchaplygina <sup>1</sup> I. Melnyk <sup>2</sup> , P. Fath <sup>2</sup> 1 JSC Analog, Russia, 2 Department of Physics, University of Konstanc, Germany  Behavior of Fe Impurity in Gia-doped Multicrystalline Silicon Solar Cells  M. Dhamrin <sup>1</sup> , T. Saitoh <sup>1</sup> , K. Kamisako <sup>1</sup> , T. Hirasawa <sup>2</sup> , T. Eguchi <sup>2</sup> and I. Yamaga <sup>2</sup> 1 Tokyo Univ. of Agr. & Tech., Japan, 2Dai-ichi Kiden Corp., Japan  Effect of Thermal Annealing on Oxygen Behavior and Minority-Carrier Lifetimes in Polycrystalline Sil
Liu Zhigangi, Sun Tieturi, Ku Shiwei, Zhou Zhibin, Jiang Wei, Luo Peiqing, Yu Huacong, Cui Rongqiang  Comparative Study of Multicrystalline Silicon Texturing with Different Chemicals for Solar Cell Fabrication  Ryunghae Kim, S. K. Dhungel, U. Gangopadhyay, U. Manna, J. Yi School of information and Communication Engineering, Sungkyunkwan University Korea  Texture Etching of Multicrystalline Sil by Atomic Hydrogen Generated by Hot Wire Method  P-11  Takchiko Sato <sup>1</sup> , Michio Ohtsubo <sup>2</sup> , Shigeru Matsuno <sup>1</sup> , and Makoto Konagai <sup>2</sup> I Material & Processing Technology Department, Advanced Technology R&D Center, Mitsubishi Electric Corporation, Japan, 2 Department of Physical Electronics, Tokyo Institute of Technology, Japan  Development about Texturing Multicrystalline Silicon Solar Cells  P-12  Liu Zhigang, Sun Tietun, Ku Shiwei, Luo Peiqing, Jiang Wei, Yu Huacong, Cui Rongqiang Department of Physics, Shanghai Jiao Tong University, China  Characteristics of Multi-crystalline Silicon in High Temperature Annealing  Xianfang Gou <sup>12</sup> , Shuang Song <sup>2</sup> Lifen Ma <sup>12</sup> Bingyan Ren <sup>1</sup> Xudong Li <sup>2</sup> Ying Xu <sup>2</sup> Wenjing Wang <sup>2</sup> I. Institute of Information Function Materials, Hebei University of Technology, China, 2. Beijing Solar Energy Research Institute, 34 HuaYuan Road-Halibian District Beijing, China  Development of Improved Screen Printed Albased Paste for Crystalline Silicon Solar Cells  V. Mikhitaryan <sup>1</sup> , A. Kravtchenko <sup>1</sup> , S. Garanzha <sup>1</sup> , O. Tchaplygina <sup>1</sup> I. Melnyk <sup>2</sup> , P. Fath <sup>2</sup> I JSC Analog, Russia, 2 Department of Physics, University of Konstanz, Germany  Behavior of Fe Impurity in Ga-doped Multicrystalline Silicon Solar Cells  M. Dhamrin <sup>1</sup> , T. Saitoh <sup>1</sup> , K. Kamisako <sup>1</sup> , T. Hirasawa <sup>2</sup> , T. Eguchi <sup>2</sup> and I. Yamaga <sup>2</sup> ITokyo Univ. of Agr. & Tech., Japan, 2Dai-ichi Kiden Corp., Japan  Effect of Thermal Annealing on Oxygen Behavior and Minority-Carrier Lifetimes in Polycrystalline Silicon  Fifex of Information Function Materials, Hebei University of Technology, Tianjin, 2. Beijing Solar Energy Research Institute, I. Institute
P-10 Kyunghae Kim, S. K. Dhungel, U. Gangopadhyay, U. Manna, J. Yi School of information and Communication Engineering, Sungkyunkwan University Korea  Testure Etching of Multicrystalline Si by Atomic Hydrogen Generated by Hot Wire Method  P-11 Takehiko Sato <sup>1</sup> , Michio Ohtsubo <sup>2</sup> , Shigeru Matsuno <sup>1</sup> , and Makoto Konagai <sup>2</sup> 1 Material & Processing Technology Department, Advanced Technology R&D Center, Mitsubishi Electric Corporation, Japan, 2 Department of Physical Electronics, Tokyo Institute of Technology, Japan  Development about Texturing Multicrystalline Silicon Solar Cells  P-12 Liu Zhigang, Sun Tietun, Ku Shiwei, Luo Peiqing, Jiang Wei, Yu Huacong, Cui Rongqiang Department of Physics, Shanghai Jiao Tong University, China  Characteristics of Multi-crystalline Silicon in High Temperature Annealing  P-13 Xianfang Gou <sup>1,2</sup> , Shuang Song <sup>2</sup> Lifen Mal <sup>1,2</sup> Bingyan Ren <sup>1</sup> Xudong Li <sup>2</sup> Ying Xu <sup>2</sup> Wenjing Wang <sup>2</sup> 1. Institute of Information Function Materials, Hebei University of Technology, China, 2.Beijing Solar Energy Research Institute, 3/HuaYuan Road, HaiDian District Beijing, China  Development of Improved Screen Printed Albased Paste for Crystalline Silicon Solar Cells  P-14 V. Mikhitaryan <sup>1</sup> , A. Kravtchenko <sup>1</sup> , S. Garanzha <sup>1</sup> , O. Tchaplygina <sup>1</sup> I. Melnyk <sup>2</sup> , P. Fath <sup>2</sup> 1 JSC Analog, Russia, 2 Department of Physics, University of Konstanz, Germany  Behavior of Fe Impurity in Ga-doped Multicrystalline Silicon Solar Cells  P-15 M. Dhamrin <sup>1</sup> , T. Saitoh <sup>1</sup> , K. Kamisako <sup>1</sup> , T. Hirasawa <sup>2</sup> , T. Eguchi <sup>2</sup> and I. Yamaga <sup>2</sup> 1 Tokyo Univ. of Agr. & Tech., Japan, 2Dai-ichi Kiden Corp., Japan  Mechanisms of Light-induced Degradation in B-doped Multicrystalline Silicon Wafers and Solar Cells  M. Dhamrin <sup>1</sup> , T. Saitoh <sup>1</sup> , K. Kamisako <sup>1</sup> , T. Hirasawa <sup>2</sup> , T. Eguchi <sup>2</sup> and I. Yamaga <sup>2</sup> 1 Tokyo Univ. of Agr. & Tech., Japan, 2Dai-ichi Kiden Corp., Japan  Effect of Thermal Annealing on Oxygen Behavior and Minority-Carrier Lifetimes in Polycrystalline Silicon  P-17 GOU Xian-fang <sup>1,2</sup> MA Li-fen <sup>1,2</sup> Li Xu-dong <sup>2</sup> XU Ying <sup>2</sup> WANG We
School of information and Communication Engineering, Sungkyunkwan University Korea  Texture Etching of Multicrystalline Si by Atomic Hydrogen Generated by Hot Wire Method  P-11 Takehiko Sato <sup>1</sup> , Michio Ohtsubo <sup>2</sup> , Shigeru Matsuno <sup>1</sup> , and Makoto Konagar <sup>2</sup> 1 Material & Processing Technology Department, Advanced Technology R&D Center, Mitsubishi Electric Corporation, Japan, 2 Development about Texturing Multicrystalline Silicon Solar Cells  P-12 Liu Zhigang, Sun Tietun, Ku Shiwei, Luo Peiqing, Jiang Wei, Yu Huacong, Cui Rongqiang Department of Physics, Shanghai Jiao Tong University, China  Characteristics of Multi-crystalline Silicon in High Temperature Annealing  P-13 Xianfang Goul <sup>1,2</sup> , Shuang Song <sup>2</sup> Lifen Mal <sup>1,2</sup> Bingyan Ren <sup>1</sup> Xudong Li <sup>2</sup> Ying Xu <sup>2</sup> Wenjing Wang <sup>2</sup> 1. Institute of Information Function Materials, Hebei University of Technology, China, 2.Beijing Solar Energy Research Institute, 34 HuaYuan Road, HaiDian District Beijing, China  Development of Improved Screen Printed Albased Paste for Crystalline Silicon Solar Cells  P-14 V. Mikhitaryan <sup>1</sup> , A. Kravtchenko <sup>1</sup> , S. Garanzha <sup>1</sup> , O. Tehaplygina <sup>1</sup> I. Melnyk <sup>2</sup> , P. Fath <sup>2</sup> 1 JSC Analog, Russia, 2 Department of Physics, University of Konstanz, Germany  Behavior of Fe Impurity in Ga-doped Multicrystalline Silicon Solar Cells  P-15 M. Dhamrin <sup>1</sup> , T. Saitoh <sup>1</sup> , K. Kamisako <sup>1</sup> , T. Hirasawa <sup>2</sup> , T. Eguchi <sup>2</sup> and I. Yamaga <sup>2</sup> 1 Tokyo Univ. of Agr. & Tech., Japan, 2Dai-ichi Kiden Corp., Japan  Mechanisms of Light-induced Degradation in B-doped Multicrystalline Silicon Wafers and Solar Cells  P-16 M. Dhamrin <sup>1</sup> , T. Saitoh <sup>1</sup> , K. Kamisako <sup>1</sup> , T. Hirasawa <sup>2</sup> , T. Eguchi <sup>2</sup> and I. Yamaga <sup>2</sup> 1 Tokyo Univ. of Agr. & Tech., Japan, 2Dai-ichi Kiden Corp., Japan  Effect of Thermal Annealing on Oxygen Behavior and Minority-Carrier Lifetimes in Polycrystalline Silicon  GOU Xian-fang <sup>1,2</sup> MA Li-fen <sup>1,2</sup> LI Xu-dong <sup>2</sup> XU Ying <sup>2</sup> WANG Wen-jing <sup>2</sup> REN Bing-yan <sup>1</sup> 1. Institute of Information Function Materials, Hebei University of Technology, Tianjin, 2. Beijing Solar Energy
P-11 Takehiko Sato <sup>1</sup> , Michio Ohtsubo <sup>2</sup> , Shigeru Matsuno <sup>1</sup> , and Makoto Konagai <sup>2</sup> 1 Material & Processing Technology Department, Advanced Technology R&D Center, Mitsubishi Electric Corporation, Japan, 2 Department of Physical Electronics, Tokyo Institute of Technology, Japan    Development about Texturing Multicrystalline Silicon Solar Cells   Liu Zhigang, Sun Tietun, Ku Shiwei, Luo Peiqing, Jiang Wei, Yu Huacong, Cui Rongqiang Department of Physics, Shanghai Jiao Tong University, China    Characteristics of Multi-crystalline Silicon in High Temperature Annealing   P-13
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P-12 Liu Zhigang, Sun Tietun, Ku Shiwei, Luo Peiqing, Jiang Wei, Yu Huacong, Cui Rongqiang Department of Physics, Shanghai Jiao Tong University, China  Characteristics of Multi-crystalline Silicon in High Temperature Annealing  P-13 Xianfang Gou <sup>1,2</sup> , Shuang Song <sup>2</sup> Lifen Ma <sup>1,2</sup> Bingyan Ren <sup>1</sup> Xudong Li <sup>2</sup> Ying Xu <sup>2</sup> Wenjing Wang <sup>2</sup> 1. Institute of Information Function Materials, Hebei University of Technology, China, 2.Beijing Solar Energy Research Institute, 3 <sup>th</sup> HuaYuan Road, HaiDian District Beijing, China  Development of Improved Screen Printed Albased Paste for Crystalline Silicon Solar Cells  P-14 V. Mikhitaryan <sup>1</sup> , A. Kravtchenko <sup>1</sup> , S.Garanzha <sup>1</sup> , O. Tchaplygina <sup>1</sup> I. Melnyk <sup>2</sup> , P. Fath <sup>2</sup> 1 JSC Analog, Russia, 2 Department of Physics, University of Konstanz, Germany  Behavior of Fe Impurity in Ga-doped Multicrystalline Silicon Solar Cells  P-15 M. Dhamrin <sup>1</sup> , T. Saitoh <sup>1</sup> , K. Kamisako <sup>1</sup> , T. Hirasawa <sup>2</sup> , T. Eguchi <sup>2</sup> and I. Yamaga <sup>2</sup> 1 Tokyo Univ. of Agr. & Tech., Japan, 2Dai-ichi Kiden Corp., Japan  Mechanisms of Light-induced Degradation in B-doped Multicrystalline Silicon Wafers and Solar Cells  P-16 M. Dhamrin <sup>1</sup> , T. Saitoh <sup>1</sup> , K. Kamisako <sup>1</sup> , T. Hirasawa <sup>2</sup> , T. Eguchi <sup>2</sup> and I. Yamaga <sup>2</sup> 1 Tokyo Univ. of Agr. & Tech., Japan, 2Dai-ichi Kiden Corp., Japan  Effect of Thermal Annealing on Oxygen Behavior and Minority-Carrier Lifetimes in Polycrystalline Silicon  P-17 GOU Xian-fang <sup>1,2</sup> MA Li-fen <sup>1,2</sup> LI Xu-dong <sup>2</sup> XU Ying <sup>2</sup> WANG Wen-jing <sup>2</sup> REN Bing-yan <sup>1</sup> 1. Institute of Information Function Materials, Hebei University of Technology, Tianjin, 2. Beijing Solar Energy Research Institute, Silicon Materials, Hebei University of Technology, Tianjin, 2. Beijing Solar Energy Research Institute, Silicon Materials, Hebei University of Technology, Tianjin, 2. Beijing Solar Energy Research Institute, Silicon Materials, Hebei University of Technology, Tianjin, 2. Beijing Solar Energy Research Institute, Silicon Materials, Hebei University of Technology, Tianjin, 2. Beijing Solar Energy Research Institute, Si
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P-13 Xianfang Gou <sup>1,2</sup> , Shuang Song <sup>2</sup> Lifen Ma <sup>1,2</sup> Bingyan Ren <sup>1</sup> Xudong Li <sup>2</sup> Ying Xu <sup>2</sup> Wenjing Wang <sup>2</sup> 1. Institute of Information Function Materials, Hebei University of Technology, China, 2.Beijing Solar Energy Research Institute, 34 HuaYuan Road, HaiDian District Beijing, China  Development of Improved Screen Printed Albased Paste for Crystalline Silicon Solar Cells  V. Mikhitaryan <sup>1</sup> , A. Kravtchenko <sup>1</sup> , S.Garanzha <sup>1</sup> , O. Tchaplygina <sup>1</sup> I. Melnyk <sup>2</sup> , P. Fath <sup>2</sup> 1 JSC Analog, Russia, 2 Department of Physics, University of Konstanz, Germany  Behavior of Fe Impurity in Ga-doped Multicrystalline Silicon Solar Cells  M. Dhamrin <sup>1</sup> , T. Saitoh <sup>1</sup> , K. Kamisako <sup>1</sup> , T. Hirasawa <sup>2</sup> , T. Eguchi <sup>2</sup> and I. Yamaga <sup>2</sup> 1 Tokyo Univ. of Agr. & Tech., Japan, 2Dai-ichi Kiden Corp., Japan  Mechanisms of Light-induced Degradation in B-doped Multicrystalline Silicon Wafers and Solar Cells  M. Dhamrin <sup>1</sup> , T. Saitoh <sup>1</sup> , K. Kamisako <sup>1</sup> , T. Hirasawa <sup>2</sup> , T. Eguchi <sup>2</sup> and I. Yamaga <sup>2</sup> 1 Tokyo Univ. of Agr. & Tech., Japan, 2Dai-ichi Kiden Corp., Japan  Effect of Thermal Annealing on Oxygen Behavior and Minority-Carrier Lifetimes in Polycrystalline Silicon  P-17 GOU Xian-fang <sup>1,2</sup> MA Li-fen <sup>1,2</sup> LI Xu-dong <sup>2</sup> XU Ying <sup>2</sup> WANG Wen-jing <sup>2</sup> REN Bing-yan <sup>1</sup> 1. Institute of Information Function Materials, Hebei University of Technology, Tianjin, 2. Beijing Solar Energy Research Institute,
1. Institute of Information Function Materials, Hebei University of Technology, China, 2.Beijing Solar Energy Research Institute, 34 HuaYuan Road, HaiDian District Beijing, China  Development of Improved Screen Printed Albased Paste for Crystalline Silicon Solar Cells  V. Mikhitaryan <sup>1</sup> , A. Kravtchenko <sup>1</sup> , S.Garanzha <sup>1</sup> , O. Tchaplygina <sup>1</sup> I. Melnyk <sup>2</sup> , P. Fath <sup>2</sup> 1 JSC Analog, Russia, 2 Department of Physics, University of Konstanz, Germany  Behavior of Fe Impurity in Ga-doped Multicrystalline Silicon Solar Cells  M. Dhamrin <sup>1</sup> , T. Saitoh <sup>1</sup> , K. Kamisako <sup>1</sup> , T. Hirasawa <sup>2</sup> , T. Eguchi <sup>2</sup> and I. Yamaga <sup>2</sup> 1 Tokyo Univ. of Agr. & Tech., Japan, 2Dai-ichi Kiden Corp., Japan  Mechanisms of Light-induced Degradation in B-doped Multicrystalline Silicon Wafers and Solar Cells  M. Dhamrin <sup>1</sup> , T. Saitoh <sup>1</sup> , K. Kamisako <sup>1</sup> , T. Hirasawa <sup>2</sup> , T. Eguchi <sup>2</sup> and I. Yamaga <sup>2</sup> 1 Tokyo Univ. of Agr. & Tech., Japan, 2Dai-ichi Kiden Corp., Japan  Effect of Thermal Annealing on Oxygen Behavior and Minority-Carrier Lifetimes in Polycrystalline Silicon  P-17 GOU Xian-fang <sup>1,2</sup> MA Li-fen <sup>1,2</sup> LI Xu-dong <sup>2</sup> XU Ying <sup>2</sup> WANG Wen-jing <sup>2</sup> REN Bing-yan <sup>1</sup> 1. Institute of Information Function Materials, Hebei University of Technology, Tianjin, 2. Beijing Solar Energy Research Institute,
P-14  V. Mikhitaryan¹, A. Kravtchenko¹, S.Garanzha¹, O. Tchaplygina¹ I. Melnyk², P. Fath² 1 JSC Analog, Russia, 2 Department of Physics, University of Konstanz, Germany  Behavior of Fe Impurity in Ga-doped Multicrystalline Silicon Solar Cells  M. Dhamrin¹, T. Saitoh¹, K. Kamisako¹, T. Hirasawa², T. Eguchi² and I. Yamaga² 1 Tokyo Univ. of Agr. & Tech., Japan, 2Dai-ichi Kiden Corp., Japan  Mechanisms of Light-induced Degradation in B-doped Multicrystalline Silicon Wafers and Solar Cells  P-16  M. Dhamrin¹, T. Saitoh¹, K. Kamisako¹, T. Hirasawa², T. Eguchi² and I. Yamaga² 1 Tokyo Univ. of Agr. & Tech., Japan, 2Dai-ichi Kiden Corp., Japan  Effect of Thermal Annealing on Oxygen Behavior and Minority-Carrier Lifetimes in Polycrystalline Silicon  P-17  GOU Xian-fang¹.² MA Li-fen¹.² LI Xu-dong² XU Ying² WANG Wen-jing² REN Bing-yan¹ 1. Institute of Information Function Materials, Hebei University of Technology, Tianjin, 2. Beijing Solar Energy Research Institute,3
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P-17 GOU Xian-fang <sup>1,2</sup> MA Li-fen <sup>1,2</sup> LI Xu-dong <sup>2</sup> XU Ying <sup>2</sup> WANG Wen-jing <sup>2</sup> REN Bing-yan <sup>1</sup> 1. Institute of Information Function Materials, Hebei University of Technology, Tianjin, 2. Beijing Solar Energy Research Institute,
1. Institute of Information Function Materials, Hebei University of Technology, Tianjin, 2. Beijing Solar Energy Research Institute,
HuaYuan Road, HaiDian District Beijing, China
Utilize N-type Crystalline Silicon to Produce Solar Cell
P-18 Longzhong Tao, Hui Shen Institute for Soalr Energy System, Sun Yat-sen University, China
Simulation Studies of the Wafer Thinning Effect on Solar Cell Conversion Efficiencies
P-19 M. Dhamrin, M. Suda, T. Saitoh and K. Kamisako Tokyo Univ. of Agr. & Tech., Japan, M. Almutawakel Sana'a University, Faculty of Science, Physics Department, Sana'a - Republic Yemen
High Efficiency Solar Cell With Passivating Hot Wire CVD SiN <sub>x</sub> Coating
P-20  V. Verlaan <sup>1</sup> , C.H.M. van der Werf <sup>1</sup> , H.F.W. Dekkers <sup>2</sup> , I.G. Romijn <sup>3</sup> , W.J. Soppe <sup>3</sup> , A.W. Weeber <sup>3</sup> H.D. Goldbach <sup>1</sup> , and R.E.I. Schrol Utrecht University, Debye Institute, SID - Physics of Devices, The Netherlands, 2IMEC vzw, Belgium, 3ECN Solar Energy, the Netherlands
P-21 Silicon Thin Film on Al <sub>2</sub> O <sub>3</sub> Ceramics by Zone Melting Recrystallization with SiNx Barrier Layers

	Ma LiFen <sup>1,2</sup> Gou XianFang <sup>1,2</sup> XuYing <sup>2</sup> Li XuDong <sup>2</sup> Wang WenJing <sup>2</sup> Ren BingYan <sup>1</sup> 1. institute of information functional materials,hebei univesity of technology, China, 2. Beijing Solar Energy Research Institute, 3 # Hua Yuan Road, Hai Dian District Beijing, China
	Forming Gas Annealing of Large Area Multicrystalline Silicon Solar Cells
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	The Effect of Thermal Expansion Coefficients on Multicrystalline Si Solar Cells with Al Electrode
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Zhao-Kui Wang <sup>2-</sup> , Kui-Xun Lin <sup>4</sup> Xuna-Ying Lin <sup>2</sup> , Gui-Ming Qui <sup>4</sup> , Zu-Song Zhu <sup>4</sup> Depurtment of Physics Shantor Unrevarly. China, Zoologe of Physics & Information Engineering, Henun Normal University, China  Peng Kai, Zhang Desian, Qi Longsin, Cai Hongkun, San Zhongjin Institute of photoelectronics thin film device and technology, Nankai university, China  Influence of Hivdocom Treatment Time on the Performance of no-SiHe-Si Heterotunction Solar Cells in HWCVD Process  Quanfang Zhang, Mediang Zhu, Fengshen Liu, Jinlong Li Department of physics, Graduate University of Chinese Academy of Sciences, China  Grain Size Enlargement of Culficialises, Thin Films by Hot-Ware Median Process  Quanfang Zhang, Sedimaga Zhu, Fengshen Liu, Jinlong Li Department of Physics and Culficialises, Thin Films by Hot-Ware Median Process  Takafumi Tsukagoshi <sup>1</sup> , Hissahi Miyazaki <sup>1</sup> , Yoshiyaki Chiba <sup>1</sup> , Takahiro Wada <sup>1</sup> , Akira Yamada <sup>1</sup> and Makoto Konaga <sup>1</sup> Dipartment of Physical Electronics, Tokyo Institute of Technology, Japan, 2Department of Masirial Chemistry, Ryskoku University, Japan, Quantum Nanoelectronics Research Center, Tokyo Institute of Technology, Japan  Microstructures and Photovoclairs Properties of Clafases, Scalar Cells by co-Evaporation  Microstructures and Photovoclairs Properties of Clafases, Scalar Cells by co-Evaporation  Microstructures and Photovoclairs Properties of Clafases, Scalar Cells by Co-Evaporation  Beth Yun, E.R.V. Chalapothy, Sook Ki, Ki, Nin, Se, Jin Alm, Jeong Chall Lee, Jinoso Song, and Kyung Hoon'yoon, Solar Cells Research Center, Korea Institute of Energy Research, Korea  Study of Polycrystalline Colcose, and CuGaySe. Plan Films Deposited by PVD  Polyman, Chalapothy, Sook Ki, Ki, Nin, Se, Jin Films Deposited by PVD  Polyman, Chalapothy, Sook Ki, Ki, Nin, Se, Jin Almina, Jinakai Linversity, China  hanceteristics of Rapid Thermal Amnedled CollogaSes. Thin Films Deposited by PVD  Polyman, Chalapothy, Sook Ki, Ki, Nin, Se, Jin Almina, Nin, Se, Jin Almina, Jin Jingshi, Jingshi, Shigginsa F. Chichiba <sup></sup>		Mass Spectroscopy Measurement of SiCl <sub>n</sub> (n<3) Radicals Spatial Distribution in SiCl <sub>4</sub> Plasma
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Institute of photoelectronics than filin device and technology, Nankau university, China  Influence of Hydrogen Treatment Time on the Performance of ne-Si-He-Si-Heterojunction Solar Cells in HWCVD Process  Quanting Zhang, Medining Zhu, Fengthen Liu, Jinlong Li Department of physics, Graduate University of Chinese Academy of Sciences, China  Grain Size Enlargement of CulfuGaSe <sub>2</sub> Thin Films by Hot-Wire Melting Process  Takathumi Tsukagoshi <sup>3</sup> , Hissahi Miyazaki <sup>3</sup> , Yoshiyuki Chiba <sup>3</sup> , Takahiro Wada <sup>3</sup> , Akira Yarnada <sup>3</sup> and Makoto Konagai <sup>3</sup> Department of Physical Electronics, Tokyo Institute of Technology, Japan, 2Department of Material Chemistry, Ryukoku University, Japan, 3Quantum Nunoelectronics Research Center, Tokyo Institute of Technology, Japan  Microstructures and Photovolaic Propenties of CuGaSe <sub>2</sub> Solar Cells by co-Evaporation  Microstructures and Photovolaic Propenties of CuGaSe <sub>2</sub> Solar Cells by co-Evaporation  Jac Ho Yun, R. B. V. Chalagashy, Sook Ki Kim, S. Jin Ahn, Jeong Chul Lee, Janoo Song, and Kyung Hoon Yoon, Solar Cells Research Center, Korea Institute of Energy Research, Korea  Sandy of Polycrystalline CuGaSe <sub>2</sub> and CuGaSe <sub>2</sub> . Thin Films Deposited by PVD  LiZhang, Qinglie, Jianping Xiao, Chumaning Xa, Warning Xue, YunSun  Institute of Phytooelectronic Thin Film Device and Technology, Nankai University, China  haracteristics of Ravid Thormal Annealed CultuGaSe <sub>2</sub> . Thin Films With High Ga Composition  Proparation of Culni-SGaSe <sub>2</sub> Films by Selenization of Metal Procursors Using Diethylselenide as a Less-Hazardous Source  Proparation of Gulni-SGaSe <sub>2</sub> Films by Selenization of Metal Procursors Using Diethylselenide as a Less-Hazardous Source  Proparation of Gulni-SGaSe <sub>2</sub> Films by Selenization of Metal Procursors Using Diethylselenide as a Less-Hazardous Source  Proparation of Gulni-SGaSe <sub>2</sub> Films by Selenization of Metal Procursors Using Diethylselenide as a Less-Hazardous Source  Proparation of Gulni-SGaSe <sub>2</sub> Films by Selenization of Metal Procursors Using Diethylselenide as a Less-Hazardous S		Optimization of Thin Film Solar Cells Deposit Temperature on Polyimide Substrate
P-63 Qunfang Zhang, Meifang Zhu, Fengzhen Liu, Jinlong Li Department of physics, Graduate University of Chinese Academy of Sciences, China Grain Size Enfarcement of CulinGaiSes Thin Films by Hot-Wire Melting Process  P-64 Takafunir Tsukagoshi', Hisashi Miyazaki', Yoshiyuki Chiha', Takahiro Wada', Akira Yamada' and Makoto Konagai' Inperartment of Physical Electronics Tokyo Institute of Technology, Japan Department of Material Chemistry, Ryukoku University, Japan, 3Quantum Nanoselectronics Research Center, Tokyo Institute of Technology, Japan  Microstructures and Photovolnic Properties of CuGisSes Solar Cells by co-Evaporation  Jae Ho Yun, R.B. V Chalapathy, Seek K. Kim, Se. Jin Ahn, Jeong Chul Lee, Jinsoo Song, and Kyung HoonYoon, Solar Cells Research Center, Korea Institute of Energy Research, Korea  Study of Polycrystalline CuGaiSes and CuGisSes, Thin Films Deposited by PVD  LiZhang, GingHe, Jianping Xiao, Chuaarming Xu, Yuming Xue, YumSun Institute of Photoelectronic Thin Film Device and Technology, Nankai University, China  haracteristics of Rapid Thermal Annealed Cu(InGaiSes Thin Films With High Ga Composition  P-67 Hisashi Miyazaki', Yoshiyuki Chiba', Akira Yamada' and Makoto Konagai' 1Department of Physical Electronics, Zquantum Nanoelectronics Research Center, Tokyo Institute of Technology, Japan  Preparation of Culn L-sciasses Films by Selenization of Metal Precursors Using Diethylselenide as a Less-Hazaridous Source  Mutsumi Sugayama', Masahiro Pakaya', Assaki Kinoshita', Yasaharu Hanou', Hisayuki Nakanshi', Stugfusa F. Chichiba' 1Department of Electrical Engineering, Tokyo University of Science, Japan, Jistitute of Applied Physics and Graduate School of Pure and Applied Sciences, University of Tsakaha, Japan  Effects of Head Treatment in N2 and Se Atmosphere on the Densification of Nanoparticle Derived Cuffu GaiNey, Absorber Laver  P-69 Ki-Hyun Kimi'-S. Se-Jin Ahn', Young-Gab Chun', Byung-Ok Park' and Kyung-Hoon Yoon* Isolar Cells Resear-Chemer, Korea Institute of Energy Research, Korea, 2Dept. of Ino	P-62	
Outstage Zhang, Merlang Zhu, Fengenen Liu, Jiniong Li Department of Physics, Gridaute Structs of Chinese Academy of Sciences, China  Grain Size Enlargement of CulfuGalSe; Thin Films by Hot-Wire Melting Process  P-64  Takafumi Tsukagoshi <sup>1</sup> , Hisashi Miyazaki <sup>1</sup> , Yoshiyuki Chiba <sup>1</sup> , Takahiro Wada <sup>2</sup> , Akira Yamada <sup>3</sup> and Makoto Konagai <sup>1</sup> IDepartment of Physical Electronics, Tokyo Institute of Technology, Japan, 2Department of Material Chemistry, Ryukoku University, Japan, 3Quantum Nanoelectronics Research Center, Tokyo Institute of Technology, Japan, 2Department of Material Chemistry, Ryukoku University, Japan, 3Quantum Nanoelectronics Research Center, Tokyo Institute of Technology, Japan  Microstructures and Photovoltaic Properties of CuGaSes, Solar Cells by co-Evaporation  Jae Io Yun, R.B.Y. Chalapathy, Seok Ki Kim, Se Jin Ahn, Jeong Chul Lee, Jinsoo Song, and Kyung Hoon Yoon, Solar Cells Research Center, Korea Institute of Energy Research, Korea  Study of Polycrystalline CuGaSes, and CuGaSes, Thin Films Deposited by PVD  LiZhang, QingHe, Jianping Xiao, Chuamaning Xia, Yuming Xue, Yumisun Institute of Photoelectronic Thin Film Device and Technology, Nankai University, China  haracteristics of Rapid Thermal Annealed Cucled Sey Thin Films With High Ga Composition  P-67  Hissahi Miyazaki <sup>1</sup> , Yoshiyuki Chiba <sup>1</sup> , Akra Yamada <sup>2</sup> and Makoto Konagai <sup>1</sup> Ilbepartment of Physical Electronics, Quantum Nanoelectronics Research Center, Tokyo Institute of Technology, Japan  Preparation of Culal-xGaxSe2 Films by Selenization of Metal Precursors Using Diethylselenide as a Less-Hazardous Source  P-68  Mutsumi Sugiyama <sup>1</sup> , Masahiro Fukaya <sup>1</sup> , Atsaki Kinoshita <sup>1</sup> , Yasuharu Hanou <sup>1</sup> , Hisayuki Nakanishi <sup>1</sup> , Shigefusa F. Chichibu <sup>2</sup> IDepartment of Electrical Engineering, Tokyo University of Science, Japan, Jastitute of Applied Physics and Graduate School of Pure and Applied Sciences, University of Tsukuba, Japan  Effects of Heat Treatment in N2 and Se Atmosphere on the Densification of Nanoparticle Derived Cufin, GalSe <sub>2</sub> Absorber		Influence of Hydrogen Treatment Time on the Performance of nc-Si:H/c-Si Heterojunction Solar Cells in HWCVD Process
P-64 Takafirmi Tsukagoshi <sup>1</sup> , Hisseshi Miyazaki <sup>1</sup> , Yoshiyuki Chiba <sup>1</sup> , Takahiro Wada <sup>2</sup> , Akira Yamada <sup>1</sup> and Makoto Konagai <sup>1</sup> IDepartment of Physical Electronics, Tokyo Institute of Technology, Japan, 2Department of Material Chemistry, Ryukoku University, Japan, 3Quantum Nanoelectronics Research Center, Tokyo Institute of Technology, Japan  Microstructures and Photovoltaic Properties of CuGaSe <sub>2</sub> Solar Cells by co-Evaporation  Microstructures and Photovoltaic Properties of CuGaSe <sub>2</sub> Solar Cells by co-Evaporation  Jae Ho Yun, R.B. V.Chalapathy, Seok Ki Kim, Se Jin Ahn, Jeong Chul Lee, Jinasoo Song, and Kyung Hoon'Yoon, Solar Cells Research Center, Korea Institute of Energy Research, Korea  Study of Polverystalline CuGaSe <sub>2</sub> and CuGaSe <sub>2</sub> . Thin Films Deposited by PVD  LiZhang, QingHe, Jianping Xiao, Chuanming Xu, Yuming Xue, YunSun Institute of Photoelectronic Thin Film Device and Technology, Nankai University, China  haracteristics of Rapid Thermal Annealed CufinGaSe <sub>2</sub> . Thin Films With High Ga Composition  P-67  Hisashi Miyazaki <sup>1</sup> , Yoshiyuki Chiba <sup>1</sup> , Akira Yamada <sup>2</sup> and Makoto Konagai <sup>1</sup> IDepartment of Physical Electronics, 2Quantum Nanoelectronics, Research Center, Tokyo Institute of Technology, Japan  Prenantion of CuIn1-XGaxSe <sub>2</sub> Films by Selenization of Metal Precursors Using Diethylselentide as a Less-Hazardous Source  P-68  Mutsumi Sugiyuma <sup>1</sup> , Masshiro Fukaya <sup>1</sup> , Assuki Kinoshita <sup>1</sup> , Yasuharu Hanou <sup>1</sup> , Hisayuki Nakanishi <sup>1</sup> , Shigefusa F. Chichibu <sup>2</sup> IDepartment of Electrical Engineering, Tokyo University of Science, Japan, 3nstitute of Applied Physics and Graduate School of Pure and Applied Sciences, University of Tsukuba, Japan  Effects of Heat Treatment in N2 and Se Atmosphere on the Densification of Nanoparticle Derived CuIn Ga)Se <sub>2</sub> Absorber Layer  Neshanically Enhanced Nucleation of CuIn Ga)Se <sub>2</sub> Nanoparticles in Low Temperature Colloidal Reaction  P-70  Se-Jin Ahn <sup>1</sup> , Ki-Hyun Kim <sup>1,2</sup> , Young-Gab Chun <sup>1</sup> , Byung-Ok Park <sup>2</sup> and Kyung-Hoon Yoon <sup>4</sup> ISolar Cells Research Center, Korea Institute of En	P-63	
Department of Physical Electronics, Tokyo Institute of Technology, Japan, Department of Material Chemistry, Ryukoku University, Japan, Department of Material Chemistry, Ryukoku University, Japan, Department of Physical Electronics, Tokyo Institute of Technology, Japan, Department of Material Chemistry, Ryukoku University, Japan, Department of Lordonics, Japan, Department of Electrical Engineering, Social Cells by co-Evaporation  Microstructures and Photovoltaic Properties of CuGaSes, Solar Cells by co-Evaporation  Jae Ho Yun, R.B. V. Chalapathy, Seok Ki Kim, Se Jin Ahn, Jeong Chul Lee, Jinsono Song, and Kyung Hoon Yoon, Solar Cells Research Center, Korea Institute of Energy Research, Korea  Study of Polycrystalline CuGaSes and CuGaSes, Thin Films Deposited by PVD  LiZhang, QingHe, Jianping Xiao, Chuamming Xu, Yuming Xue, YunSun Institute of Photoelectronic Thin Film Device and Technology, Nankai University, China  haracteristics of Rapid Thermal Annealed CuGlnGaSes, Thin Films With High Ga Composition  P-67  Hisashi Miyazaki¹, Yoshiyuki Chiba¹, Akira Yamada² and Makoto Konagai¹ IDepartment of Physical Electronics, 2Quantum Nanoelectronics Research Center, Tokyo Institute of Technology, Japan  Preparation of CuIn1 - SGaSes Films by Selenziation of Metal Precursors Using Diethylselenide as a Less-Hazardous Source  P-68  Mutsumi Sugiyama¹, Massahiro Fukaya¹, Assuki Kinoshira¹, Yasuharu Hanou¹, Hisayuki Nakanishi¹, Shigefusa F. Chichibu² IDepartment of Electrical Engineering, Tokyo University of Science, Japan, 3nstitute of Applied Physics and Graduate School of Pure and Applied Sciences, University of Tsukuba, Japan  Effects of Heat Treatment in N2 and Se Atmosphere on the Densification of Nanoparticle Derived CuIn Ga)Se, Absorber Laver  P-69  Ki-Hyun Kim¹², Se-Jin Ahn¹, Young-Gab Chun¹, Byung-Ok Park² and Kyung-Hoon Yoons¹ ISolar Cells Research Center, Korea Institute of Energy Research, Korea, 2Dept. of Inorganic Materials Engineering, Kyungpook National University, Korea  Mechanically Enhanced Nucleation of C		Grain Size Enlargement of Cu(InGa)Se <sub>2</sub> Thin Films by Hot-Wire Melting Process
P-65  Jae Ho Yun, R.B. V. Chalapathy, Seok Ki Kim, Se Jin Ahn, Jeong Chul Lee, Jinsoo Song, and Kyung Hoon Yoon, Solar Cells Research Center, Korea Institute of Energy Research, Korea  Study of Polycrystalline CuGaSe <sub>2</sub> and CuGaSe <sub>3</sub> Thin Films Deposited by PVD  LiZhang, QingHe, Jianping Xiao, Chuanning Xu, Yuming Xue, YunSun Institute of Photoelectronic Thin Film Device and Technology, Nankai University, China  haracteristics of Rapid Thermal Annealed Cu(InGa)Se <sub>2</sub> Thin Films With High Ga Composition  P-67  Hissahi Miyazaki¹, Yoshiyuki Chiba¹, Akira Yamada² and Makoto Konagai¹ Department of Physical Electronics, 2Quantum Nanoelectronics Research Center, Tokyo Institute of Technology, Japan  Preparation of CuIn1-xGaxSe <sub>2</sub> Films by Selenization of Metal Precursors Using Diethylselenide as a Less-Hazardous Source  Mutsumi Sugiyama¹, Masahiro Fukaya¹, Atsuki Kinoshita¹, Yasuharu Hanou¹, Hissyuki Nakanishi¹, Shigefusa F. Chichibu² Department of Electrical Engineering, Tokyo University of Science, Japan, 3nstitute of Applied Physics and Graduate School of Pure and Applied Sciences, University of Tsukuba, Japan  Effects of Heat Treatment in N2 and Se Atmosphere on the Densification of Nanoparticle Derived Cu(In.Ga)Se <sub>2</sub> Absorber Laver  P-69  Ki-Hyun Kim¹², Se-Jin Ahn¹, Young-Gab Chun¹, Byung-Ok Park² and Kyung-Hoon Yoon*¹ ISolar Cells Research Center, Korea Institute of Energy Research, Korea, 2Dept. of Inorganic Materials Engineering, Kyungpook National University, Korea  Mechanically Enhanced Nucleation of Cu(In.Ga)Se <sub>2</sub> Nanoparticles in Low Temperature Colloidal Reaction  P-70  Se-Jin Ahn¹, Ki-Hyun Kim¹², Young-Gab Chun¹, Byung-Ok Park² and Kyung-Hoon Yoon*¹ ISolar Cells Research Center, Korea Institute of Energy Research, Korea, 2Dept. of Inorganic Materials Engineering, Kyungpook National University, Korea  Suussen Merdes¹, Lakhdar Bechir², Mohammed Benabdeslem², Noureddine Benslim² Roger Madelon³, Gérard Nouet³, Masatoshi Sano¹ and Shizutoshi Ando¹  1 Department of Electrical Engineering, Faculty of Engineering	P-64	1Department of Physical Electronics, Tokyo Institute of Technology, Japan, 2Department of Material Chemistry, Ryukoku University,
Jase Ho Yun, R. B. V. Chalapathy, Seok Ki Kim, Se Jin Ahn, Jeong Chul Lee, Jinsoo Song, and Kyung Hoon Yoon, Solar Cells Research Center, Korea Institute of Energy Research, Korea  Study of Polvervstalline CuGaSes and CuGaSes Thin Films Deposited by PVD  LiZhang, QingHe, Jianping Xiao, Chuanning Xu, Yuming Xue, YunSun Institute of Photoelectronic Thin Film Device and Technology, Anakai University, China  haracteristics of Rapid Thermal Annealed Cu(InGa)Ses_Thin Films With High Ga Composition  P-67  Hisashi Miyazaki¹, Yoshiyuki Chiba¹, Akira Yamada² and Makoto Konagai¹ IDepartment of Physical Electronics, 2Quantum Nanoelectronics Research Center, Tokyo Institute of Technology, Japan  Preparation of CuIn1-xGaxSe2 Films by Selenization of Metal Precursors Using Diethylselenide as a Less-Hazardous Source  Mutsumi Sugiyama¹, Masahiro Fukaya¹, Atsuki Kinoshita¹, Yasuharu Hanou¹, Hisayuki Nakanishi¹, Shigefusa F. Chichibu² IDepartment of Electrical Engineering, Tokyo University of Science, Japan, 3nstitute of Applied Physics and Graduate School of Pure and Applied Sciences, University of Tsukuba, Japan  Effects of Heat Treatment in N2 and Se Atmosphere on the Densification of Nanoparticle Derived Cu(In.Ga)Ses_Absorber Laver  P-69  Ki-Hyun Kim¹², Se-Jin Ahn¹, Young-Gab Chun¹, Byung-Ok Park² and Kyung-Hoon Yoon*¹ ISolar Cells Research Center, Korea Institute of Energy Research, Korea, 2Dept. of Inorganic Materials Engineering, Kyungpook National University, Korea  Mechanically Enhanced Nucleation of Cu(In.Ga)Ses_Nanoparticles in Low Temperature Colloidal Reaction  P-70  Se-Jin Ahn¹, Ki-Hyun Kim¹², Young-Gab Chun¹, Byung-Ok Park² and Kyung-Hoon Yoon*¹ ISolar Cells Research Center, Korea Institute of Energy Research, Korea, 2Dept. of Inorganic Materials Engineering, Kyungpook National University, Korea  Structural and Optical Characterization of Cu (In.Ga)Tes_Polverystalline Thin Films Prepared by Flash Evaporation Technique  Saoussen Merdes¹, Lakhdar Bechir², Mohammed Benabdeslem², Noureddine Benslim² Roger Madelon³, Gér		Microstructures and Photovoltaic Properties of CuGaSe <sub>2</sub> Solar Cells by co-Evaporation
P-66 LiZhang, QingHe, Jianping Xiao, Chuamming Xu, Yuming Xue, YunSun Institute of Photoelectronic Thin Film Device and Technology, Nankai University, China  haracteristics of Rapid Thermal Annealed Cu(InGa)Se <sub>2</sub> Thin Films With High Ga Composition  Hisashi Miyazaki <sup>1</sup> , Yoshiyuki Chiba <sup>1</sup> , Akira Yamada <sup>2</sup> and Makoto Konagai <sup>1</sup> IlDepartment of Physical Electronics, 2Quantum Nanoelectronics Research Center, Tokyo Institute of Technology, Japan  Preparation of CuIn1-xGaxSe2 Films by Selenization of Metal Precursors Using Diethylselenide as a Less-Hazardous Source  P-68 Mutsumi Sugiyama <sup>1</sup> , Masahiro Fukaya <sup>1</sup> , Atsuki Kinoshita <sup>1</sup> , Yasuharu Hanou <sup>1</sup> , Hisayuki Nakanishi <sup>1</sup> , Shigefusa F, Chichibu <sup>2</sup> IlDepartment of Electrical Engineering, Tokyo University of Science, Japan, 3nstitute of Applied Physics and Graduate School of Pure and Applied Sciences, University of Tsukuba, Japan  Effects of Heat Treatment in N2 and Se Atmosphere on the Densification of Nanoparticle Derived Cu(In Ga)Se <sub>2</sub> Absorber Layer  P-69 Ki-Hyun Kim <sup>12</sup> , Se-Jin Ahn <sup>1</sup> , Young-Gab Chun <sup>1</sup> , Byung-Ok Park <sup>2</sup> and Kyung-Hoon Yoon* <sup>1</sup> ISolar Cells Research Center, Korea Institute of Energy Research, Korea, 2Dept. of Inorganic Materials Engineering, Kyungpook National University, Korea  Mechanically Enhanced Nucleation of Cu(In,Ga)Se <sub>2</sub> Nanoparticles in Low Temperature Colloidal Reaction  P-70 Se-Jin Ahn <sup>1</sup> , Ki-Hyun Kim <sup>12</sup> , Young-Gab Chun <sup>1</sup> , Byung-Ok Park <sup>2</sup> and Kyung-Hoon Yoon* <sup>1</sup> ISolar Cells Research Center, Korea Institute of Energy Research, Korea, 2Dept. of Inorganic Materials Engineering, Kyungpook National University, Korea  Structural and Optical Characterization of Cu (In,Ga)Te <sub>2</sub> Polycrystalline Thin Films Prepared by Flash Evaporation Technique  Saoussen Merdes <sup>3</sup> , Lakhdar Bechiri <sup>2</sup> , Mohammed Benabdeslem <sup>2</sup> , Noureddine Benslim <sup>2</sup> Roger Madelon <sup>3</sup> , Gérard Nouet <sup>3</sup> , Masatoshi Sano <sup>1</sup> and Shizutoshi Ando <sup>1</sup> 1 Department of Electrical Engineering, Faculty of Engineering, Tokyo University of Science, Japan, 2 Department of Physics, Faculty of S	P-65	
Institute of Photoelectronic Thin Film Device and Technology, Nankai University, China  haracteristics of Rapid Thermal Annealed Cu(InGa)Se_Thin Films With High Ga Composition  P-67  Hisashi Miyazaki <sup>1</sup> , Yoshiyuki Chiba <sup>1</sup> , Akira Yamada <sup>2</sup> and Makoto Konagai <sup>1</sup> 1Department of Physical Electronics, 2Quantum Nanoelectronics Research Center, Tokyo Institute of Technology, Japan  Preparation of CuIn1-xGaxSe2 Films by Selenization of Metal Precursors Using Diethylselenide as a Less-Hazardous Source  Mutsumi Sugiyama <sup>1</sup> , Masahiro Fukaya <sup>1</sup> , Atsuki Kinoshita <sup>1</sup> , Yasuharu Hanou <sup>1</sup> , Hisayuki Nakanishi <sup>1</sup> , Shigefusa F. Chichibu <sup>2</sup> 1Department of Electrical Engineering, Tokyo University of Science, Japan, 3nstitute of Applied Physics and Graduate School of Pure and Applied Sciences, University of Tsukuba, Japan  Effects of Heat Treatment in N2 and Se Atmosphere on the Densification of Nanoparticle Derived Cu(In Ga)Se <sub>2</sub> Absorber Laver  P-69  Ki-Hyun Kim <sup>1,2</sup> , Se-Jin Ahn <sup>1</sup> , Young-Gab Chun <sup>1</sup> , Byung-Ok Park <sup>2</sup> and Kyung-Hoon Yoon* <sup>1</sup> 1Solar Cells Research Center, Korea Institute of Energy Research, Korea, 2Dept. of Inorganic Materials Engineering, Kyungpook National University, Korea  Mechanically Enhanced Nucleation of Cu(In Ga)Se <sub>2</sub> Nanoparticles in Low Temperature Colloidal Reaction  P-70  Se-Jin Ahn <sup>1</sup> , Ki-Hyun Kimi <sup>1,2</sup> Young-Gab Chun <sup>1</sup> , Byung-Ok Park <sup>2</sup> and Kyung-Hoon Yoon* <sup>1</sup> 1Solar Cells Research Center, Korea Institute of Energy Research, Korea, 2Dept. of Inorganic Materials Engineering, Kyungpook National University, Korea  Se-Jin Ahn <sup>1</sup> , Ki-Hyun Kimi <sup>1,2</sup> Young-Gab Chun <sup>1</sup> , Byung-Ok Park <sup>2</sup> and Kyung-Hoon Yoon* <sup>1</sup> 1Solar Cells Research Center, Korea Institute of Energy Research, Korea, 2Dept. of Inorganic Materials Engineering, Kyungpook National University, Korea  Structural and Optical Characterization of Cu (In Ga)Te <sub>2</sub> Polycrystalline Thin Films Prepared by Flash Evaporation Technique  Saoussen Merdes <sup>1</sup> , Lakhdar Bechiri <sup>2</sup> , Mohammed Benabdeslem <sup>2</sup> , Noureddine Benslim <sup>2</sup> Roger Madelon <sup>3</sup> , Gérard Nouet <sup>3</sup> , M		Study of Polycrystalline CuGaSe <sub>2</sub> and CuGa <sub>3</sub> Se <sub>5</sub> Thin Films Deposited by PVD
P-67 Hissahi Miyazaki <sup>1</sup> , Yoshiyuki Chiba <sup>1</sup> , Akira Yamada <sup>2</sup> and Makoto Konagai <sup>1</sup> IDepartment of Physical Electronics, 2Quantum Nanoelectronics Research Center, Tokyo Institute of Technology, Japan  Preparation of CuIn1-xGaxSe2 Films by Selenization of Metal Precursors Using Diethylselenide as a Less-Hazardous Source  P-68 Mutsumi Sugiyama <sup>1</sup> , Masahiro Fukaya <sup>1</sup> , Atsuki Kinoshita <sup>1</sup> , Yasuharu Hanou <sup>1</sup> , Hissayuki Nakanishi <sup>1</sup> , Shigefusa F. Chichibu <sup>2</sup> IDepartment of Electrical Engineering, Tokyo University of Science, Japan, 3nstitute of Applied Physics and Graduate School of Pure and Applied Sciences, University of Tsukuha, Japan  Effects of Heat Treatment in N2 and Se Atmosphere on the Densification of Nanoparticle Derived CuIn.Ga)Se <sub>2</sub> Absorber Laver  P-69 Ki-Hyun Kim <sup>12</sup> , Se-Jin Ahn <sup>1</sup> , Young-Gab Chun <sup>1</sup> , Byung-Ok Park <sup>2</sup> and Kyung-Hoon Yoon <sup>61</sup> ISolar Cells Research Center, Korea Institute of Energy Research, Korea, 2Dept. of Inorganic Materials Engineering, Kyungpook National University, Korea  Mechanically Enhanced Nucleation of Cu(In.Ga)Se <sub>2</sub> Nanoparticles in Low Temperature Colloidal Reaction  P-70 Se-Jin Ahn <sup>1</sup> , Ki-Hyun Kim <sup>12</sup> , Young-Gab Chun <sup>1</sup> , Byung-Ok Park <sup>2</sup> and Kyung-Hoon Yoon <sup>61</sup> ISolar Cells Research Center, Korea Institute of Energy Research, Korea, 2Dept. of Inorganic Materials Engineering, Kyungpook National University, Korea  Se-Jin Ahn <sup>1</sup> , Ki-Hyun Kim <sup>12</sup> , Young-Gab Chun <sup>1</sup> , Byung-Ok Park <sup>2</sup> and Kyung-Hoon Yoon <sup>61</sup> ISolar Cells Research Center, Korea Institute of Energy Research, Korea, 2Dept. of Inorganic Materials Engineering, Kyungpook National University, Korea  Se-Jin Ahn <sup>1</sup> , Ki-Hyun Kim <sup>12</sup> , Young-Gab Chun <sup>1</sup> , Byung-Ok Park <sup>2</sup> and Kyung-Hoon Yoon <sup>61</sup> ISolar Cells Research Center, Korea Institute of Energy Research, Korea, 2Dept. of Inorganic Materials Engineering, Kyungpook National University, Korea  Saoussen Merdes <sup>1</sup> , Lakhdar Bechiri <sup>2</sup> , Mohammed Benabdeslem <sup>2</sup> , Noureddine Benslim <sup>2</sup> Roger Madelon <sup>3</sup> , Gérard Nouet <sup>3</sup> , Masatoshi Sano <sup>1</sup> and Shizutoshi Ando <sup>1</sup> I Department of Ele	P-66	
Hisashi Miyazaki¹, Yoshiyuki Chiba¹, Akira Yamada¹ and Makoto Konagai¹ IDepartment of Physical Electronics, 2Quantum Nanoelectronics Research Center, Tokyo Institute of Technology, Japan  Preparation of Culn1-xGaxSe2 Films by Selenization of Metal Precursors Using Diethylselenide as a Less-Hazardous Source  Mutsumi Sugiyama¹, Masahiro Fukaya¹, Atsuki Kinoshita¹, Yasuharu Hanou¹, Hisayuki Nakanishi¹, Shigefusa F. Chichibu² IDepartment of Electrical Engineering, Tokyo University of Science, Japan, 3nstitute of Applied Physics and Graduate School of Pure and Applied Sciences, University of Tsukuba, Japan  Effects of Heat Treatment in N2 and Se Atmosphere on the Densification of Nanoparticle Derived Cu(In.Ga)Se₂ Absorber Laver  P-69  Ki-Hyun Kim¹², Se-Jin Ahn¹, Young-Gab Chun¹, Byung-Ok Park² and Kyung-Hoon Yoon*¹ ISolar Cells Research Center, Korea Institute of Energy Research, Korea, 2Dept. of Inorganic Materials Engineering, Kyungpook National University, Korea  Mechanically Enhanced Nucleation of Cu(In.Ga)Se₂ Nanoparticles in Low Temperature Colloidal Reaction  P-70  Se-Jin Ahn¹, Ki-Hyun Kim¹², Young-Gab Chun¹, Byung-Ok Park² and Kyung-Hoon Yoon*¹ ISolar Cells Research Center, Korea Institute of Energy Research, Korea, 2Dept. of Inorganic Materials Engineering, Kyungpook National University, Korea  Structural and Optical Characterization of Cu (In.Ga)Te₂ Polverystalline Thin Films Prepared by Flash Evaporation Technique  Saoussen Merdes¹, Lakhdar Bechiri², Mohammed Benabdeslem², Noureddine Benslim² Roger Madelon³, Gérard Nouet³, Masatoshi Sano¹ and Shizutoshi Ando¹  1 Department of Electrical Engineering, Faculty of Engineering, Tokyo University of Science, Japan, 2 Department of Physics, Faculty of Science, Badji-Mokhtar University, Algeria, 3 Laboratoire de Cristallographie des Matériaux, UMR 6508 CNRS, Institut des Sciences de la Matière et du Rayonnement, 6 Boulevard du Maréchal Juin, France  Electrodeposition of CulnSe₂ Thin Film for Applications in Photovoltaic Cells  Rui Yu, Tong Ren, Hongjian Yan, Guope		haracteristics of Rapid Thermal Annealed Cu(InGa)Se <sub>2</sub> Thin Films With High Ga Composition
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